Notice for TAIYO YUDEN products

Please read this notice before using the TAIYO YUDEN products.

!\ REMINDERS

Product information in this catalog is as of October 2016. All of the contents specified herein are subject to change without notice due to technical improvements, etc. Therefore, please check for the latest information carefully before practical application or use of our products.

Please note that TAIYO YUDEN shall not be in any way responsible for any damages and defects in products or equipment incorporating our products, which are caused under the conditions other than those specified in this catalog or individual specification.

- Please contact TAIYO YUDEN for further details of product specifications as the individual specification is available.
- Please conduct validation and verification of our products in actual condition of mounting and operating environment before using our products.
- The products listed in this catalog are intended for use in general electronic equipment (e.g., AV equipment, OA equipment, home electric appliances, office equipment, information and communication equipment), general medical equipment, industrial equipment, and automotive interior applications, etc. Please be sure to contact TAIYO YUDEN for further information before using the products for any equipment which may directly cause loss of human life or bodily injury (e.g., specially controlled medical equipment, transportation equipment including, without limitation, automotive powertrain control system, train control system, and ship control system, traffic signal equipment).

Please do not incorporate our products into any equipment requiring high levels of safety and/or reliability (e.g., aerospace equipment, aviation equipment, nuclear control equipment, undersea equipment, military equipment).

When our products are used even for high safety and/or reliability-required devices or circuits of general electronic equipment, it is strongly recommended to perform a thorough safety evaluation prior to use of our products and to install a protection circuit as necessary.

Please note that unless you obtain prior written consent of TAIYO YUDEN, TAIYO YUDEN shall not be in any way responsible for any damages incurred by you or third parties arising from use of the products listed in this catalog for any equipment requiring inquiry to TAIYO YUDEN or prohibited for use by TAIYO YUDEN as described above.

- Please note that TAIYO YUDEN shall have no responsibility for any controversies or disputes that may occur in connection with a third party's intellectual property rights and other related rights arising from use of our products. TAIYO YUDEN grants no license for such rights.
- Please note that unless otherwise agreed in writing, the scope of warranty for our products is limited to the delivered our products themselves and TAIYO YUDEN shall not be in any way responsible for any damages resulting from a fault or defect in our products.
- The contents of this catalog are applicable to our products which are purchased from our sales offices or authorized distributors (hereinafter "TAIYO YUDEN's official sales channel"). Please note that the contents of this catalog are not applicable to our products purchased from any seller other than TAIYO YUDEN's official sales channel.
- Caution for Export

Some of our products listed in this catalog may require specific procedures for export according to "U.S. Export Administration Regulations", "Foreign Exchange and Foreign Trade Control Law" of Japan, and other applicable regulations. Should you have any questions on this matter, please contact our sales staff.

MULTILAYER CERAMIC CAPACITORS





■PART NUMBER

J	М	Κ	3	1	6	Δ	В	J	1	0	6	М	L	Н	Т	Δ
1	2	3		4		(5)	(3		7		8	9	10	11	12

△=Blank space

End termination

Plated

Soft Termination

Cu Internal Electrodes

High Reliability Application

(J	ا(را	R	a	ted	vo	ľ	ta	g	

2Series name

Code	Rated voltage[VDC]
Α	4
J	6.3
L	10
Е	16
Т	25
G	35
U	50
Н	100
Q	250
S	630

S R

432

3End termination Code

Κ

J

4Dimension(L×	: W)	
Туре	Dimensions (L×W)[mm]	EIA(inch)
063	0.6 × 0.3	0201
105	1.0 × 0.5	0402
105	0.52 × 1.0 💥	0204
107	1.6 × 0.8	0603
107	0.8 × 1.6 💥	0306
212	2.0 × 1.25	0805
212	1.25 × 2.0 💥	0508
316	3.2 × 1.6	1206
325	3.2 × 2.5	1210

4.5 × 3.2

Code Series name

M Multilayer ceramic capacitor

V Multilayer ceramic capacitor for high frequency

W LW reverse type multilayer capacitor

Note: ※LW reverse type(□WK) only

⑤Dimension tolerance

Code	Туре	L[mm]	W[mm]	T[mm]
Δ	ALL	Standard	Standard	Standard
	063	0.6±0.05	0.3±0.05	0.3±0.05
	105	1.0±0.10	0.5±0.10	0.5±0.10
	107	1.6+0.15/-0.05	0.8+0.15/-0.05	0.8+0.15/-0.05
Α	010	0.0 1.0 15 / 0.05	105 1015/ 005	0.85±0.10
	212	2.0 + 0.15 / -0.05	1.25 + 0.15 / -0.05	1.25+0.15/-0.05
	316	3.2±0.20	1.6±0.20	1.6±0.20
	325	3.2±0.30	2.5±0.30	2.5±0.30
	105	1.0+0.15/-0.05	0.5+0.15/-0.05	0.5+0.15/-0.05
	107	1.6+0.20/-0	0.8+0.20/-0	0.8+0.20/-0
В	212	2.0+0.20/-0	1.25+0.20/-0	0.85±0.10
	212	2.0+0.20/ -0	1.25+0.20/ -0	1.25+0.20/-0
	316	3.2±0.30	1.6±0.30	1.6±0.30
	105	1.0+0.20/-0	0.5 + 0.20 / -0	0.5+0.20/-0
С	107	1.6+0.25/-0	0.8 + 0.25 / -0	0.8 + 0.25 / -0
	212	2.0+0.25/-0	1.25+0.25/-0	1.25 + 0.25 / -0
	212	2.0±0.15	1.25±0.15	0.85±0.15
K	316	3.2±0.20	1.6±0.20	1.15±0.20
K	310	3.2 ± 0.20	1.0 ± 0.20	1.6±0.20
	325	3.2±0.50	2.5±0.30	2.5 ± 0.30

Note: P. 22 Standard external dimensions

Δ= Blank space

1812

©Temperature characteristics code

■High dielectric type

Code	Applicable standard				Temperature range[°C]	Ref. Temp.[°C]	Capacitance change	Capacitance tolerance	Tolerance code										
	ΕIΛ	X5R	−55 ~ + 85	25	±15%	±10%	K												
	BJ EIA X		-55°° + 65	20	上15%	±20%	М												
C6	00 FIA V		-55 ~ +105	25	±22%	±10%	K												
	C6 EIA	X6S	-55~+105	25	± 22 70	±20%	М												
В7	EIA	EIA V7D	VZD	VZD	VZD	V7D	CIA V7D	CIA V7D	-1A V7D	V2D	EIA V7D	ETA V7D	ETA V7D	EIA X7R	-55 ~ +125	25	±15%	±10%	K
Б/	B/ EIA ^/		-55.4 + 125	25	±1370	±20%	М												
C7	EIA	X7S	-55 ~ +125	25	±22%	±10%	K												
	LIA	A/3	-55° + 125	20	1 22 70	±20%	М												
D7	EIA X	A V7T	-55 ~ +125	25	+22%/-33%	±10%	K												
		^/1	_55.3 + 125		+2270/ - 33%	±20%	М												

[▶] This catalog contains the typical specification only due to the limitation of space. When you consider the purchase of our products, please check our specification. For details of each product (characteristics graph, reliability information, precautions for use, and so on), see our website (http://www.ty-top.com/) .

■Temperature compensating type

<u></u>	Tomporacare compensating type									
Code		cable idard	Temperature range[°C]	Ref. Temp.[°C]	Capacitance change	Capacitance tolerance	Tolerance code			
						±0.1pF	В			
	JIS	CG		20		±0.25pF	С			
CG			-55 ~ +125		0±30ppm/°C	±0.5pF	D			
CG						-55.4 + 125		о±зоррпі/ С	±1pF	F
	EIA	EIA COG	COG	25		±2%	G			
						±5%	J			

7Nominal capacitance

(Fitominal capacitance						
Code (example)	Nominal cpacitance					
0R5	0.5pF					
010	1pF					
100	10pF					
101	100pF					
102	1,000pF					
103	0.01 <i>μ</i> F					
104	0.1 μ F					
105	1.0 <i>μ</i> F					
106	10 μ F					
107	100 μ F					

Note : R=Decimal point

8 Capacitance tolerance

Code	Capacitance tolerance
В	±0.1pF
С	±0.25pF
D	±0.5pF
G	±2%
J	±5%
K	±10%
М	±20%

Thickness

Code	Thickness[mm]
Р	0.3
Т	0.3
V	0.5
С	0.7(107type or more)
Α	0.8
D	0.85(212type or more)
F	1.15
G	1.25
Н	1.5
L	1.6
N	1.9
М	2.5

10Special code

Code	Special code
Н	MLCC for Industrial and Automotive

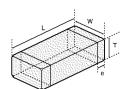
11)Packaging

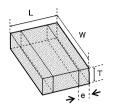
Code	Packaging
F	ϕ 178mm Taping (2mm pitch)
R	ϕ 178mm Embossed Taping (4mm pitch)
Т	ϕ 178mm Taping (4mm pitch)
	ϕ 178mm Taping (4mm pitch, 1000 pcs/reel)
P	325 type(Thickness code M)

①Internal code

9	
Code	Internal code
Δ	Standard

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 \divideontimes LW reverse type

Tuno(FIA)		Dime	nsion [mm] (inch)		
Type(EIA)	L	W	T	*1	е
DM/(000/0001)	0.6±0.03	0.3±0.03	0.3±0.03	_	0.15±0.05
□MK063(0201)	(0.024 ± 0.001)	(0.012 ± 0.001)	(0.012 ± 0.001)	Т	(0.006 ± 0.002)
DMK10E (0400)	1.0±0.05	0.5±0.05	0.5±0.05	٧	0.25±0.10
□MK105(0402)	(0.039 ± 0.002)	(0.020 ± 0.002)	(0.020 ± 0.002)	V	(0.010 ± 0.004)
TWIC10E (0004) \	0.52±0.05	1.0±0.05	0.3±0.05	Р	0.18±0.08
⊐WK105(0204)※	(0.020 ± 0.002)	(0.039 ± 0.002)	(0.012 ± 0.002)	Р	(0.007 ± 0.003)
TMK107(0000)	1.6±0.10	0.8±0.10	0.8±0.10		0.35±0.25
□MK107(0603)	(0.063 ± 0.004)	(0.031 ± 0.004)	(0.031 ± 0.004)	Α	(0.014 ± 0.010)
TM 1407 (0000)	1.6±0.10	0.8±0.10	0.8±0.10		0.35+0.3/-0.25
⊐MJ107(0603)	(0.063 ± 0.004)	(0.031 ± 0.004)	(0.031 ± 0.004)	Α	(0.014 + 0.012 / -0.010)
TVC107(0000)	1.6±0.10	0.8±0.10	0.7±0.10	_	0.35±0.25
□VS107(0603)	(0.063 ± 0.004)	(0.031 ± 0.004)	(0.028 ± 0.004)	С	(0.014 ± 0.010)
TMD407(0000)	1.6±0.10	0.8±0.10	0.8±0.10	•	0.1~0.6
⊐MR107(0603)	(0.063 ± 0.004)	(0.031 ± 0.004)	(0.031 ± 0.004)	Α	(0.004~0.024)
	0.8±0.10	1.6±0.10	0.5±0.05		0.25±0.15
⊐WK107(0306)※	(0.031 ± 0.004)	(0.063 ± 0.004)	(0.020 ± 0.002)	V	(0.010 ± 0.006)
	((0.85±0.10		(33232227
	2.0±0.10	1.25±0.10	(0.033±0.004)	D	0.5±0.25
□MK212(0805)	(0.079±0.004)	(0.049 ± 0.004)	1.25±0.10	 	(0.020±0.010)
	(0.073 ± 0.004)	(0.043 ± 0.004)	(0.049±0.004)	G	(0.020±0.010)
	 		0.049±0.004)	 	
	001010	405.0.0		D	051055/ 055
□MJ212(0805)	2.0±0.10	1.25±0.10	(0.033±0.004)		0.5+0.35/-0.25
	(0.079 ± 0.004)	(0.049 ± 0.004)	1.25±0.10	G	(0.020 + 0.014 / -0.010)
			(0.049 ± 0.004)		
□VS212(0805)	2.0±0.10	1.25±0.10	0.85±0.10	D	0.5±0.25
1 40212 (0000)	(0.079 ± 0.004)	(0.049 ± 0.004)	(0.033 ± 0.004)		(0.020 ± 0.010)
□MR212(0805)	2.0 ± 0.10	1.25±0.10	1.25±0.10	G	0.25~0.75
JIVIN212 (0003)	(0.079 ± 0.004)	(0.049 ± 0.004)	(0.049 ± 0.004)	G	(0.010~0.029)
JWK010 (0E00) %	1.25±0.15	2.0±0.15	0.85±0.10	7	0.3±0.2
⊒WK212(0508)※	(0.049 ± 0.006)	(0.079 ± 0.006)	(0.033 ± 0.004)	D	(0.012 ± 0.008)
			1.15±0.10	_	
	3.2±0.15	1.6±0.15	(0.045 ± 0.004)	F	0.5+0.35/-0.25
⊐MK316(1206)	(0.126±0.006)	(0.063±0.006)	1.6±0.20		(0.020+0.014/-0.010)
	(0.120 ± 0.000)	(0.000 ± 0.000)		L	(0.020 1 0.014) 0.010)
			(0.063±0.008)		
			1.15±0.10	F	
□MJ316(1206)	3.2±0.15	1.6±0.15	(0.045 ± 0.004)	'	0.6+0.4/-0.3
J1410310(1200)	(0.126 ± 0.006)	(0.063 ± 0.006)	1.6±0.20		(0.024+0.016/-0.012)
			(0.063 ± 0.008)	L	
TMD040(4000)	3.2±0.15	1.6±0.15	1.6±0.20		0.25~0.85
∃MR316(1206)	(0.126 ± 0.006)	(0.063 ± 0.006)	(0.063 ± 0.008)	L	(0.010~0.033)
			1.15±0.10	_	
			(0.045 ± 0.004)	F	
			1.5±0.10	 	1
	3.2±0.30	2.5±0.20	(0.059 ± 0.004)	Н	0.6±0.3
∃MK325(1210)	(0.126±0.012)	(0.098±0.008)	1.9±0.20	 	(0.024±0.012)
	(323 = 3.312)	(0.000 ± 0.000)	(0.075±0.008)	N	(5.52 1 2 5.512)
			2.5±0.20		+
			(0.098±0.008)	M	
	 			 	
	001000	0.5 / 0.00	1.9±0.20	N	00104/ 05
]MJ325(1210)	3.2±0.30	2.5±0.20	(0.075±0.008)	-	0.6+0.4/-0.3
	(0.126±0.012)	(0.098 ± 0.008)	2.5±0.20	М	(0.024+0.016/-0.012
			(0.098 ± 0.008)		
			1.9±0.20	N	
	3.2±0.30	2.5±0.20	(0.075 ± 0.008)		0.3~0.9
TMR325 (1210)		(0.098 ± 0.008)	2.5±0.20		(0.012~0.035)
□MR325(1210)	(0.126±0.012)	(0.030 ± 0.000)		1 1/4	
□MR325(1210)	(0.126±0.012)	(0.030 ± 0.000)	(0.098±0.008)	М	
□MR325(1210) □MK432(1812)	(0.126±0.012) 4.5±0.40	3.2±0.30	(0.098±0.008) 2.5±0.20	M M	0.9±0.6

Note: X. LW reverse type, *1.Thickness code

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STANDARD QUANTITY

т	EIA (inch)	Dime	nsion	Standard qu	uantity[pcs]
Type	EIA (inch)	[mm]	Code	Paper tape	Embossed tape
063	0201	0.3	Т	15000	_
105	0402	0.5	V	10000	
105	0204 ※	0.30	Р	10000	_
		0.7	С	4000	
		0.8	Α	4000	_
107	0603	0.8	А	3000 (Soft Termination)	_
		0.8	А	_	3000 (Soft Termination)
	0306 ※	0.50	V	_	4000
		0.85	D	4000	_
	0805	1.25	G	_	3000
212	0805	1.25	G	_	2000 (Soft Termination
	0508 ※	0.85	D	4000	-
010	1000	1.15	F	_	3000
316	1206	1.6	L	_	2000
		1.15	F		
205	1010	1.5	Н	_	2000
325	1210	1.9	N		
		2.5	М	_	500(T), 1000(P)
432	1812	2.5	М	_	500

Note : ※.LW Reverse type(□WK)

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- · All the Multilayer Ceramic Capacitors of the catalog lineup are RoHS compliant.
- Capacitance tolerance code is applied to □ of part number.
- All the Multilayer Ceramic Capacitors in the catalog lineup are applicable for reflow-soldering.

- The exchange of individual specifications is necessary depending on the application and circuit condition. Please contact Taiyo Yuden sales channels.
- * *1: Automotive (AEC-Q200 Qualified) products
 - : AEC-Q200 qualified>

All the Multilayer Ceramic Capacitors of *1 marks are tested based on the test conditions and methods defined in AEC-Q200 by family item.

125°C products: AEC-Q200 Grade1 (we conduct the evaluation at the test condition of Grade1.)

105°C products: AEC-Q200 Grade2 (we conduct the evaluation at the test condition of Grade2.)

 85°C products: AEC-Q200 Grade3 (we conduct the evaluation at the test condition of Grade3.)

Please consult with TAIYO YUDEN's official sales channel for the details of the product specification and AEC-Q200 test results, etc.,

and please review and approve TAIYO YUDEN's product specification before ordering.

- * *2: Industrial products and Medical products
- *3: For standard case size, please kindly refer to @Dimension, @Dimension tolerance, @Thickness and Standard external dimensions on Page 22.

Multilayer Ceramic Capacitors (High dielectric type)

●105TYPE (Demension:1.0×0.5mm JIS:1005 EIA:0402)

[Temperature Characteristic BJ: X5R] 0.5mm thickness(V)

Part number 1	Part number 2	Rated voltage [V]	Temperature characteristics	Capacitance [F]	Capacitance tolerance [%]	tan δ [%]	HTLT Rated voltage x %	Thickness*3 [mm]	Note
JMK105 BJ102∏VHF			X5R	1000 p	±10, ±20	2.5	200	0.5±0.05	*1 ,*2
JMK105 BJ102∐VHF JMK105 BJ152∏VHF		-	X5R X5R	1500 p	±10, ±20 ±10, ±20	2.5	200	0.5±0.05	*1 .*2
JMK105 BJ222∏VHF		-	X5R	2200 p	±10, ±20 ±10, ±20	2.5	200	0.5±0.05	*1 .*2
UMK105 BJ332∏VHF		-	X5R	3300 p	±10, ±20 ±10, ±20	2.5	200	0.5±0.05	*1 .*2
UMK105 BJ472 VHF		-	X5R	4700 p	±10, ±20	2.5	200	0.5±0.05	*1 .*2
UMK105 BJ682 VHF		50	X5R	6800 p	±10, ±20 ±10, ±20	2.5	150	0.5±0.05	*1 .*2
UMK105 BJ103 VHF		-	X5R	0.01 μ	±10, ±20	3.5	200	0.5±0.05	*1 .*2
UMK105 BJ223 VHF		-	X5R	0.012 μ	±10, ±20	5.5	150	0.5±0.05	*1 .*2
UMK105 BJ223UVHF		4	X5R X5R	0.022 μ	±10, ±20 ±10, ±20	5	150	0.5±0.05 0.5±0.05	*1 .*2
		4	X5R X5R	0.047 μ	±10, ±20 ±10, ±20	10	150	0.5±0.05 0.5±0.05	*1 .*2
UMK105 BJ104∏VHF TMK105 BJ472∏VHF			X5R X5R	0.1 μ 4700 p	±10, ±20 ±10, ±20	2.5	200	0.5±0.05 0.5±0.05	*1 .*2
TMK105 BJ472UVHF		4	X5R X5R	6800 p	±10, ±20 ±10, ±20	2.5	200	0.5±0.05 0.5±0.05	*1 .*2
TMK105 BJ682UVHF		4	X5R X5R	0.01 μ	±10, ±20 ±10, ±20	3.5	200	0.5±0.05 0.5±0.05	*1 ,*2
		_	X5R X5R			3.5			
TMK105 BJ223 VHF		25		0.022 μ	±10, ±20		200	0.5±0.05	*1 ,*2
TMK105 BJ473 VHF		_	X5R	0.047 μ	±10, ±20	3.5	150	0.5±0.05	*1 ,*2
TMK105 BJ104 VHF		4	X5R	0.1 μ	±10, ±20	5	150	0.5±0.05	*1 ,*2
TMK105 BJ224∏VHF		4	X5R	0.22 μ	±10, ±20	10	150	0.5±0.05	*1 ,*2
TMK105ABJ474[]VHF			X5R	0.47 μ	±10, ±20	10	150	0.5±0.10	*1 ,*2
EMK105 BJ223 VHF		4	X5R	0.022 μ	±10, ±20	3.5	200	0.5±0.05	*1 ,*2
EMK105 BJ473[VHF			X5R	0.047 μ	±10, ±20	3.5	150	0.5 ± 0.05	*1 ,*2
EMK105 BJ104 VHF		16	X5R	0.1 μ	±10, ±20	5	150	0.5±0.05	*1 ,*2
EMK105 BJ224[]VHF			X5R	0.22 μ	±10, ±20	10	150	0.5±0.05	*1 ,*2
EMK105ABJ474∏VHF			X5R	0.47 μ	±10, ±20	10	150	0.5±0.10	*1 ,*2
EMK105 BJ105∏VHF			X5R	1 μ	±10, ±20	10	150	0.5±0.05	*1 ,*2
LMK105 BJ224[]VHF		_	X5R	0.22 μ	±10, ±20	5	150	0.5±0.05	*1 ,*2
LMK105ABJ474[]VHF		10	X5R	0.47 μ	±10, ±20	10	150	0.5±0.10	*1 ,*2
LMK105 BJ105[]VHF		10	X5R	1 μ	±10, ±20	10	150	0.5 ± 0.05	*1 ,*2
LMK105ABJ225MVHF			X5R	2.2 μ	±20	10	150	0.5±0.10	*1 ,*2
JMK105 BJ224 VHF			X5R	0.22 μ	±10, ±20	5	150	0.5 ± 0.05	*1 ,*2
JMK105 BJ474[]VHF			X5R	0.47 μ	±10, ±20	10	150	0.5 ± 0.05	*1 ,*2
JMK105 BJ105[]VHF		6.3	X5R	1 μ	±10, ±20	10	150	0.5 ± 0.05	*1 ,*2
JMK105 BJ225MVHF			X5R	2.2 μ	±20	10	150	0.5±0.05	*1 ,*2
JMK105BBJ475MVHF			X5R	4.7 μ	±20	10	150	0.5+0.15/-0.05	*1 ,*2
AMK105 BJ225MVHF			X5R	2.2 μ	±20	10	150	0.5±0.05	*1 ,*2
AMK105BBJ475MVHF		4	X5R	4.7 μ	±20	10	150	0.5+0.15/-0.05	*1 ,*2
AMK105CBJ106MVHF		1	X5R	10 μ	±20	10	150	0.5+0.20/-0	*1 ,*2

Temperature Characterist	tic B7 : X7R 】 0.5mm t	nickness(V)							
Part number 1	Part number 2	Data danahana N/I	Temperature	Capacitance	Capacitance	tan δ	HTLT	*3 - 7	Note
	Part number 2	Rated voltage [V]	characteristics	[F]	tolerance [%]	[%]	Rated voltage x %	Thickness*3 [mm]	Note
UMK105 B7102 UHF			X7R	1000 p	±10, ±20	2.5	200	0.5±0.05	*1 ,*2
UMK105 B7152 VHF			X7R	1500 p	±10, ±20	2.5	200	0.5 ± 0.05	*1 ,*2
UMK105 B7222 UHF			X7R	2200 p	±10, ±20	2.5	200	0.5±0.05	*1 ,*2
UMK105 B7332 UHF			X7R	3300 p	±10, ±20	2.5	200	0.5±0.05	*1 ,*2
UMK105 B7472 UHF		50	X7R	4700 p	±10, ±20	2.5	150	0.5±0.05	*1 ,*2
UMK105 B7682 UHF		30	X7R	6800 p	±10, ±20	2.5	150	0.5±0.05	*1 ,*2
UMK105 B7103∏VHF			X7R	0.01 μ	±10, ±20	3.5	150	0.5±0.05	*1 ,*2
UMK105 B7223 UHF			X7R	0.022 μ	±10, ±20	10	200	0.5 ± 0.05	*1 ,*2
UMK105 B7473 UHF			X7R	0.047 μ	±10, ±20	10	200	0.5 ± 0.05	*1 ,*2
UMK105 B7104 UHF			X7R	0.1 μ	±10, ±20	10	150	0.5 ± 0.05	*1 ,*2
TMK105 B7472 UHF			X7R	4700 p	±10, ±20	2.5	200	0.5 ± 0.05	*1 ,*2
TMK105 B7682 □VHF			X7R	6800 p	±10, ±20	2.5	200	0.5 ± 0.05	*1 ,*2
TMK105 B7103 UHF		25	X7R	0.01 μ	±10, ±20	3.5	200	0.5 ± 0.05	*1 ,*2
TMK105 B7223 UHF		25	X7R	0.022 μ	±10, ±20	3.5	150	0.5 ± 0.05	*1 ,*2
TMK105 B7473 UHF			X7R	0.047 μ	±10, ±20	3.5	150	0.5 ± 0.05	*1 ,*2
TMK105 B7104 UHF			X7R	0.1 μ	±10, ±20	10	150	0.5 ± 0.05	*1 ,*2
EMK105 B7223 UHF			X7R	0.022 μ	±10, ±20	3.5	150	0.5 ± 0.05	*1 ,*2
EMK105 B7473 UHF		16	X7R	0.047 μ	±10, ±20	3.5	150	0.5 ± 0.05	*1 ,*2
EMK105 B7104 UHF		10	X7R	0.1 μ	±10, ±20	5	150	0.5±0.05	*1 ,*2
EMK105 B7224 UHF			X7R	0.22 μ	±10, ±20	10	150	0.5±0.05	*1 ,*2
LMK105 B7104 VHF		10	X7R	0.1 μ	±10, ±20	5	150	0.5±0.05	*1 ,*2
LMK105 B7224 VHF] 10	X7R	0.22 μ	±10, ±20	10	150	0.5±0.05	*1 ,*2
JMK105 B7224 UHF		6.3	X7R	0.22 μ	±10, ±20	10	150	0.5±0.05	*1 ,*2
JMK105 B7474 UHF		0.3	X7R	0.47 μ	±10, ±20	10	150	0.5±0.05	*1 ,*2

[▶] This catalog contains the typical specification only due to the limitation of space. When you consider the purchase of our products, please check our specification. For details of each product (characteristics graph, reliability information, precautions for use, and so on), see our website (http://www.ty-top.com/) .

■107TYPE (Dimension:1.6 × 0.8mm JIS:1608 EIA:0603)

[Temperature Characteristic BJ: X5R] 0.8mm thickness(A)

Temperature Characterist			Temperature	Capacitance	Capacitance	$ an\delta$	HTLT	+2	
Part number 1	Part number 2	Rated voltage [V]	characteristics	[F]	tolerance [%]	[%]	Rated voltage x %	Thickness*3 [mm]	Note
UMK107 BJ104[AHT			X5R	0.1 μ	±10, ±20	3.5	150	0.8±0.10	*1 ,*2
UMK107 BJ224[AHT		50	X5R	0.22 μ	±10, ±20	10	150	0.8±0.10	*1 ,*2
UMK107 BJ474[AHT		30	X5R	0.47 μ	±10, ±20	10	150	0.8±0.10	*1 ,*2
UMK107ABJ105∏AHT			X5R	1 μ	±10, ±20	10	150	0.8+0.15/-0.05	*1 ,*2
GMK107 BJ223∏AHT			X5R	0.022 μ	±10, ±20	2.5	200	0.8±0.10	*1 ,*2
GMK107 BJ473∏AHT			X5R	0.047 μ	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
GMK107 BJ104∏AHT		35	X5R	0.1 μ	±10, ±20	3.5	150	0.8±0.10	*1 ,*2
GMK107 BJ224∏AHT		30	X5R	0.22 μ	±10, ±20	10	150	0.8±0.10	*1 ,*2
GMK107ABJ474∏AHT			X5R	0.47 μ	±10, ±20	10	150	0.8+0.15/-0.05	*1 ,*2
GMK107 BJ105∏AHT			X5R	1 μ	±10, ±20	10	150	0.8±0.10	*1 ,*2
TMK107 BJ223 AHT			X5R	0.022 μ	±10, ±20	2.5	200	0.8±0.10	*1 ,*2
TMK107 BJ473[AHT			X5R	0.047 μ	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
TMK107 BJ104∏AHT			X5R	0.1 μ	±10, ±20	3.5	150	0.8±0.10	*1 ,*2
TMK107 BJ224□AHT		25	X5R	0.22 μ	±10, ±20	5	150	0.8±0.10	*1 ,*2
TMK107 BJ474[AHT			X5R	0.47 μ	±10, ±20	3.5	150	0.8±0.10	*1 ,*2
TMK107 BJ105∏AHT			X5R	1 μ	±10, ±20	10	150	0.8±0.10	*1 ,*2
TMK107BBJ225[AHT			X5R	2.2 μ	±10, ±20	10	150	0.8+0.20/-0	*1 ,*2
EMK107 BJ104 AHT			X5R	0.1 μ	±10, ±20	3.5	150	0.8±0.10	*1 ,*2
EMK107 BJ224 AHT			X5R	0.22 μ	±10, ±20	5	150	0.8±0.10	*1 ,*2
EMK107 BJ474 AHT		16	X5R	0.47 μ	±10, ±20	3.5	150	0.8±0.10	*1 ,*2
EMK107 BJ105 AHT		10	X5R	1 μ	±10, ±20	5	150	0.8±0.10	*1 ,*2
EMK107ABJ225 AHT			X5R	2.2 μ	±10, ±20	10	150	0.8+0.15/-0.05	*1 ,*2
EMK107BBJ475 AHT			X5R	4.7 μ	±10, ±20	10	150	0.8+0.20/-0	*1 ,*2
LMK107 BJ474 AHT			X5R	0.47 μ	±10, ±20	3.5	150	0.8±0.10	*1 ,*2
LMK107 BJ105 AHT			X5R	1 μ	±10, ±20	5	150	0.8±0.10	*1 ,*2
LMK107 BJ225∏AHT		10	X5R	2.2 μ	±10, ±20	10	150	0.8±0.10	*1 ,*2
LMK107 BJ475 AHT			X5R	4.7 μ	±10, ±20	10	150	0.8±0.10	*1 ,*2
LMK107BBJ106MAHT			X5R	10 μ	±20	10	150	0.8+0.20/-0	*1 ,*2
JMK107 BJ225∏AHT			X5R	2.2 μ	±10, ±20	10	150	0.8±0.10	*1 ,*2
JMK107 BJ475∏AHT		6.3	X5R	4.7 μ	±10, ±20	10	150	0.8±0.10	*1 ,*2
JMK107ABJ106MAHT		1	X5R	10 μ	±20	10	150	0.8+0.15/-0.05	*1 ,*2
AMK107ABJ106MAHT		4	X5R	10 μ	±20	10	150	0.8+0.15/-0.05	*1 ,*2
AMK107BBJ226MAHT] 4	X5R	22 μ	±20	10	150	0.8+0.20/-0	*1 ,*2

[Temperature Characteristic B7 : X7R , D7 : X7T] 0.8mm thickness(A)

Temperature Characterisi	uc br. Ark, br. Ari	U.OIIIIII UIICKIIESS (7	٦)						
Part number 1	Part number 2	Rated voltage [V]	Temperature characteristics	Capacitance [F]	Capacitance tolerance [%]	tan δ [%]	HTLT Rated voltage x %	Thickness*3 [mm]	Note
UMK107 B7102 AHT			X7R	1000 p	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
UMK107 B7152 AHT			X7R	1500 p	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
UMK107 B7222 AHT			X7R	2200 p	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
UMK107 B7332∏AHT			X7R	3300 р	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
UMK107 B7472 AHT		50	X7R	4700 p	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
UMK107 B7682∏AHT			X7R	6800 p	±10, ±20	3.5	200	0.8 ± 0.10	*1 ,*2
UMK107 B7103[AHT			X7R	0.01 μ	±10, ±20	3.5	200	0.8 ± 0.10	*1 ,*2
UMK107 B7223[AHT			X7R	0.022 μ	$\pm 10, \pm 20$	3.5	200	0.8 ± 0.10	*1 ,*2
UMK107 B7473[AHT			X7R	0.047 μ	±10, ±20	3.5	200	0.8 ± 0.10	*1 ,*2
UMK107 B7104[]AHT			X7R	0.1 μ	±10, ±20	3.5	200	0.8 ± 0.10	*1 ,*2
GMK107 B7473[AHT			X7R	0.047 μ	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
GMK107 B7104[]AHT			X7R	0.1 μ	±10, ±20	3.5	150	0.8±0.10	*1 ,*2
GMK107 B7224[]AHT		35	X7R	0.22 μ	±10, ±20	10	150	0.8±0.10	*1 ,*2
GMK107 B7474[]AHT			X7R	0.47 μ	±10, ±20	10	150	0.8±0.10	*1 ,*2
GMK107AB7105∏AHT			X7R	1 μ	±10, ±20	10	150	0.8+0.15/-0.05	*1 ,*2
TMK107 B7223∏AHT			X7R	0.022 μ	±10, ±20	2.5	200	0.8±0.10	*1 ,*2
TMK107 B7473[]AHT			X7R	0.047 μ	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
TMK107 B7104[]AHT		25	X7R	0.1 μ	±10, ±20	3.5	150	0.8±0.10	*1 ,*2
TMK107 B7224[]AHT		23	X7R	0.22 μ	±10, ±20	10	150	0.8±0.10	*1 ,*2
TMK107 B7474[]AHT			X7R	0.47 μ	±10, ±20	10	150	0.8±0.10	*1 ,*2
TMK107AB7105[AHT			X7R	1 μ	±10, ±20	10	150	0.8+0.15/-0.05	*1 ,*2
EMK107 B7473[AHT			X7R	0.047 μ	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
EMK107 B7104[]AHT			X7R	0.1 μ	±10, ±20	3.5	150	0.8±0.10	*1 ,*2
EMK107 B7224[]AHT		16	X7R	0.22 μ	±10, ±20	5	150	0.8±0.10	*1 ,*2
EMK107 B7474[]AHT			X7R	0.47 μ	±10, ±20	10	150	0.8±0.10	*1 ,*2
EMK107 B7105∏AHT			X7R	1 μ	±10, ±20	10	150	0.8±0.10	*1 ,*2
LMK107 B7224□AHT			X7R	0.22 μ	±10, ±20	5	150	0.8±0.10	*1 ,*2
LMK107 B7474[]AHT		10	X7R	0.47 μ	±10, ±20	3.5	150	0.8±0.10	*1 ,*2
LMK107 B7105∏AHT		10	X7R	1 μ	±10, ±20	10	150	0.8±0.10	*1 ,*2
LMK107BD7225 AHT			X7T	2.2 μ	±10, ±20	10	150	0.8+0.20/-0	*1 ,*2
JMK107 B7225∏AHTR		6.3	X7R	2.2 μ	±10, ±20	10	150	0.8±0.10	*1 ,*2

212TYPE (Dimension:2.0 × 1.25mm JIS:2012 EIA:0805)

Temperature Characterist	tic BJ : X5R】 1.25mm th	nickness(G)							
Part number 1	Part number 2	Rated voltage [V]		Capacitance tan δ	HTLT	Thickness*3 [mm]	Note		
T die Hamber 1	T die Hamber 2	· · · · · · · · · · · · · · · · · · ·		[F]	tolerance [%]	[%]	Rated voltage x %	THICKIESS [HIII]	11000
UMK212 BJ104 GHT			X5R	0.1 μ	±10, ±20	3.5	200	1.25±0.10	*1 ,*2
UMK212 BJ224 GHT		50	X5R	0.22 μ	±10, ±20	3.5	150	1.25±0.10	*1 ,*2
UMK212 BJ474∏GHT		- 50	X5R	0.47 μ	±10, ±20	3.5	150	1.25±0.10	*1 ,*2
UMK212 BJ105∏GHT			X5R	1 μ	±10, ±20	5	150	1.25±0.10	*1 ,*2
GMK212 BJ104∏GHT			X5R	0.1 μ	±10, ±20	3.5	200	1.25±0.10	*1 ,*2
GMK212 BJ224∏GHT			X5R	0.22 μ	±10, ±20	3.5	150	1.25±0.10	*1 ,*2
GMK212 BJ474∏GHT		35	X5R	0.47 μ	±10, ±20	3.5	150	1.25±0.10	*1 ,*2
GMK212 BJ105∏GHT			X5R	1 μ	±10, ±20	5	150	1.25±0.10	*1 ,*2
GMK212BBJ225[]GHT			X5R	2.2 μ	±10, ±20	10	150	1.25+0.20/-0	*1 ,*2

[▶] This catalog contains the typical specification only due to the limitation of space. When you consider the purchase of our products, please check our specification. For details of each product (characteristics graph, reliability information, precautions for use, and so on), see our website (http://www.ty-top.com/).

Part number 1	Part number 2	Rated voltage [V]	Temperature	Capacitance	Capacitance	tan δ	HTLT	Thickness*3 [mm]	Note
T di c Hambor 1	T di c Hamboi E	Thatba Fortage [1]	characteristics	[F]	tolerance [%]	[%]	Rated voltage x %	THICKINGS [IIIII]	
TMK212 BJ104[]GHT			X5R	0.1 μ	±10, ±20	3.5	200	1.25±0.10	*1 ,*2
TMK212 BJ224 GHT			X5R	0.22 μ	±10, ±20	3.5	150	1.25±0.10	*1 ,*2
TMK212 BJ474[]GHT			X5R	0.47 μ	±10, ±20	3.5	200	1.25±0.10	*1 ,*2
TMK212 BJ105 GHT		25	X5R	1 μ	±10, ±20	3.5	150	1.25±0.10	*1 ,*2
TMK212 BJ225 GHT			X5R	2.2 μ	±10, ±20	5	150	1.25±0.10	*1 ,*2
TMK212BBJ475[]GHT			X5R	4.7 μ	±10, ±20	10	150	1.25+0.20/-0	*1 ,*2
TMK212BBJ106[]GHT			X5R	10 μ	±10, ±20	10	150	1.25+0.20/-0	*1 ,*2
EMK212 BJ105 GHT			X5R	1 μ	±10, ±20	3.5	150	1.25±0.10	*1 ,*2
EMK212 BJ225 GHT		16	X5R	2.2 μ	±10, ±20	5	200	1.25±0.10	*1 ,*2
EMK212ABJ475[]GHT		10	X5R	4.7 μ	±10, ±20	10	150	1.25+0.15/-0.05	*1 ,*2
EMK212BBJ106 GHT			X5R	10 μ	±10, ±20	10	150	1.25+0.20/-0	*1 ,*2
LMK212 BJ225 GHT			X5R	2.2 μ	±10, ±20	5	200	1.25±0.10	*1 ,*2
LMK212ABJ475[]GHT		10	X5R	4.7 μ	±10, ±20	10	150	1.25+0.15/-0.05	*1 ,*2
LMK212ABJ106 GHT			X5R	10 μ	±10, ±20	10	150	1.25+0.15/-0.05	*1 ,*2
JMK212ABJ475[]GHT			X5R	4.7 μ	±10, ±20	5	200	1.25+0.15/-0.05	*1 ,*2
JMK212ABJ106[]GHT		6.3	X5R	10 μ	±10, ±20	10	150	1.25+0.15/-0.05	*1 ,*2
JMK212BBJ226MGHT			X5R	22 μ	±20	10	150	1.25+0.20/-0	*1 ,*2
AMK212ABJ226MGHT		4	X5R	22 μ	±20	10	150	1.25+0.15/-0.05	*1 ,*2
AMK212BBJ476MGHT		1 4	X5R	47 μ	±20	10	150	1.25+0.20/-0	*1 ,*2

[Temperature Characteristic BJ : X5R] 0.85mm thickness(D)

Part number 1	Part number 2	Rated voltage [V]	Temperature characteristics	Capacitance [F]	Capacitance tolerance [%]	tan δ [%]	HTLT Rated voltage x %	Thickness*3 [mm]	Note
EMK212 BJ105 DHT			X5R	1 μ	±10, ±20	5	200	0.85±0.10	*1 ,*2
EMK212ABJ225 DHT		16	X5R	2.2 μ	±10, ±20	5	150	0.85±0.10	*1 ,*2
EMK212BBJ475[]DHT			X5R	4.7 μ	±10, ±20	10	150	0.85±0.10	*1 ,*2

【Temperature Characteristic B7 : X7R】 1.25mm thickness(G)

Part number 1	Part number 2	Data danakana [V/]	Temperature	Capacitance	Capacitance	tan δ	HTLT	*3 []	N
Part number 1	Part number 2	Rated voltage [V]	characteristics	[F]	tolerance [%]	[%]	Rated voltage x %	Thickness*3 [mm]	Note
UMK212 B7103[]GHT			X7R	0.01 μ	±10, ±20	3.5	200	1.25±0.10	*1 ,*2
UMK212 B7223[]GHT			X7R	0.022 μ	±10, ±20	3.5	200	1.25±0.10	*1 ,*2
UMK212 B7473[]GHT		50	X7R	0.047 μ	±10, ±20	3.5	200	1.25±0.10	*1 ,*2
UMK212 B7104[]GHT		30	X7R	0.1 μ	±10, ±20	3.5	200	1.25±0.10	*1 ,*2
UMK212 B7224[]GHT			X7R	0.22 μ	±10, ±20	3.5	150	1.25±0.10	*1 ,*2
UMK212 B7105[]GHT			X7R	1 μ	±10, ±20	10	150	1.25±0.10	*1 ,*2
GMK212 B7224 GHT		35	X7R	0.22 μ	±10, ±20	3.5	150	1.25±0.10	*1 ,*2
GMK212 B7105[]GHT		33	X7R	1 μ	±10, ±20	10	150	1.25±0.10	*1 ,*2
TMK212 B7224 GHT			X7R	0.22 μ	±10, ±20	3.5	150	1.25±0.10	*1 ,*2
TMK212 B7474 GHT		25	X7R	0.47 μ	±10, ±20	3.5	150	1.25±0.10	*1 ,*2
TMK212 B7105 GHTR		2.5	X7R	1 μ	±10, ±20	10	150	1.25±0.10	*1 ,*2
TMK212 B7225 GHT			X7R	2.2 μ	±10, ±20	10	150	1.25±0.10	*1 ,*2
EMK212 B7224 GHT			X7R	0.22 μ	±10, ±20	3.5	150	1.25±0.10	*1 ,*2
EMK212 B7474 GHT			X7R	0.47 μ	±10, ±20	3.5	150	1.25±0.10	*1 ,*2
EMK212 B7105∏GHTR		16	X7R	1 μ	±10, ±20	10	150	1.25±0.10	*1 ,*2
EMK212 B7225 GHT			X7R	2.2 μ	±10, ±20	10	150	1.25±0.10	*1 ,*2
EMK212AB7475∏GHT			X7R	4.7 μ	±10, ±20	10	150	1.25+0.15/-0.05	*1 ,*2
LMK212 B7105 GHTR			X7R	1 μ	±10, ±20	10	150	1.25±0.10	*1 ,*2
LMK212 B7225 GHT		10	X7R	2.2 μ	±10, ±20	10	150	1.25±0.10	*1 ,*2
LMK212 B7475 GHT			X7R	4.7 μ	±10, ±20	10	150	1.25±0.10	*1 ,*2
JMK212AB7106∏GHT		6.3	X7R	10 μ	±10, ±20	10	150	1.25+0.15/-0.05	*1 ,*2

■316TYPE (Dimension:3.2 × 1.6mm JIS:3216 EIA:1206)

[Temperature Characteristic BJ : X5R] 1.6mm thickness (L)

Part number 1	Part number 2	Rated voltage [V]	Temperature	Capacitance	Capacitance	$ an\delta$	HTLT	Thickness*3 [mm]	Note
T art Humber T	T art number 2	Nated Voltage [V]	characteristics	[F]	tolerance [%]	[%]	Rated voltage x %	Thickness [mm]	Note
UMK316 BJ474[]LHT			X5R	0.47 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
UMK316 BJ105[LHT		50	X5R	1 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
UMK316 BJ225□LHT		30	X5R	2.2 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
UMK316ABJ475[]LHT			X5R	4.7 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
GMK316 BJ105[LHT			X5R	1 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
GMK316 BJ225 LHT		35	X5R	2.2 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
GMK316 BJ475□LHT		33	X5R	4.7 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
GMK316BBJ106MLHT			X5R	10 μ	±20	10	150	1.6±0.30	*1 ,*2
TMK316 BJ225□LHT			X5R	2.2 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
TMK316 BJ475 LHT		25	X5R	4.7 μ	±10, ±20	5	150	1.6±0.20	*1 ,*2
TMK316 BJ106□LHT			X5R	10 μ	±10, ±20	5	150	1.6±0.20	*1 ,*2
EMK316 BJ225□LHT			X5R	2.2 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
EMK316 BJ475 LHT		16	X5R	4.7 μ	±10, ±20	5	150	1.6±0.20	*1 ,*2
EMK316 BJ106□LHT		10	X5R	10 μ	±10, ±20	5	150	1.6±0.20	*1 ,*2
EMK316BBJ226MLHT			X5R	22 μ	±20	10	150	1.6±0.30	*1 ,*2
LMK316 BJ475□LHT			X5R	4.7 μ	±10, ±20	5	150	1.6±0.20	*1 ,*2
LMK316 BJ106□LHT		10	X5R	10 μ	±10, ±20	5	150	1.6±0.20	*1 ,*2
LMK316ABJ226□LHT			X5R	22 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
JMK316 BJ106□LHT			X5R	10 μ	±10, ±20	5	200	1.6±0.20	*1 ,*2
JMK316ABJ226□LHT		6.3	X5R	22 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
JMK316ABJ476MLHT		0.3	X5R	47 μ	±20	10	150	1.6±0.20	*1 ,*2
JMK316BBJ107MLHT			X5R	100 μ	±20	10	150	1.6±0.30	*2
AMK316ABJ107MLHT		4	X5R	100 μ	±20	10	150	1.6±0.20	*2

[▶] This catalog contains the typical specification only due to the limitation of space. When you consider the purchase of our products, please check our specification. For details of each product (characteristics graph, reliability information, precautions for use, and so on), see our website (http://www.ty-top.com/) .

[Temperature Characteristic B7 · X7R C7 · X7S] 1 6mm thickness(L)

Temperature Characteris	UC B7 : X/R , C7 : X/S]	1.0mm unickness(L)						
Part number 1	Part number 2	Rated voltage [V]	Temperature	Capacitance	Capacitance	tan δ	HTLT	Thickness*3 [mm]	Note
T di C Hambor T	T di t Hamboi 2	Nated Voltage [V]	characteristics	[F]	tolerance [%]	[%]	Rated voltage x %	THICKHESS [HIII]	14000
UMK316 B7473[]LHT			X7R	0.047 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
UMK316 B7104 LHT			X7R	0.1 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
UMK316 B7224 LHT		50	X7R	0.22 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
UMK316 B7474 LHT		30	X7R	0.47 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
UMK316 B7105[]LHT			X7R	1 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
UMK316 B7225 LHT			X7R	2.2 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
GMK316 B7105[]LHT			X7R	1 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
GMK316 B7225 LHT		35	X7R	2.2 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
GMK316AB7475[]LHT			X7R	4.7 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
TMK316 B7225[]LHT			X7R	2.2 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
TMK316AB7475[]LHT		25	X7R	4.7 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
TMK316AB7106[]LHT			X7R	10 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
EMK316 B7225 LHT			X7R	2.2 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
EMK316AB7475[]LHT		16	X7R	4.7 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
EMK316AB7106□LHT			X7R	10 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
LMK316 B7475 LHT		10	X7R	4.7 μ	±10, ±20	5	150	1.6±0.20	*1 ,*2
LMK316AB7106 LHT		10	X7R	10 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
JMK316AB7106□LHT		6.3	X7R	10 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
JMK316AB7226□LHT		0.3	X7R	22 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
AMK316AB7226 LHT		4	X7R	22 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
AMK316AC7476MLHT		7	X7S	47 μ	±20	10	150	1.6±0.20	*1 ,*2

325TYPE (Dimension:3.2 × 2.5mm JIS:3225 EIA:1210)

[Temperature Characteristic BJ : X5R] 2.5mm thickness (M)

Part number 1	Part number 2	Rated voltage [V]	Temperature	Capacitance	Capacitance	tan δ	HTLT	Thickness*3 [mm]	Note
rait ilulliber i	Fart number 2	Rated Voltage [V]	characteristics	[F]	tolerance [%]	[%]	Rated voltage x %	Inickness [mm]	Note
UMK325 BJ106 MHP	UMK325 BJ106∏MHT	50	X5R	10 μ	±10, ±20	5	150	2.5±0.20	*1 ,*2
GMK325 BJ106 MHP	GMK325 BJ106[MHT	35	X5R	10 μ	±10, ±20	5	150	2.5±0.20	*1 ,*2
TMK325 BJ106□MHP	TMK325 BJ106 MHT	25	X5R	10 μ	±10, ±20	5	150	2.5±0.20	*1 ,*2
EMK325 BJ226 MHP	EMK325 BJ226 MHT	16	X5R	22 μ	±10, ±20	5	150	2.5±0.20	*1 ,*2
EMK325ABJ476 MHP		10	X5R	47 μ	±10, ±20	5	150	2.5 ± 0.30	*1 ,*2
LMK325 BJ226□MHP	LMK325 BJ226 MHT		X5R	22 μ	±10, ±20	5	150	2.5 ± 0.20	*1 ,*2
LMK325 BJ476□MHP	LMK325 BJ476 MHT	10	X5R	47 μ	±10, ±20	10	150	2.5±0.20	*1 ,*2
LMK325ABJ107MMHP	LMK325ABJ107MMHT		X5R	100 μ	±20	10	150	2.5±0.30	*2
JMK325 BJ476∏MHP	JMK325 BJ476 MHT	6.3	X5R	47 μ	±10, ±20	10	150	2.5±0.20	*1 ,*2
JMK325ABJ107MMHP	JMK325ABJ107MMHT	0.5	X5R	100 μ	±20	10	150	2.5±0.30	*2
AMK325ABJ107MMHP	AMK325ABJ107MMHT	4	X5R	100 μ	±20	10	150	2.5±0.30	*2
AMK325ABJ227MMHP	AMK325ABJ227MMHT	4	X5R	220 μ	±20	10	150	2.5±0.30	*2

[Temperature Characteristic BJ : X5R] 1.9mm thickness(N)

Part number 1	Part number 2	Rated voltage [V]	Tempera		Capacitance	Capacitance	$ an\delta$	HTLT	Thickness*3 [mm]	Note
T art Humber 1	T art Humber 2	Nated Voltage [V]	characte	ristics	[F]	tolerance [%]	[%]	Rated voltage x %	Thickness [mm]	14016
UMK325 BJ475[NHT		50		X5R	4.7 μ	±10, ±20	10	150	1.9±0.20	*1 ,*2
GMK325 BJ225MNHT		35		X5R	2.2 μ	±20	3.5	200	1.9±0.20	*1 ,*2
GMK325 BJ475∏NHT		30		X5R	4.7 μ	±10, ±20	10	150	1.9±0.20	*1 ,*2
TMK325 BJ475□NHT		25		X5R	4.7 μ	±10, ±20	10	150	1.9±0.20	*1 ,*2
EMK325 BJ475MNHT		16		X5R	4.7 μ	±20	3.5	200	1.9±0.20	*1 ,*2
EMK325 BJ106□NHT		10		X5R	10 μ	±10, ±20	5	150	1.9±0.20	*1 ,*2

[Temperature Characteristic BJ : X5R] 1.5mm thickness(H)

Part number 1	Part number 2	Rated voltage [V]	Tempe charact	erature eristics	Capacitance [F]	Capacitance tolerance [%]	tan δ [%]	HTLT Rated voltage x %	Thickness*3 [mm]	Note
UMK325 BJ105MHHT		50		X5R	1 μ	±20	3.5	200	1.5±0.10	*1 ,*2
TMK325 BJ225MHHT		25		X5R	2.2 μ	±20	3.5	200	1.5±0.10	*1 ,*2

[Temperature Characteristic C6 : X6S] 2.5mm thickness (M)

Part number 1	Part number 2	Rated voltage [V]	Tempe charact	rature eristics	Capacitance [F]	Capacitance tolerance [%]	tan δ [%]	HTLT Rated voltage x %	Thickness*3 [mm]	Note
JMK325AC6107MMHP	JMK325AC6107MMHT	6.3		X6S	100 μ	±20	10	150	2.5±0.30	*2

 $\label{eq:continuous} \begin{tabular}{ll} \textbf{[} Temperature \ Characteristic \ B7: X7R \ , \ C7: X7S \end{tabular} \begin{tabular}{ll} 2.5mm \ thickness \end{tabular} \end{tabular}$

Part number 1	Part number 2	Rated voltage [V]	Tempe	rature	Capacitance	Capacitance	$ an\delta$	HTLT	Thickness*3 [mm]	Note
Fart number 1	Fart number 2	Nated Voltage [V]	charact	eristics	[F]	tolerance [%]	[%]	Rated voltage x %	Inickness [mm]	Note
UMK325 B7475[]MHP	UMK325 B7475[]MHT	50		X7R	4.7 μ	±10, ±20	5	150	2.5±0.20	*1 ,*2
UMK325AB7106[]MHP	UMK325AB7106 MHT	30		X7R	10 μ	±10, ±20	10	150	2.5±0.30	*1 ,*2
GMK325AB7106[]MHP		35		X7R	10 μ	±10, ±20	10	150	2.5±0.30	*1 ,*2
TMK325AB7106 MHPR	TMK325AB7106□MHTR	25		X7R	10 μ	±10, ±20	10	150	2.5±0.30	*1 ,*2
TMK325 B7226 MHP	TMK325 B7226 MHT	23		X7R	22 μ	±10, ±20	10	150	2.5±0.20	*1 ,*2
EMK325 B7226 MHP	EMK325 B7226[]MHT	16		X7R	22 μ	±10, ±20	10	150	2.5±0.20	*1 ,*2
LMK325 B7226 MHP		10		X7R	22 μ	±10, ±20	10	150	2.5±0.20	*1 ,*2
JMK325 B7226 ☐ MHPR	JMK325 B7226[]MHTR	6.3		X7R	22 μ	±10, ±20	10	150	2.5±0.20	*1 ,*2
JMK325 B7476 MHPR	JMK325 B7476 MHTR	0.5		X7R	47 μ	±10, ±20	10	150	2.5±0.20	*1 ,*2

[Temperature Characteristic B7 : X7R] 1.9mm thickness(N)

Part number 1	Part number 2	Rated voltage [V]	Temperati characteris		Capacitance [F]	Capacitance tolerance [%]	tan δ [%]	HTLT Rated voltage x %	Thickness*3 [mm]	Note
GMK325 B7225 NHT		35	>	X7R	2.2 μ	±10, ±20	3.5	200	1.9±0.20	*1 ,*2
GMK325 B7475MNHTR		33	>	X7R	4.7 μ	±20	10	150	1.9±0.20	*1 ,*2
TMK325 B7475∏NHT		25	>	X7R	4.7 μ	±10, ±20	10	150	1.9±0.20	*1 ,*2
EMK325 B7106 NHTR		16	>	X7R	10 μ	±10, ±20	5	150	1.9±0.20	*1 ,*2

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[Temperature Characteristic B7 : X7R] 1.5mm thickness(H)

Part number 1	Part number 2	Rated voltage [V]	Tempe charact	erature eristics	Capacitance [F]	Capacitance tolerance [%]	tan δ [%]	HTLT Rated voltage x %	Thickness*3 [mm]	Note
UMK325 B7105∏HHT		50		X7R	1 μ	±10, ±20	3.5	200	1.5±0.10	*1 ,*2

Multilayer Ceramic Capacitors (Temperature compensating type)

●063TYPE (Dimension:0.6 × 0.3mm JIS:0603 EIA:0201)

Part number 1	Part number 2	Rated voltage [V]		erature eristics	Capacitance [F]	Capacitance tolerance	Q [at 1MHz] (Min)	HTLT Rated voltage x %	Thickness*3 [mm]	Note
UMK063 CG0R5CTHF			CG	C0G	0.5 p	± 0.25pF	410	200	0.3 ± 0.03	*1 ,*2
UMK063 CG010CTHF			CG	COG	1 p	± 0.25pF	420	200	0.3 ± 0.03	*1 ,*2
UMK063 CG1R5CTHF			CG	COG	1.5 p	± 0.25pF	430	200	0.3 ± 0.03	*1 ,*2
UMK063 CG020CTHF			CG	COG	2 p	± 0.25pF	440	200	0.3 ± 0.03	*1 ,*2
UMK063 CG030CTHF			CG	COG	3 р	± 0.25pF	460	200	0.3 ± 0.03	*1 ,*2
UMK063 CG040CTHF			CG	COG	4 p	± 0.25pF	480	200	0.3 ± 0.03	*1 ,*2
UMK063 CG050CTHF			CG	COG	5 p	± 0.25pF	500	200	0.3 ± 0.03	*1 ,*2
UMK063 CG060DTHF			CG	COG	6 p	± 0.5pF	520	200	0.3 ± 0.03	*1 ,*2
UMK063 CG070DTHF			CG	C0G	7 p	± 0.5pF	540	200	0.3 ± 0.03	*1 ,*2
UMK063 CG080DTHF			CG	C0G	8 p	± 0.5pF	560	200	0.3 ± 0.03	*1 ,*2
UMK063 CG090DTHF			CG	C0G	9 р	± 0.5pF	580	200	0.3 ± 0.03	*1 ,*2
UMK063 CG100DTHF		50	CG	C0G	10 p	± 0.5pF	600	200	0.3 ± 0.03	*1 ,*2
UMK063 CG120JTHF		30	CG	C0G	12 p	± 5 %	640	200	0.3 ± 0.03	*1 ,*2
UMK063 CG150JTHF			CG	C0G	15 p	± 5 %	700	200	0.3 ± 0.03	*1 ,*2
UMK063 CG180JTHF			CG	C0G	18 p	± 5 %	760	200	0.3 ± 0.03	*1 ,*2
UMK063 CG220JTHF			CG	C0G	22 p	± 5 %	840	200	0.3 ± 0.03	*1 ,*2
UMK063 CG270JTHF			CG	C0G	27 p	± 5 %	940	200	0.3 ± 0.03	*1 ,*2
UMK063 CG330JTHF			CG	C0G	33 p	± 5 %	1000	200	0.3 ± 0.03	*1 ,*2
UMK063 CG390JTHF			CG	C0G	39 p	± 5 %	1000	200	0.3 ± 0.03	*1 ,*2
UMK063 CG470JTHF			CG	C0G	47 p	± 5 %	1000	200	0.3 ± 0.03	*1 ,*2
UMK063 CG560JTHF			CG	C0G	56 p	± 5 %	1000	200	0.3 ± 0.03	*1 ,*2
UMK063 CG680JTHF			CG	C0G	68 p	± 5 %	1000	200	0.3 ± 0.03	*1 ,*2
UMK063 CG820JTHF			CG	C0G	82 p	± 5 %	1000	200	0.3 ± 0.03	*1 ,*2
UMK063 CG101JTHF			CG	C0G	100 p	± 5 %	1000	200	0.3 ± 0.03	*1 ,*2
TMK063 CG121JTHF			CG	C0G	120 p	± 5 %	1000	200	0.3 ± 0.03	*1 ,*2
TMK063 CG151JTHF		25	CG	C0G	150 p	± 5 %	1000	200	0.3 ± 0.03	*1 ,*2
TMK063 CG181JTHF		2.5	CG	C0G	180 p	± 5 %	1000	200	0.3 ± 0.03	*1 ,*2
TMK063 CG221JTHF	·		CG	COG	220 p	± 5 %	1000	200	0.3 ± 0.03	*1 ,*2

● 105TYPE (Dimension:1.0 × 0.5mm JIS:1005 EIA:0402) [Temperature Characteristic CG: CG/C0G] 0.5mm thickness(V)

Temperature Characterist	ac CG : CG/COG 0.5	mm thickness(V)	T		Capacitance	Capacitance	Q	HTLT		
Part number 1	Part number 2	Rated voltage [V]		erature eristics	[F]	tolerance	[at 1MHz] (Min)	Rated voltage x %	Thickness*3 [mm]	Note
UMK105 CG0R5CVHF			CG	C0G	0.5 p	±0.25pF	410	200	0.5±0.05	*1 ,*2
UMK105 CG010CVHF		-	CG	COG	1 p	±0.25pF	420	200	0.5±0.05	*1.*2
UMK105 CG1R5CVHF		-	CG	COG	1.5 p	±0.25pF	430	200	0.5±0.05	*1.*2
UMK105 CG020CVHF		7	CG	C0G	2 p	±0.25pF	440	200	0.5±0.05	*1 ,*2
UMK105 CG030CVHF		∃	CG	COG	3 p	±0.25pF	460	200	0.5±0.05	*1 ,*2
UMK105 CG040CVHF		∃	CG	COG	4 p	±0.25pF	480	200	0.5±0.05	*1 ,*2
UMK105 CG050CVHF		∃	CG	COG	5 p	±0.25pF	500	200	0.5±0.05	*1 ,*2
UMK105 CG060DVHF		∃	CG	COG	6 p	±0.5pF	520	200	0.5±0.05	*1 ,*2
UMK105 CG070DVHF		-	CG	COG	7 p	±0.5pF	540	200	0.5±0.05	*1.*2
UMK105 CG080DVHF		-	CG	COG	8 p	±0.5pF	560	200	0.5±0.05	*1.*2
UMK105 CG090DVHF		7	CG	C0G	9 p	±0.5pF	580	200	0.5±0.05	*1 ,*2
UMK105 CG100DVHF		7 1	CG	COG	10 p	±0.5pF	600	200	0.5±0.05	*1 ,*2
UMK105 CG120JVHF		7	CG	C0G	12 p	±5%	640	200	0.5±0.05	*1 ,*2
UMK105 CG150JVHF		7	CG	C0G	15 p	±5%	700	200	0.5±0.05	*1 ,*2
UMK105 CG180JVHF		7	CG	C0G	18 p	±5%	760	200	0.5±0.05	*1 ,*2
UMK105 CG220JVHF		7	CG	C0G	22 p	±5%	840	200	0.5±0.05	*1 ,*2
UMK105 CG270JVHF		7	CG	C0G	27 p	±5%	940	200	0.5±0.05	*1 ,*2
UMK105 CG330JVHF		7	CG	C0G	33 p	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG390JVHF		7	CG	C0G	39 p	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG470JVHF		7	CG	C0G	47 p	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG560JVHF		50	CG	C0G	56 p	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG680JVHF		7	CG	C0G	68 p	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG820JVHF		7	CG	C0G	82 p	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG101JVHF		7	CG	C0G	100 p	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG121JVHF		7	CG	C0G	120 p	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG151JVHF		7	CG	C0G	150 p	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG181JVHF		7	CG	C0G	180 p	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG221JVHF		7 [CG	C0G	220 p	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG271JVHF		7 [CG	C0G	270 р	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG331JVHF		7 [CG	C0G	330 р	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG361JVHF		7 [CG	C0G	360 p	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG391JVHF			CG	C0G	390 р	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG431JVHF			CG	C0G	430 p	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG471JVHF			CG	C0G	470 p	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG511JVHF		_ [CG	C0G	510 р	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG561JVHF			CG	C0G	560 р	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG621JVHF		_ [CG	C0G	620 p	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG681JVHF		_ [CG	C0G	680 p	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG751JVHF		_ [CG	C0G	750 p	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG821JVHF		_ [CG	C0G	820 p	±5%	1000	200	0.5±0.05	*1 ,*2
UMK105 CG102JVHF			CG	C0G	1000 p	±5%	1000	200	0.5±0.05	*1 ,*2

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Medium-High Voltage Multilayer Ceramic Capacitors

■107TYPE (Dimension:1.6 × 0.8mm JIS:1608 EIA:0603)

[Temperature Characteristic B7 : X7R] 0.8mm thickness(A)

Part number 1	Part number 2	Rated voltage [V]	Temperature	Capacitance	Capacitance	tan δ	HTLT	Thickness*3 [mm]	Note
Fart number 1	Fart Humber 2	Nated Voltage [V]	characteristics	[F]	tolerance [%]	[%]	Rated voltage x %	Inickness [mm]	Note
HMK107 B7102□AHT			X7R	1000 p	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
HMK107 B7152 AHT			X7R	1500 p	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
HMK107 B7222 AHT			X7R	2200 p	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
HMK107 B7332□AHT			X7R	3300 p	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
HMK107 B7472 AHT			X7R	4700 p	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
HMK107 B7682□AHT		100	X7R	6800 p	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
HMK107 B7103[AHT		100	X7R	0.01 μ	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
HMK107 B7153[AHT			X7R	0.015 μ	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
HMK107 B7223[AHT			X7R	0.022 μ	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
HMK107 B7333∏AHT]	X7R	0.033 μ	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
HMK107 B7473 AHT]	X7R	0.047 μ	±10, ±20	3.5	200	0.8±0.10	*1 ,*2
HMK107 B7104∏AHT			X7R	0.1 μ	±10, ±20	3.5	200	0.8±0.10	*1 ,*2

212TYPE (Dimension:2.0 × 1.25mm JIS:2012 EIA:0805)

[Temperature Characteristic B7 : X7R] 1.25mm thickness(G)

Part number 1	Part number 2	Rated voltage [V]	Temperat	ture	Capacitance	Capacitance	tan δ	HTLT	Thickness*3 [mm]	Note
Part number 1	Part number 2	Rated Voltage [V]	characteri	istics	[F]	tolerance [%]	[%]	Rated voltage x %	Thickness [mm]	Note
HMK212 B7103 GHT				X7R	0.01 μ	±10, ±20	3.5	200	1.25±0.10	*1 ,*2
HMK212 B7153 GHT				X7R	0.015 μ	±10, ±20	3.5	200	1.25±0.10	*1 ,*2
HMK212 B7223 GHT				X7R	0.022 μ	±10, ±20	3.5	200	1.25±0.10	*1 ,*2
HMK212 B7333∏GHT		100		X7R	0.033 μ	±10, ±20	3.5	200	1.25±0.10	*1 ,*2
HMK212 B7473 GHT		100		X7R	0.047 μ	±10, ±20	3.5	200	1.25±0.10	*1 ,*2
HMK212 B7683∏GHT				X7R	0.068 μ	±10, ±20	3.5	200	1.25±0.10	*1 ,*2
HMK212 B7104 GHT				X7R	0.1 μ	±10, ±20	3.5	200	1.25±0.10	*1 ,*2
HMK212 B7224 GHT				X7R	0.22 μ	±10, ±20	3.5	200	1.25±0.10	*1 ,*2
QMK212 B7472 GHT				X7R	4700 p	±10, ±20	2.5	150	1.25±0.10	*1 ,*2
QMK212 B7682 GHT				X7R	6800 p	±10, ±20	2.5	150	1.25±0.10	*1 ,*2
QMK212 B7103[]GHT		250		X7R	0.01 μ	±10, ±20	2.5	150	1.25±0.10	*1 ,*2
QMK212 B7153[]GHT				X7R	0.015 μ	±10, ±20	2.5	150	1.25±0.10	*1 ,*2
QMK212 B7223[]GHT				X7R	0.022 μ	±10, ±20	2.5	150	1.25±0.10	*1 ,*2

[Temperature Characteristic B7 : X7R] 0.85mm thickness(D)

Part number 1	Part number 2	Rated voltage [V]	erature eristics	Capacitance [F]	Capacitance tolerance [%]	tan δ [%]	HTLT Rated voltage x %	Thickness*3 [mm]	Note
QMK212 B7102 DHT			X7R	1000 p	±10, ±20	2.5	150	0.85 ± 0.10	*1 ,*2
QMK212 B7152 DHT		250	X7R	1500 p	±10, ±20	2.5	150	0.85±0.10	*1 ,*2
QMK212 B7222 DHT		250	X7R	2200 p	±10, ±20	2.5	150	0.85±0.10	*1 ,*2
QMK212 B7332 DHT]	X7R	3300 p	±10, ±20	2.5	150	0.85 ± 0.10	*1 ,*2

316TYPE (Dimension:3.2 × 1.6mm JIS:3216 EIA:1206)

[Temperature Characteristic B7 : X7R] 1.6mm thickness(L)

Part number 1	Part number 2	Rated voltage [V]	Temperature	Capacitance	Capacitance	$ an\delta$	HTLT	Thickness*3 [mm]	Note
Fart number 1	Fart Humber 2	Rated voltage [v]	characteristics	[F]	tolerance [%]	[%]	Rated voltage x %	Inickness [mm]	Note
HMK316 B7473 LHT			X7R	0.047 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
HMK316 B7104□LHT			X7R	0.1 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
HMK316 B7154 LHT			X7R	0.15 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
HMK316 B7224 LHT		100	X7R	0.22 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
HMK316 B7334□LHT			X7R	0.33 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
HMK316 B7474□LHT			X7R	0.47 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
HMK316 B7105□LHT			X7R	1 μ	±10, ±20	3.5	200	1.6±0.20	*1 ,*2
QMK316 B7333 LHT			X7R	0.033 μ	±10, ±20	2.5	150	1.6±0.20	*1 ,*2
QMK316 B7473[]LHT		250	X7R	0.047 μ	±10, ±20	2.5	150	1.6±0.20	*1 ,*2
QMK316 B7683[]LHT		250	X7R	0.068 μ	±10, ±20	2.5	150	1.6±0.20	*1 ,*2
QMK316 B7104 LHT			X7R	0.1 μ	±10, ±20	2.5	150	1.6±0.20	*1 ,*2
SMK316 B7153[]LHT		630	X7R	0.015 μ	±10, ±20	2.5	120	1.6±0.20	*1 ,*2
SMK316 B7223[LHT		030	X7R	0.022 μ	±10, ±20	2.5	120	1.6±0.20	*1 ,*2

【Temperature Characteristic B7 : X7R】 1.15mm thickness(F)

Part number 1	Part number 2	Rated voltage [V]	Temperature		Capacitance	Capacitance	$ an\delta$	HTLT	Thickness*3 [mm]	Note
rart number i	Fart Humber 2	Nated Voltage [V]	characte	eristics	[F]	tolerance [%]	[%]	Rated voltage x %	Inickness [mm]	Note
SMK316 B7102[]FHT				X7R	1000 p	±10, ±20	2.5	120	1.15±0.10	*1 ,*2
SMK316 B7152 FHT				X7R	1500 p	±10, ±20	2.5	120	1.15±0.10	*1 ,*2
SMK316 B7222[]FHT				X7R	2200 p	±10, ±20	2.5	120	1.15±0.10	*1 ,*2
SMK316 B7332[]FHT		630		X7R	3300 р	±10, ±20	2.5	120	1.15±0.10	*1 ,*2
SMK316 B7472[]FHT				X7R	4700 p	±10, ±20	2.5	120	1.15±0.10	*1 ,*2
SMK316 B7682[FHT				X7R	6800 p	±10, ±20	2.5	120	1.15±0.10	*1 ,*2
SMK316 B7103[FHT				X7R	0.01 μ	±10, ±20	2.5	120	1.15±0.10	*1 ,*2

[▶] This catalog contains the typical specification only due to the limitation of space. When you consider the purchase of our products, please check our specification. For details of each product (characteristics graph, reliability information, precautions for use, and so on), see our website (http://www.ty-top.com/).

325TYPE (Dimension:3.2 × 2.5mm JIS:3225 EIA:1210)

Temperature Characteristic B7 : X7R 2.5mm thickness (M)

Li emperature Oriaracteria	CC D7 . X/IN 2.0IIIIII CIII	CKI1633 (IVI)								
Part number 1	Part number 2	Rated voltage [V]	Temper characte		Capacitance [F]	Capacitance tolerance [%]	tan δ [%]	HTLT Rated voltage x %	Thickness*3 [mm]	Note
HMK325 B7225∏MHP	HMK325 B7225∏MHT	100		X7R	2.2 11	±10. ±20	3.5	200	2.5 ± 0.20	*1.*2

[Temperature Characteristic B7 : X7R] 1.9mm thickness(N)

Part number 1	Part number 2	Rated voltage [V]	Temperature	Capacitance	Capacitance	$ an\delta$	HTLT	Thickness*3 [mm]	Note
Part number 1	Part number 2	Rated voltage [v]	characteristics	[F]	tolerance [%]	[%]	Rated voltage x %	Thickness [mm]	Note
HMK325 B7224[]NHT			X7R	0.22 μ	±10, ±20	3.5	200	1.9±0.20	*1 ,*2
HMK325 B7474[]NHT		100	X7R	0.47 μ	±10, ±20	3.5	200	1.9±0.20	*1 ,*2
HMK325 B7684□NHT		100	X7R	0.68 μ	±10, ±20	3.5	200	1.9±0.20	*1 ,*2
HMK325 B7105□NHT			X7R	1 μ	±10, ±20	3.5	200	1.9±0.20	*1 ,*2
QMK325 B7473[NHT			X7R	0.047 μ	±10, ±20	2.5	150	1.9±0.20	*1 ,*2
QMK325 B7104[]NHT		250	X7R	0.1 μ	±10, ±20	2.5	150	1.9±0.20	*1 ,*2
QMK325 B7154[]NHT		250	X7R	0.15 μ	±10, ±20	2.5	150	1.9±0.20	*1 ,*2
QMK325 B7224[]NHT			X7R	0.22 μ	±10, ±20	2.5	150	1.9±0.20	*1 ,*2
SMK325 B7223[NHT			X7R	0.022 μ	±10, ±20	2.5	120	1.9±0.20	*1 ,*2
SMK325 B7333 NHT		630	X7R	0.033 μ	±10, ±20	2.5	120	1.9±0.20	*1 ,*2
SMK325 B7473[NHT			X7R	0.047 μ	±10, ±20	2.5	120	1.9±0.20	*1 ,*2

[Temperature Characteristic B7 : X7R] 1.15mm thickness(F)

Part number 1	Part number 2	Rated voltage [V]	Tempe charact	erature eristics	Capacitance [F]	Capacitance tolerance [%]	tan δ [%]	HTLT Rated voltage x %	Thickness*3 [mm]	Note
HMK325 B7104∏FHT		100		X7R	0.1 μ	±10, ±20	3.5	200	1.15±0.10	*1 ,*2

432TYPE (Dimension:4.5 × 3.2mm JIS:4532 EIA:1812)

Temperature Characteristic B7 : X7R 2.5mm thickness(M)

Part number 1	Part number 2	Rated voltage [V]	Temperatu	re	Capacitance	Capacitance	tan δ	HTLT	Thickness*3 [mm]	Note
Fart number 1	Fart Humber 2	Nated Voltage [V]	characterist	ics	[F]	tolerance [%]	[%]	Rated voltage x %	Inickness [mm]	Note
HMK432 B7474[]MHT			X	7R	0.47 μ	±10, ±20	3.5	200	2.5±0.20	*1 ,*2
HMK432 B7105∏MHT		100	X	7R	1 μ	±10, ±20	3.5	200	2.5±0.20	*1 ,*2
HMK432 B7155[]MHT		100	X	7R	1.5 μ	±10, ±20	3.5	200	2.5±0.20	*1 ,*2
HMK432 B7225∏MHT			X	7R	2.2 μ	±10, ±20	3.5	200	2.5±0.20	*1 ,*2
QMK432 B7104[]MHT			X	7R	0.1 μ	±10, ±20	2.5	150	2.5±0.20	*1 ,*2
QMK432 B7224[]MHT		250	X	7R	0.22 μ	±10, ±20	2.5	150	2.5±0.20	*1 ,*2
QMK432 B7334[]MHT		230	X	7R	0.33 μ	±10, ±20	2.5	150	2.5±0.20	*1 ,*2
QMK432 B7474[]MHT			X	7R	0.47 μ	±10, ±20	2.5	150	2.5±0.20	*1 ,*2
SMK432 B7473[]MHT			X	7R	0.047 μ	±10, ±20	2.5	120	2.5±0.20	*1 ,*2
SMK432 B7683[]MHT		630	X	7R	0.068 μ	±10, ±20	2.5	120	2.5±0.20	*1 ,*2
SMK432 B7104[MHT			X	7R	0.1 μ	±10, ±20	2.5	120	2.5±0.20	*1 ,*2

[▶] This catalog contains the typical specification only due to the limitation of space. When you consider the purchase of our products, please check our specification. For details of each product (characteristics graph, reliability information, precautions for use, and so on), see our website (http://www.ty-top.com/) .

Medium-High Voltage Multilayer Ceramic Capacitors for High Frequency Applications

● 107TYPE (Dimension:1.6 × 0.8mm JIS:1608 EIA:0603) [Temperature Characteristic CG: CG/COG] 0.7mm thickness (C)

Temperature Characteristi	ic CG:CG/C0G] 0.7	mm thickness(C)								
Deat word on 1	Dt	Data danakan NA	Tempe	erature	Capacitance	Capacitance	Q	HTLT	*3 - 3	M.s.
Part number 1	Part number 2	Rated voltage [V]	charact	teristics	[F]	tolerance	[at 1MHz] (Min)	Rated voltage x %	Thickness*3 [mm]	Note
QVS107 CG0R5∏CHT			CG	COG	0.5 p	± 0.1pF,± 0.25pF	810	200	0.7±0.10	*2
QVS107 CG0R6[]CHT			CG	COG	0.6 p	± 0.1pF,± 0.25pF	812	200	0.7±0.10	*2
QVS107 CG0R7[]CHT			CG	COG	0.7 p	± 0.1pF,± 0.25pF	814	200	0.7±0.10	*2
QVS107 CGR75[]CHT			CG	COG	0.75 p	± 0.1pF,± 0.25pF	815	200	0.7±0.10	*2
QVS107 CG0R8∏CHT			CG	COG	0.8 p	± 0.1pF,± 0.25pF	816	200	0.7±0.10	*2
QVS107 CG0R9[CHT			CG	COG	0.9 p	± 0.1pF,± 0.25pF	818	200	0.7±0.10	*2
QVS107 CG010 CHT			CG	COG	1 p	± 0.1pF,± 0.25pF	820	200	0.7±0.10	*2
QVS107 CG1R1[]CHT			CG	COG	1.1 p	± 0.1pF,± 0.25pF	822	200	0.7±0.10	*2
QVS107 CG1R2[]CHT			CG	COG	1.2 p	± 0.1pF,± 0.25pF	824	200	0.7±0.10	*2
QVS107 CG1R3[]CHT			CG	COG	1.3 p	± 0.1pF,± 0.25pF	826	200	0.7±0.10	*2
QVS107 CG1R5[]CHT			CG	COG	1.5 p	± 0.1pF,± 0.25pF	830	200	0.7±0.10	*2
QVS107 CG1R6[CHT			CG	COG	1.6 p	± 0.1pF,± 0.25pF	832	200	0.7±0.10	*2
QVS107 CG1R8[]CHT			CG	COG	1.8 p	± 0.1pF,± 0.25pF	836	200	0.7±0.10	*2
QVS107 CG020 CHT			CG	C0G	2 p	± 0.1pF,± 0.25pF	840	200	0.7±0.10	*2
QVS107 CG2R2[]CHT			CG	COG	2.2 p	± 0.1pF,± 0.25pF	844	200	0.7±0.10	*2
QVS107 CG2R4[]CHT			CG	C0G	2.4 p	± 0.1pF,± 0.25pF	848	200	0.7±0.10	*2
QVS107 CG2R7[]CHT			CG	COG	2.7 p	± 0.1pF,± 0.25pF	854	200	0.7±0.10	*2
QVS107 CG030∏CHT			CG	C0G	3 p	± 0.1pF,± 0.25pF	860	200	0.7±0.10	*2
QVS107 CG3R3[]CHT			CG	COG	3.3 p	± 0.1pF,± 0.25pF	866	200	0.7±0.10	*2
QVS107 CG3R6[]CHT			CG	C0G	3.6 p	± 0.1pF,± 0.25pF	872	200	0.7±0.10	*2
QVS107 CG3R9[]CHT			CG	C0G	3.9 p	± 0.1pF,± 0.25pF	878	200	0.7±0.10	*2
QVS107 CG4R3[]CHT			CG	C0G	4.3 p	\pm 0.1pF, \pm 0.25pF	886	200	0.7±0.10	*2
QVS107 CG4R7[]CHT			CG	C0G	4.7 p	\pm 0.1pF, \pm 0.25pF	894	200	0.7±0.10	*2
QVS107 CG5R1[]CHT			CG	C0G	5.1 p	$\pm 0.25 pF, \pm 0.5 pF$	902	200	0.7±0.10	*2
QVS107 CG5R6[CHT			CG	C0G	5.6 p	\pm 0.25pF, \pm 0.5pF	912	200	0.7±0.10	*2
QVS107 CG6R2[CHT			CG	C0G	6.2 p	\pm 0.25pF, \pm 0.5pF	924	200	0.7±0.10	*2
QVS107 CG6R8[CHT		250	CG	C0G	6.8 p	$\pm 0.25 pF, \pm 0.5 pF$	936	200	0.7±0.10	*2
QVS107 CG7R5∏CHT			CG	C0G	7.5 p	$\pm 0.25 pF, \pm 0.5 pF$	950	200	0.7±0.10	*2
QVS107 CG8R2[CHT			CG	COG	8.2 p	\pm 0.25pF, \pm 0.5pF	964	200	0.7±0.10	*2
QVS107 CG100∏CHT			CG	COG	10 p	± 2 %,± 5 %	1000	200	0.7±0.10	*2
QVS107 CG110JCHT			CG	COG	11 p	± 5 %	1020	200	0.7±0.10	*2
QVS107 CG120JCHT			CG	COG	12 p	± 5 %	1040	200	0.7±0.10	*2
QVS107 CG130JCHT			CG	C0G	13 p	± 5 %	1060	200	0.7±0.10	*2
QVS107 CG150JCHT			CG	C0G	15 p	± 5 %	1100	200	0.7±0.10	*2
QVS107 CG160JCHT			CG	C0G	16 p	± 5 %	1120	200	0.7±0.10	*2
QVS107 CG180JCHT			CG	C0G	18 p	± 5 %	1160	200	0.7±0.10	*2
QVS107 CG200JCHT		_	CG	COG	20 p	± 5 %	1200	200	0.7±0.10	*2
QVS107 CG220JCHT		4	CG	C0G	22 p	± 5 %	1240	200	0.7±0.10	*2
QVS107 CG240JCHT		4	CG CG	C0G C0G	24 p	± 5 %	1280 1340	200	0.7±0.10	*2 *2
QVS107 CG270JCHT		4	CG	COG	27 p	± 5 % ± 5 %	1340	200 200	0.7±0.10 0.7±0.10	*2 *2
QVS107 CG300JCHT		4			30 p					*2
QVS107 CG330JCHT QVS107 CG360JCHT		4	CG	C0G C0G	33 p 36 p	± 5 % ± 5 %	1400 1400	200 200	0.7±0.10 0.7±0.10	*2
QVS107 CG390JCHT		_	CG	COG	_	_	1400	200	0.7±0.10 0.7±0.10	*2
QVS107 CG390JCHT QVS107 CG430JCHT		4	CG	COG	39 p 43 p	± 5 % ± 5 %	1400	200	0.7±0.10 0.7±0.10	*2
QVS107 CG430JCHT QVS107 CG470JCHT		4	CG	COG	43 p 47 p	± 5 %	1400	200	0.7±0.10 0.7±0.10	*2
QVS107 CG470JCH1 QVS107 CG510JCHT		Ⅎ	CG	COG	47 p 51 p	± 5 %	1400	200	0.7±0.10 0.7±0.10	*2
QVS107 CG510JCHT QVS107 CG560JCHT		4	CG	COG	51 p	± 5 %	1400	200	0.7±0.10 0.7±0.10	*2
QVS107 CG560JCHT QVS107 CG620JCHT		Ⅎ	CG	COG	62 p	± 5 %	1400	200	0.7±0.10 0.7±0.10	*2 *2
QVS107 CG620JCHT		Ⅎ	CG	COG	62 p	± 5 %	1400	200	0.7±0.10 0.7±0.10	*2 *2
QVS107 CG680JCHT QVS107 CG750JCHT		Ⅎ	CG	COG	75 p	± 5 %	1400	200	0.7±0.10 0.7±0.10	*2 *2
QVS107 CG750JCHT QVS107 CG820JCHT		Ⅎ	CG	COG	75 p 82 p	± 5 %	1400	200	0.7±0.10 0.7±0.10	*2
QVS107 CG820JCHT QVS107 CG910JCHT		Ⅎ	CG	COG	82 p 91 p	± 5 %	1400	200	0.7±0.10 0.7±0.10	*2 *2
QVS107 CG9103CH1		Ⅎ	CG	COG	100 p	± 5 %	1400	200	0.7±0.10 0.7±0.10	*2
WASIAL CRIMINOUL		<u> </u>	UG	CUG	100 β		1400	200	0.7 ± 0.10	* Z

212TYPE (Dimension:2.0 × 1.25mm JIS:2012 EIA:0805)

[Temperature Characteristic CG : CG/C0G] 0.85mm thickness(D)

Part number 1	Part number 2	Rated voltage [V]	Tempe	rature	Capacitance	Capacitance	Q [at 1MHz]	HTLT	Thickness*3 [mm]	Note
	Fart Humber 2	Nated Voltage [V]	charact	eristics	[F]	tolerance	(Min)	Rated voltage x %	Inickness [mm]	Note
QVS212 CG0R5[]DHT			CG	C0G	0.5 p	\pm 0.1pF, \pm 0.25pF	810	200	0.85 ± 0.10	*2
QVS212 CG0R6 DHT			CG	C0G	0.6 p	\pm 0.1pF, \pm 0.25pF	812	200	0.85 ± 0.10	*2
QVS212 CG0R7 DHT			CG	C0G	0.7 p	\pm 0.1pF, \pm 0.25pF	814	200	0.85 ± 0.10	*2
QVS212 CG0R9 DHT			CG	C0G	0.9 p	\pm 0.1pF, \pm 0.25pF	818	200	0.85 ± 0.10	*2
QVS212 CG2R2[]DHT			CG	COG	2.2 p	\pm 0.1pF, \pm 0.25pF	844	200	0.85±0.10	*2
QVS212 CG2R7[DHT			CG	COG	2.7 p	\pm 0.1pF, \pm 0.25pF	854	200	0.85±0.10	*2
QVS212 CG3R3[DHT			CG	COG	3.3 p	\pm 0.1pF, \pm 0.25pF	866	200	0.85±0.10	*2
QVS212 CG4R7 DHT			CG	COG	4.7 p	\pm 0.1pF, \pm 0.25pF	894	200	0.85±0.10	*2
QVS212 CG6R2□DHT			CG	COG	6.2 p	\pm 0.25pF, \pm 0.5pF	924	200	0.85±0.10	*2
QVS212 CG8R2 DHT			CG	COG	8.2 p	\pm 0.25pF, \pm 0.5pF	964	200	0.85±0.10	*2
QVS212 CG9R1□DHT			CG	COG	9.1 p	\pm 0.25pF, \pm 0.5pF	982	200	0.85±0.10	*2
QVS212 CG100JDHT		250	CG	COG	10 p	± 5 %	1000	200	0.85±0.10	*2
QVS212 CG150JDHT			CG	COG	15 p	± 5 %	1100	200	0.85±0.10	*2
QVS212 CG180JDHT			CG	COG	18 p	± 5 %	1160	200	0.85±0.10	*2
QVS212 CG220JDHT			CG	COG	22 p	± 5 %	1240	200	0.85±0.10	*2
QVS212 CG270JDHT			CG	COG	27 p	± 5 %	1340	200	0.85 ± 0.10	*2
QVS212 CG300JDHT			CG	C0G	30 p	± 5 %	1400	200	0.85±0.10	*2
QVS212 CG330JDHT			CG	C0G	33 p	± 5 %	1400	200	0.85±0.10	*2
QVS212 CG390JDHT	·]	CG	C0G	39 p	± 5 %	1400	200	0.85±0.10	*2
QVS212 CG470JDHT		1	CG	COG	47 p	± 5 %	1400	200	0.85±0.10	*2
QVS212 CG560JDHT		1	CG	COG	56 p	± 5 %	1400	200	0.85±0.10	*2
QVS212 CG620JDHT		1	CG	COG	62 p	± 5 %	1400	200	0.85±0.10	*2
QVS212 CG101JDHT		1	CG	C0G	100 p	± 5 %	1400	200	0.85±0.10	*2

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Soft Termination Multilayer Ceramic Capacitors

■107TYPE (Dimension:1.6 × 0.8mm JIS:1608 EIA:0603)

[Temperature Characteristic B7 : X7R] 0.8mm thickness(A)

Part number 1	Part number 2	Rated voltage [V]	Temperature characteristics	Capacitance [F]	Capacitance tolerance [%]	tan δ [%]	HTLT Rated voltage x %	Thickness*3 [mm]	Note
TMJ107BB7473[]AHT			X7R	0.047 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1 ,*2
TMJ107BB7104[]AHT			X7R	0.1 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1 ,*2
TMJ107BB7224[]AHT		25	X7R	0.22 μ	±10, ±20	10	150	0.8+0.20/-0	*1 ,*2
TMJ107BB7474[]AHT			X7R	0.47 μ	±10, ±20	10	150	0.8+0.20/-0	*1 ,*2
TMJ107CB7105[AHR			X7R	1 μ	±10, ±20	10	150	0.8+0.25/-0	*1 ,*2
GMJ107BB7473[]AHT			X7R	0.047 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1 ,*2
GMJ107BB7104[]AHT			X7R	0.1 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1 ,*2
GMJ107BB7224□AHT		35	X7R	0.22 μ	±10, ±20	10	150	0.8+0.20/-0	*1 ,*2
GMJ107BB7474[]AHT			X7R	0.47 μ	±10, ±20	10	150	0.8+0.20/-0	*1 ,*2
GMJ107CB7105∏AHR			X7R	1 μ	±10, ±20	10	150	0.8+0.25/-0	*1 ,*2
UMJ107AB7102∏AHT			X7R	1000 p	±10, ±20	3.5	200	0.8+0.15/-0.05	*1 ,*2
UMJ107AB7222 AHT			X7R	2200 p	±10, ±20	3.5	200	0.8+0.15/-0.05	*1 ,*2
UMJ107BB7472 AHT			X7R	4700 p	±10, ±20	3.5	200	0.8+0.20/-0	*1 ,*2
UMJ107BB7103∏AHT		50	X7R	0.01 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1 ,*2
UMJ107BB7223∏AHT			X7R	0.022 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1 ,*2
UMJ107BB7473∏AHT			X7R	0.047 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1 ,*2
UMJ107BB7104∏AHT			X7R	0.1 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1 ,*2
HMJ107AB7102□AHT			X7R	1000 p	±10, ±20	3.5	200	0.8+0.15/-0.05	*1 ,*2
HMJ107AB7222□AHT			X7R	2200 p	±10, ±20	3.5	200	0.8+0.15/-0.05	*1 ,*2
HMJ107BB7472∏AHT			X7R	4700 p	±10, ±20	3.5	200	0.8+0.20/-0	*1 ,*2
HMJ107BB7103∏AHT		100	X7R	0.01 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1 ,*2
HMJ107BB7223∏AHT			X7R	0.022 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1 ,*2
HMJ107BB7473∏AHT			X7R	0.047 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1 ,*2
HMJ107BB7104 AHT			X7R	0.1 μ	±10, ±20	3.5	200	0.8+0.20/-0	*1 ,*2

212TYPE (Dimension:2.0 × 1.25mm JIS:2012 EIA:0805)

Temperature Characterist			Ta man a washi wa	Capacitance	Capacitance	tan δ	HTLT		
Part number 1	Part number 2	Rated voltage [V]	characteristics	[F]	tolerance [%]	[%]	Rated voltage x %	Thickness*3 [mm]	Note
JMJ212CB7106∏GHT		6.3	X7R	10 μ	±10, ±20	10	150	1.25+0.25/-0	*1 ,*2
EMJ212CB7225 GHT		16	X7R	2.2 μ	±10, ±20	10	150	1.25+0.25/-0	*1 ,*2
EMJ212CB7475 GHT		10	X7R	4.7 μ	±10, ±20	10	150	1.25+0.25/-0	*1 ,*2
TMJ212CB7225[]GHT		25	X7R	2.2 μ	±10, ±20	10	150	1.25+0.25/-0	*1 ,*2
GMJ212CB7105 GHT		35	X7R	1 μ	±10, ±20	10	150	1.25+0.25/-0	*1 ,*2
UMJ212BB7103[]GHT			X7R	0.01 μ	±10, ±20	2.5	200	1.25+0.20/-0	*1 ,*2
UMJ212BB7223[]GHT		50	X7R	0.022 μ	±10, ±20	2.5	200	1.25+0.20/-0	*1 ,*2
UMJ212BB7473[]GHT		50	X7R	0.047 μ	±10, ±20	3.5	200	1.25+0.20/-0	*1 ,*2
UMJ212BB7104[]GHT			X7R	0.1 μ	±10, ±20	3.5	200	1.25+0.20/-0	*1 ,*2
UMJ212CB7105[]GHT			X7R	1 μ	±10, ±20	10	150	1.25+0.25/-0	*1 ,*2
HMJ212KB7102 DHT			X7R	1000 p	±10, ±20	2.5	200	0.85±0.15	*1 ,*2
HMJ212KB7222[]DHT			X7R	2200 p	±10, ±20	2.5	200	0.85 ± 0.15	*1 ,*2
HMJ212BB7472[]GHT			X7R	4700 p	±10, ±20	2.5	200	1.25+0.20/-0	*1 ,*2
HMJ212BB7103[]GHT		100	X7R	0.01 μ	±10, ±20	2.5	200	1.25+0.20/-0	*1 ,*2
HMJ212BB7223[]GHT		100	X7R	0.022 μ	±10, ±20	3.5	200	1.25+0.20/-0	*1 ,*2
HMJ212BB7473[]GHT			X7R	0.047 μ	±10, ±20	3.5	200	1.25+0.20/-0	*1 ,*2
HMJ212BB7104[]GHT			X7R	0.1 μ	±10, ±20	3.5	200	1.25+0.20/-0	*1 ,*2
HMJ212BB7224[]GHT			X7R	0.22 μ	±10, ±20	3.5	200	1.25+0.20/-0	*1 ,*2
QMJ212KB7102DHT			X7R	1000 p	±10, ±20	2.5	150	0.85±0.15	*1 ,*2
QMJ212KB7222 DHT			X7R	2200 p	±10, ±20	2.5	150	0.85±0.15	*1 ,*2
QMJ212BB7472[]GHT		250	X7R	4700 p	±10, ±20	2.5	150	1.25+0.20/-0	*1 ,*2
QMJ212BB7103[]GHT			X7R	0.01 μ	±10, ±20	2.5	150	1.25+0.20/-0	*1 ,*2
QMJ212BB7223[]GHT			X7R	0.022 μ	±10, ±20	2.5	150	1.25+0.20/-0	*1 ,*2

●316TYPE (Dimension:3.2 × 1.6mm JIS:3216 EIA:1206)

Temperature Characterist	tic B7 : X7R] 1.15mm th	ickness(F),1.6mm	thickness(L)						
Deat words of	Dt	D . I II D4	Temperature	Capacitance	Capacitance	tan δ	HTLT	*3 - 3	N
Part number 1	Part number 2	Rated voltage [V]	characteristics	[F]	tolerance [%]	[%]	Rated voltage x %	Thickness*3 [mm]	Note
LMJ316BB7226[]LHT		10	X7R	22 μ	±10, ±20	10	150	1.6±0.30	*1 ,*2
EMJ316BB7475 LHT		16	X7R	4.7 μ	±10, ±20	10	150	1.6±0.30	*1 ,*2
EMJ316BB7106 LHT		10	X7R	10 μ	±10, ±20	10	150	1.6±0.30	*1 ,*2
TMJ316BB7474 LHT			X7R	0.47 μ	±10, ±20	3.5	200	1.6±0.30	*1 ,*2
TMJ316BB7475 LHT		25	X7R	4.7 μ	±10, ±20	10	150	1.6±0.30	*1 ,*2
TMJ316BB7106□LHT			X7R	10 μ	±10, ±20	10	150	1.6±0.30	*1 ,*2
GMJ316BB7474[LHT			X7R	0.47 μ	±10, ±20	3.5	200	1.6±0.30	*1 ,*2
GMJ316AB7225[]LHT		35	X7R	2.2 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
GMJ316BB7475[]LHT		30	X7R	4.7 μ	±10, ±20	10	150	1.6±0.30	*1 ,*2
GMJ316BB7106 LHT			X7R	10 μ	±10, ±20	10	150	1.6±0.30	*1 ,*2
UMJ316BB7473 LHT			X7R	0.047 μ	±10, ±20	2.5	200	1.6±0.30	*1 ,*2
UMJ316BB7104□LHT			X7R	0.1 μ	±10, ±20	3.5	200	1.6±0.30	*1 ,*2
UMJ316BB7224 LHT		50	X7R	0.22 μ	±10, ±20	3.5	200	1.6±0.30	*1 ,*2
UMJ316BB7474 LHT		30	X7R	0.47 μ	±10, ±20	3.5	200	1.6±0.30	*1 ,*2
UMJ316BB7105□LHT			X7R	1 μ	±10, ±20	3.5	200	1.6±0.30	*1 ,*2
UMJ316AB7225□LHT			X7R	2.2 μ	±10, ±20	10	150	1.6±0.20	*1 ,*2
HMJ316 B7102∏FHT			X7R	1000 p	±10, ±20	2.5	200	1.15±0.10	*1 ,*2
HMJ316 B7222∏FHT			X7R	2200 p	±10, ±20	2.5	200	1.15±0.10	*1 ,*2
HMJ316 B7472∏FHT			X7R	4700 p	±10, ±20	2.5	200	1.15±0.10	*1 ,*2
HMJ316KB7103∏FHT			X7R	0.01 μ	±10, ±20	2.5	200	1.15±0.20	*1 ,*2
HMJ316BB7223□LHT		100	X7R	0.022 μ	±10, ±20	2.5	200	1.6±0.30	*1 ,*2
HMJ316BB7473∏LHT		100	X7R	0.047 μ	±10, ±20	2.5	200	1.6±0.30	*1 ,*2
HMJ316BB7104□LHT			X7R	0.1 μ	±10, ±20	2.5	200	1.6±0.30	*1 ,*2
HMJ316BB7224□LHT			X7R	0.22 μ	±10, ±20	3.5	200	1.6±0.30	*1 ,*2
HMJ316BB7474□LHT]	X7R	0.47 μ	±10, ±20	3.5	200	1.6±0.30	*1 ,*2
HMJ316BB7105[]LHT			X7R	1 μ	±10, ±20	3.5	200	1.6±0.30	*1 ,*2

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Part number 1	Part number 2	Rated voltage [V]	Tempe	erature	Capacitance	Capacitance	tan δ	HTLT	Thickness*3 [mm]	Note
Part number 1	Part number 2	Rated voitage [v]	charact	eristics	[F]	tolerance [%]	[%]	Rated voltage x %	Inickness [mm]	Note
QMJ316 B7102[]FHT				X7R	1000 p	±10, ±20	2.5	150	1.15±0.10	*1 ,*2
QMJ316 B7222[]FHT				X7R	2200 p	±10, ±20	2.5	150	1.15±0.10	*1 ,*2
QMJ316 B7472[]FHT				X7R	4700 p	±10, ±20	2.5	150	1.15±0.10	*1 ,*2
QMJ316KB7103[]FHT		250		X7R	0.01 μ	±10, ±20	2.5	150	1.15±0.20	*1 ,*2
QMJ316BB7223[]LHT				X7R	0.022 μ	±10, ±20	2.5	150	1.6±0.30	*1 ,*2
QMJ316BB7473[]LHT				X7R	0.047 μ	±10, ±20	2.5	150	1.6±0.30	*1 ,*2
QMJ316BB7104[]LHT				X7R	0.1 μ	±10, ±20	2.5	150	1.6±0.30	*1 ,*2
SMJ316 B7102□FHT				X7R	1000 p	±10, ±20	2.5	120	1.15±0.10	*1 ,*2
SMJ316 B7222 FHT				X7R	2200 p	±10, ±20	2.5	120	1.15±0.10	*1 ,*2
SMJ316 B7472□FHT		630		X7R	4700 p	±10, ±20	2.5	120	1.15±0.10	*1 ,*2
SMJ316KB7103[FHT				X7R	0.01 μ	±10, ±20	2.5	120	1.15±0.20	*1 ,*2
SMJ316BB7223 LHT				X7R	0.022 μ	±10, ±20	2.5	120	1.6±0.30	*1 ,*2

325TYPE (Dimension:3.2 × 2.5mm JIS:3225 EIA:1210)

[Temperature Characteristic B7 : X7R] 1.9mm thickness(N), 2.5mm thickness(M)

Part number 1	Part number 2	Rated voltage [V]	Temperature	Capacitance	Capacitance	tan δ	HTLT	Thickness*3 [mm]	Note
T art number 1	Tarc Humber 2	Nated Voltage [V]	characteristics	[F]	tolerance [%]	[%]	Rated voltage x %	Thickness [mm]	14006
JMJ325KB7476∏MHP	JMJ325KB7476[]MHT	6.3	X7R	47 μ	±10, ±20	10	150	2.5±0.30	*1 ,*2
EMJ325KB7226□MHP	EMJ325KB7226 MHT	16	X7R	22 μ	±10, ±20	10	150	2.5±0.30	*1 ,*2
TMJ325AB7475 MHP	TMJ325AB7475[MHT	25	X7R	4.7 μ	±10, ±20	2.5	150	2.5±0.30	*1 ,*2
TMJ325KB7106□MHP	TMJ325KB7106☐MHT	20	X7R	10 μ	±10, ±20	10	150	2.5±0.30	*1 ,*2
GMJ325AB7475[MHP	GMJ325AB7475[MHT	35	X7R	4.7 μ	±10, ±20	2.5	150	2.5±0.30	*1 ,*2
GMJ325KB7106 MHP	GMJ325KB7106□MHT	00	X7R	10 μ	±10, ±20	10	150	2.5±0.30	*1 ,*2
UMJ325AB7225[MHP	UMJ325AB7225[MHT		X7R	2.2 μ	±10, ±20	3.5	200	2.5±0.30	*1 ,*2
UMJ325AB7475 MHP	UMJ325AB7475[MHT	50	X7R	4.7 μ	±10, ±20	2.5	150	2.5±0.30	*1 ,*2
UMJ325KB7106 MHP	UMJ325KB7106∏MHT		X7R	10 μ	±10, ±20	10	150	2.5±0.30	*1 ,*2
HMJ325 B7223[NHT			X7R	0.022 μ	±10, ±20	2.5	200	1.9±0.20	*1 ,*2
HMJ325 B7473[NHT			X7R	0.047 μ	±10, ±20	2.5	200	1.9±0.20	*1 ,*2
HMJ325 B7104[]NHT			X7R	0.1 μ	±10, ±20	2.5	200	1.9±0.20	*1 ,*2
HMJ325 B7224[NHT		100	X7R	0.22 μ	±10, ±20	2.5	200	1.9±0.20	*1 ,*2
HMJ325 B7474[NHT			X7R	0.47 μ	±10, ±20	3.5	200	1.9±0.20	*1 ,*2
HMJ325 B7105□NHT			X7R	1 μ	±10, ±20	3.5	200	1.9±0.20	*1 ,*2
HMJ325AB7225 MHP	HMJ325AB7225 MHT		X7R	2.2 μ	±10, ±20	3.5	200	2.5±0.30	*1 ,*2
QMJ325 B7223[NHT			X7R	0.022 μ	±10, ±20	2.5	150	1.9±0.20	*1 ,*2
QMJ325 B7473[NHT		250	X7R	0.047 μ	±10, ±20	2.5	150	1.9±0.20	*1 ,*2
QMJ325 B7104[NHT		230	X7R	0.1 μ	±10, ±20	2.5	150	1.9±0.20	*1 ,*2
QMJ325 B7224[NHT			X7R	0.22 μ	±10, ±20	2.5	150	1.9±0.20	*1 ,*2
SMJ325 B7223 NHT		630	X7R	0.022 μ	±10, ±20	2.5	120	1.9±0.20	*1 ,*2
SMJ325 B7473[NHT		030	X7R	0.047 μ	±10, ±20	2.5	120	1.9±0.20	*1 ,*2

LW Reversal Decoupling Capacitors (LWDCTM)

■105TYPE (Dimension:0.52 × 1.0mm JIS:0510 EIA:0204)

[Temperature Characteristic BJ : X5R] 0.3mm thickness(P)

Part number 1	Part number 2	Rated voltage [V]	Tempe	rature	Capacitance	Capacitance	tan δ	HTLT	Th::*3 []	Note
rart number i	Fart Humber 2	Rated voltage [v]	charact	eristics	[F]	tolerance [%]	[%]	Rated voltage x %	Thickness [mm]	Note
TWK105 BJ104MPHF		25		X5R	0.1 μ	±20	5	150	0.3±0.05	*1 ,*2
EWK105 BJ224MPHF		16		X5R	0.22 μ	±20	10	150	0.3±0.05	*1 ,*2
LWK105 BJ474MPHF		10		X5R	0.47 μ	±20	10	150	0.3±0.05	*1 ,*2
AWK105 BJ105MPHF		4		X5R	1 μ	±20	10	150	0.3±0.05	*1 ,*2

 $\begin{tabular}{c} \textbf{[Temperature Characteristic C6: X6S, C7: X7S]} & 0.3mm thickness(P) \\ \end{tabular}$

Part number 1	Part number 2	Rated voltage [V]	Temperature	Capacitance	Capacitance	tan δ	HTLT	Thickness*3 [mm]	Note
T art Humber 1	1 art number 2	Nated Voltage [V]	characteristics	[F]	tolerance [%]	[%]	Rated voltage x %	Thickness [mm]	Note
EWK105 C6104MPHF		16	X6S	0.1 μ	±20	5	150	0.3±0.05	*1 ,*2
LWK105 C7104MPHF		10	X7S	0.1 μ	±20	5	150	0.3±0.05	*1 ,*2
LWK105 C6224MPHF		10	X6S	0.22 μ	±20	10	150	0.3±0.05	*1 ,*2
JWK105 C7104MPHF			X7S	0.1 μ	±20	5	150	0.3±0.05	*1 ,*2
JWK105 C7224MPHF		6.3	X7S	0.22 μ	±20	10	150	0.3±0.05	*1 ,*2
JWK105 C6474MPHF			X6S	0.47 μ	±20	10	150	0.3±0.05	*1 ,*2
AWK105 C7224MPHF		4	X7S	0.22 μ	±20	10	150	0.3±0.05	*1 ,*2
AWK105 C6474MPHF		4	X6S	0.47 μ	±20	10	150	0.3 ± 0.05	*1 ,*2

●107TYPE (Dimension:0.8 × 1.6mm JIS:0816 EIA:0306)

[Temperature Characteristic BJ : X5R] 0.5mm thickness(V)

Part number 1	Part number 2	Rated voltage [V]	Tempe	erature	Capacitance	Capacitance	$ an\delta$	HTLT	Thickness*3 [mm]	Note
i ai ciidilibei i	T art Humber 2	Nated voitage [v]	charact	eristics	[F]	tolerance [%]	[%]	Rated voltage x %	Thickness [mm]	Note
LWK107 BJ105MVHT		10		X5R	1 μ	±20	10	150	0.5±0.05	*1 ,*2
JWK107 BJ225MVHT		6.3		X5R	2.2 μ	±20	10	150	0.5±0.05	*1 ,*2
JWK107 BJ475MVHT		0.3		X5R	4.7 μ	±20	10	150	0.5 ± 0.05	*1 ,*2

 $\begin{tabular}{ll} \textbf{[Temperature Characteristic B7: X7R, C6: X6S, C7: X7S]} & 0.5mm & thickness (V) \\ \end{tabular}$

Part number 1	Part number 2	Rated voltage [V]	Temperature characteristics	Capacitance [F]	Capacitance tolerance [%]	tan δ [%]	HTLT Rated voltage x %	Thickness*3 [mm]	Note
TWK107 B7104MVHT		25	X7R	0.1 μ	±20	5	150	0.5±0.05	*1 ,*2
EWK107 B7224MVHT		16	X7R	0.22 μ	±20	5	150	0.5±0.05	*1 ,*2
EWK107 B7474MVHT		10	X7R	0.47 μ	±20	5	150	0.5±0.05	*1 ,*2
LWK107 B7474MVHT		10	X7R	0.47 μ	±20	5	150	0.5±0.05	*1 ,*2
JWK107 C7105MVHT		6.3	X7S	1 μ	±20	10	150	0.5±0.05	*1 ,*2
AWK107 C6225MVHT		4	X6S	2.2 μ	±20	10	150	0.5 ± 0.05	*1 ,*2
AWK107 C6475MVHT]	X6S	4.7 μ	±20	10	150	0.5 ± 0.05	*1 ,*2

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212TYPE (Dimension:1.25 × 2.0mm JIS:1220 EIA:0508)

[Temperature Characteristic BJ : X5R] 0.85mm thickness(D)

Temperature Onaracterist	IC DO . ASKI 0.8311111 tri	CKITESS (D)								
Part number 1	Part number 2	Rated voltage [V]	Tempe	rature	Capacitance	Capacitance	$ an\delta$	HTLT	Thickness*3 [mm]	Note
rart number i	Fart number 2	Nated Voltage [V]	charact	eristics	[F]	tolerance [%]	[%]	Rated voltage x %	Inickness [mm]	Note
LWK212 BJ475[]DHT		10		X5R	4.7 μ	±10, ±20	10	150	0.85±0.10	*1 ,*2
JWK212 BJ106MDHT		6.3		X5R	10 μ	±20	10	150	0.85 ± 0.10	*1 ,*2
AWK212 BJ226MDHT		4		X5R	22 μ	±20	10	150	0.85±0.10	*1 ,*2

[Temperature Characteristic C6 : X6S] 0.85mm thickness(D)

	Part number 1	Part number 2	Rated voltage [V]	Temper characte		Capacitance [F]	Capacitance tolerance [%]	tan δ [%]	HTLT Rated voltage x %	Thickness*3 [mm]	Note
-	JWK212 C6475[]DHT		6.3		X6S	4.7 μ	±10, ±20	10	150	0.85±0.10	*1 ,*2

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- All the Multilayer Ceramic Capacitors of the catalog lineup are RoHS compliant.
- Capacitance tolerance code is applied to □ of part number.
- All the Multilayer Ceramic Capacitors in the catalog lineup are applicable for reflow-soldering.

Note:

- The exchange of individual specifications is necessary depending on the application and circuit condition. Please contact Taiyo Yuden sales channels.
- * *1: Automotive (AEC-Q200 Qualified) products
 - < AEC-0200 :AEC-Q200 qualified>

All the Multilayer Ceramic Capacitors of *1 marks are tested based on the test conditions and methods defined in AEC-Q200 family item.

 125°C products: AEC-Q200 Grade1 (we conduct the evaluation at the test condition of Grade1.)

Please consult with TAIYO YUDEN's official sales channel for the details of the product specification and AEC-Q200 test results, etc.,

and please review and approve TAIYO YUDEN's product specification before ordering.

*3: For standard case size, please kindly refer to @Dimension, @Dimension tolerance, @Thickness and Standard external dimensions on Page 22.

High Reliability Application Multilayer Ceramic Capacitors

●107TYPE (Dimension:1.6 × 0.8mm JIS:1608 EIA:0603)

[Temperature Characteristic B7 : X7R] 0.8mm thickness(A)

Pa	rt number 1	Part number 2	Rated voltage [V]	erature eristics	Capacitance [F]	Capacitance tolerance [%]	tan δ [%]	HTLT Rated voltage x %	Thickness*3 [mm]	Note
UMR107	B7104[]A-T		50	X7R	0.1 μ	±10, ±20	3.5	200	0.8±0.10	*1
TMR107	B7224[]A-T		25	X7R	0.22 μ	±10, ±20	3.5	200	0.8±0.10	*1
EMR107	B7474∏A−T		16	X7R	0.47 μ	±10, ±20	3.5	200	0.8±0.10	*1
LMR107	B7105∏A−T		10	X7R	1 μ	±10, ±20	5	200	0.8±0.10	*1

212TYPE (Dimension:2.0 × 1.25mm JIS:2012 EIA:0805)

[Temperature Characteristic B7 : X7R] 1.25mm thickness(G)

L remperatare emaracterio										
Part number 1	Part number 2	Rated voltage [V]		rature	Capacitance	Capacitance	tan δ	HTLT	Thickness*3 [mm]	Note
T at Chamber 1	T art Humber 2	Nated Voltage [V]	charact	eristics	[F]	tolerance [%]	[%]	Rated voltage x %	Thickness [mm]	Note
UMR212 B7473[]G-T				X7R	0.047 μ	±10, ±20	3.5	200	1.25±0.10	*1
UMR212 B7104 G-T		50		X7R	0.1 μ	±10, ±20	3.5	200	1.25±0.10	*1
UMR212 B7224 G-T				X7R	0.22 μ	±10, ±20	3.5	200	1.25±0.10	*1
TMR212 B7474 G-T		25		X7R	0.47 μ	±10, ±20	3.5	200	1.25±0.10	*1
TMR212 B7105 G-T		25		X7R	1 μ	±10, ±20	5	200	1.25±0.10	*1
LMR212 B7225 G-T		10		X7R	2.2 μ	±10, ±20	5	200	1.25±0.10	*1

●316TYPE (Dimension:3.2 × 1.6mm JIS:3216 EIA:1206)

[Temperature Characteristic B7 : X7R] 1.6mm thickness(L)

Part number 1	Part number 2	Rated voltage [V]	Tempe	rature	Capacitance	Capacitance	$ an\delta$	HTLT	Thickness*3 [mm]	Note
Fart number 1	Fart Humber 2	Nated Voltage [V]	charact	eristics	[F]	tolerance [%]	[%]	Rated voltage x %	Inickness [mm]	Note
UMR316 B7224[]L-T		50		X7R	0.22 μ	±10, ±20	3.5	200	1.6±0.20	*1
TMR316 B7474 L-T		25		X7R	0.47 μ	±10, ±20	3.5	200	1.6±0.20	*1
TMR316 B7105[L-T		2.5		X7R	1 μ	±10, ±20	3.5	200	1.6±0.20	*1
EMR316 B7225 L-T		16		X7R	2.2 μ	±10, ±20	3.5	200	1.6±0.20	*1
LMR316 B7475 L-T		10		X7R	4.7 μ	±10, ±20	5	200	1.6±0.20	*1
JMR316 B7106□L-T		6.3		X7R	10 μ	±10, ±20	5	200	1.6±0.20	*1

■325TYPE (Dimension:3.2 × 2.5mm JIS:3225 EIA:1210)

Temperature Characteristic B7 : X7R 2.5mm thickness(M)

L remperature Orianacteria	dC D7 . X/IN 2.5IIIIII dilC	KIIC33 (IVI)								
Part number 1	Part number 2	Rated voltage [V]	Tempe characte		Capacitance [F]	Capacitance tolerance [%]	tan δ [%]	HTLT Rated voltage x %	Thickness*3 [mm]	Note
TMR325 B7106∏M-P	TMR325 B7106∏M-T	25		X7R	10 μ	±10, ±20	5	200	2.5 ± 0.20	*1

【Temperature Characteristic B7 : X7R】1.9mm thickness(N)

Tromperature onaracteris	THE TRUE BY . ACTIVE 1.0111111 GITE	7((1000 (14)							
Part number 1	Part number 2	Rated voltage [V]	erature eristics	Capacitance [F]	Capacitance tolerance [%]	tan δ [%]	HTLT Rated voltage x %	Thickness*3 [mm]	Note
UMR325 B7474[]N-T		50	X7R	0.47 μ	±10, ±20	3.5	200	1.9±0.20	*1
UMR325 B7105□N-T		30	X7R	1 μ	±10, ±20	3.5	200	1.9±0.20	*1
TMR325 B7225 N-T		25	X7R	2.2 μ	±10, ±20	3.5	200	1.9±0.20	*1
TMR325 B7475□N-T] 25	X7R	4.7 μ	±10, ±20	3.5	200	1.9±0.20	*1

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Multilayer Ceramic Capacitors

■PACKAGING

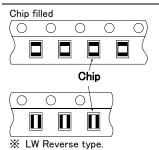
1 Minimum Quantity

Taped package				
Type(EIA)	Thick	ness	Standard o	quantity [pcs]
Type(LIA)	mm	code	Paper tape	Embossed tape
☐MK021(008004)	0.125	K	_	50000
☐MK042(01005)	0.2	C, D	_	40000
□VS042(01005)	0.2	С		40000
☐MK063(0201)	0.3	P,T	15000	_
□WK105(0204) ※	0.3	Р	10000	_
	0.13	Н	_	20000
	0.18	Е	_	15000
☐MK105(0402)	0.2	С	20000	_
	0.3	Р	15000	_
	0.5	V	10000	_
□VK105(0402)	0.5	W	10000	_
□MK107(0603)	0.45	К	4000	_
□WK107(0306) ※	0.5	V	_	4000
□MR107(0603)	0.8	Α	4000	_
□VS107(0603)	0.7	С	4000	_
□MJ107(0603)	0.8	Α	3000	3000
□MK212(0805)	0.45	К	4000	
□WK212(0508) ※	0.85	D	4000	
□MR212(0805)	1.25	G	_	3000
□VS212(0805)	0.85	D	4000	_
ΠΜ (010/000F)	0.85	D	4000	_
□MJ212(0805)	1.25	G	_	2000
51.1 (01.0(1.000)	0.85	D	4000	_
□MK316(1206) □MR316(1206)	1.15	F	_	3000
□INIK310(1200)	1.6	L	_	2000
[] M 104 0/4 000)	1.15	F	_	3000
□MJ316(1206)	1.6	L	_	2000
	0.85	D		
[] M ((((((((((((((((((1.15	F		2000
☐MK325(1210)	1.9	N	_	2000
□MR325(1210)	2.0max.	Υ		
	2.5	М	_	1000
ΠΜ (205/1010)	1.9	N	_	2000
□MJ325(1210)	2.5	М	_	500(T), 1000(P)
□MK432(1812)	2.5	М	_	500

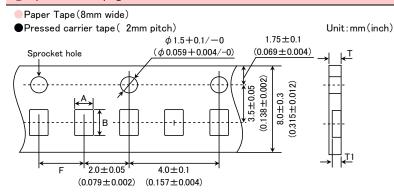
Note: X LW Reverse type.

**No bottom tape for pressed carrier tape Card board carrier tape Top tape Base tape Sprocket hole Chip cavity Base tape Chip cavity

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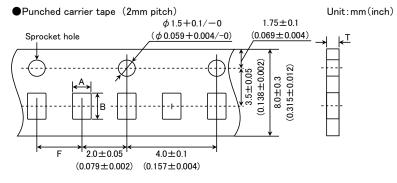
3 Representative taping dimensions



Type(EIA)	Chip	Cavity	Insertion Pitch	Tape Th	nickness
Type(EIA)	Α	В	F	Т	T1
□MK063(0201)	0.37	0.67		0.45max.	0.42max.
□WK105(0204) ※			0.0 ± 0.05	0.45max.	0.42max.
☐MK105(0402) (*1 C)	0.65	1.15	2.0±0.05	0.4max.	0.3max.
□MK105(0402) (*1 P)				0.45max.	0.42max.

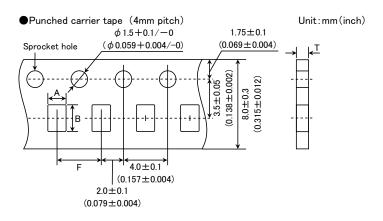
Note *1 Thickness, C:0.2mm ,P:0.3mm. * LW Reverse type.

Unit:mm



Type(EIA)	Chip (Cavity	Insertion Pitch	Tape Thickness
Type(EIA)	Α	В	F	Т
□MK105 (0402) □VK105 (0402)	0.65	1.15	2.0±0.05	0.8max.

Unit:mm



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Type(EIA)	Chip (Cavity	Insertion Pitch	Tape Thickness
Type(EIA)	Α	В	F	Т
□MK107(0603)				
□WK107(0306) ※	1.0	1.8		1.1max.
☐MR107(0603)			40101	
□MK212(0805)	1.65	0.4	4.0±0.1	
□WK212(0508) ※	1.00	2.4		1.1max.
□MK316(1206)	2.0	3.6		

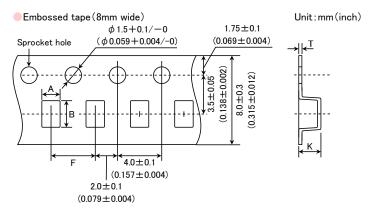
Note: Taping size might be different depending on the size of the product. 💥 LW Reverse type.

Unit:mm

Embossed tape (4mm wide)			Unit:mm(inch)
	ϕ 0.8 \pm 0.04	0.9 ± 0.05	
Sprocket hole	$(\phi 0.031 \pm 0.002)$	(0.035 ± 0.002)	_JL ^T
F 1.0±0.02 (0.039±0.001) (0	2.0±0.04 079±0.002)	(0.071±0.001) 4.0±0.05 (0.157±0.002)	K

Type(EIA)	Chip (Cavity	Insertion Pitch	Tape Th	nickness
Type(EIA)	Α	В	F	K	Т
☐MK021(008004)	0.135	0.27			
☐MK042(01005)	0.23	0.43	1.0±0.02	0.5max.	0.25max.
□VS042(01005)	0.23	0.43			

Unit:mm



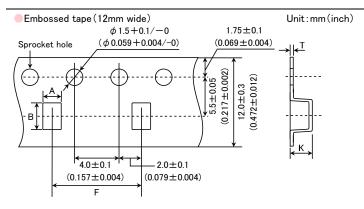
Type(EIA)	Chip (Cavity	Insertion Pitch	Tape Ti	nickness
Type(EIA)	Α	В	F	K	Т
☐MK105(0402)	0.6	1.1	2.0±0.1	0.6max	0.2±0.1
□WK107(0306) ※	1.0	1.8		1.3max.	0.25±0.1
□MK212(0805) □MR212(0805)	1.65	2.4			
☐MK316(1206) ☐MR316(1206)	2.0	3.6	4.0±0.1	3.4max.	0.6max.
☐MK325(1210) ☐MR325(1210)	2.8	3.6			

Note:

LW Reverse type.

Unit:mm

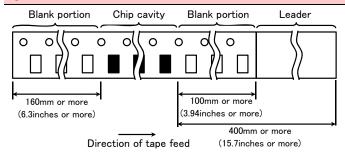
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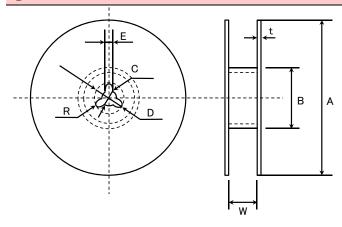
Type(EIA)	Chip (Cavity	Insertion Pitch	Tape Th	nickness
Type(EIA)	Α	В	F	K	Т
☐MK325(1210)	3.1	4.0	8.0±0.1	4.0max.	0.6max.
☐MK432(1812)	3.7	4.9	8.0±0.1	4.0max.	0.6max.

Unit:mm

4 Trailer and Leader



5Reel size



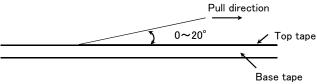
Α	В	С	D	E	R
ϕ 178 ± 2.0	<i>ф</i> 50min.	ϕ 13.0 \pm 0.2	ϕ 21.0 ± 0.8	2.0±0.5	1.0

	T	W
4mm wide tape	1.5max.	5±1.0
8mm wide tape	2.5max.	10±1.5
12mm wide tape	2.5max.	14±1.5

Unit:mm

©Top Tape Strength

The top tape requires a peel-off force of 0.1 to 0.7N in the direction of the arrow as illustrated below.



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Multilayer Ceramic Capacitors

■ RELIABILITY DATA

Methods and

Remarks

Duration

Charge/discharge current

Temperature Compensating (Class High Frequency Type	1.Operating Ten	nperature Range							
Compensating (Class 1) High Frequency Type Specification Temperature Range B.U XSR -55 to +85°C S7 X7R -55 to +125°C C6 XSS -55 to +125°C D7 X7T -55 to +125°C S8B -25 to +85°C S7 X7R -55 to +125°C D7 X7T D7	peraamg ren	<u>-</u>	Standard						
Specification Temperature Range B		•		−55 to +	−55 to +125°C				
Bu	-	Compensating (Class 1)							
B						Temperature	Range		
High Permittivity (Class2) BJ X5R -55 to +85°C B7 X7R -55 to +105°C C6 X6S -55 to +105°C C7 X7S -55 to +105°C C7 X7S -55 to +125°C C7 X7S -55 to +125°C C7 X7S X7R X7R X7S						·			
High Permittivity (Class2) B7			BJ						
High Permittivity (Class2)	pecified alue			B7					
C7	alue	High Permittivity (Class2)	 					
D7		g	,						
LD(※) X5R					+				
Note: ※LD Low distortion high value multilayer ceramic calculations									
Temperature Compensating (Class1)									
Temperature Compensating (Class1)	Storage Cons	litions							
Compensating (Class1) High Frequency Type Temperature Standard Compensating (Class1) High Permittivity (Class2) Standard Compensating (Class1) High Permittivity (Class2) Standard Compensating (Class1) High Permittivity (Class2) Class 1 Class 2 Applied voltage Rated voltax 3 Rated voltage Compensating (Class1) Compensating (Class1) Compensating (Class1) Compensating (Class2) Class 1 Class 2 Cla	Storage Cont		Standard						
Specification Temperature Range BJ		·	-	−55 to +	-125°C				
B	-				Specification	Temperature	Range		
High Permittivity (Class2) BJ X5R -55 to +85°C B7				 	<u>.</u>				
B7	S:E			BJ					
High Permittivity (Class2)	Specified Value Hi			B7	ł				
C7		High Permittivity (Class2)			 				
D7									
LD(※) X5R					ł				
Note: ※LD Low distortion high value multilayer ceramic content of the compensating (Class 1) Standard SoVDC, 25VDC				ł					
Temperature Standard 50VDC, 25VDC High Permittivity (Class2) 50VDC, 25VDC High Permittivity (Class2) 50VDC, 35VDC, 25VDC, 16VDC, 10VDC, 6.3VDC, 4VDC, 2.5VDC Standard Standard Standard High Frequency Type High Permittivity (Class2) High Permittivity (Class2) Ods and arks Class 1 Class 2 Applied voltage Rated volta × 3 Rated voltage × 2.5 Duration 1 to 5 sec. Charge/discharge current Standard Charge/discharge current Standard Charge/discharge current Standard Charge/discharge current Compensating (Class 1) High Permittivity (Class2) Note 1 C ≤ 0.047 μF : 10000 MΩ min. C ≤ 0.047 μF : 10000 MΩ min. C ≤ 0.047 μF : 500M Ω · μF Applied voltage : Rated voltage :					L				
Temperature Compensating (Class1) High Frequency Type 50VDC, 25VDC High Permittivity (Class2) 50VDC, 35VDC, 25VDC, 16VDC, 10VDC, 6.3VDC, 4VDC, 2.5V thstanding Voltage (Between terminals) Temperature Standard Compensating (Class1) High Frequency Type High Permittivity (Class2) Ods and arks Class 1 Class 2 Applied voltage Rated volta × 3 Rated voltage × 2.5 Duration 1 to 5 sec. Charge/discharge current 50mA max. Sulation Resistance Temperature Compensating (Class1) High Frequency Type High Permittivity (Class2) Temperature Compensating (Class1) High Frequency Type High Permittivity (Class2) Note 1 C ≤ 0.047 μF : 10000 MΩ min. C > 0.047 μF : 500MΩ · μF Applied voltage : Rated voltage	1			•					
High Permittivity (Class2) High Frequency Type 50VDC, 25VDC	3. Rated Voltage	9	1						
High Permittivity (Class2) High Permittivity (Class2) Temperature Compensating (Class1) High Frequency Type Standard Compensating (Class1) High Frequency Type High Permittivity (Class2) Class 1 Applied voltage Rated volta × 3 Rated voltage × 2.5 Duration Charge/discharge current Temperature Compensating (Class1) Class 1 Applied voltage Rated volta × 3 Rated voltage × 2.5 Duration Charge/discharge current Temperature Compensating (Class1) High Frequency Type I to 5 sec. Charge/discharge current Standard High Frequency Type High Permittivity (Class2) Note 1 C ≤ 0.047 μ F : 10000 MΩ min. C > 0.047 μ F : 500M Ω • μ F Applied voltage Rated voltage Rated voltage	Specified	•							
thstanding Voltage (Between terminals) Temperature Compensating (Class1) High Frequency Type High Permittivity (Class2) Ods and arks Class 1 Class 2 Applied voltage Rated volta × 3 Rated voltage × 2.5 Duration 1 to 5 sec. Charge/discharge current 50mA max. Standard Class 1 Class 2 Applied voltage Rated volta × 3 Rated voltage × 2.5 Duration 1 to 5 sec. Charge/discharge current 50mA max. Cultiple Voltage Standard Temperature Compensating (Class1) High Frequency Type High Permittivity (Class2) Note 1 C≤0.047 μ F : 10000 MΩ min. C > 0.047 μ F : 500M Ω • μ F Applied voltage : Rated voltage	Value -	Compensating(Class1)	High Frequency Type	50VDC, 25VDC					
Temperature Compensating (Class 1) High Frequency Type High Permittivity (Class 2) No breakdown or damage $ \frac{\text{Class 1}}{\text{High Permittivity (Class 2)}} $		High Permittivity (Class2)	50VDC, 35	5VDC, 25VDC, 16VD	C, 10VDC, 6.3VDC,	4VDC, 2.5\		
Temperature Compensating (Class1) High Frequency Type High Permittivity (Class2) No breakdown or damage $\frac{\text{Class 1}}{\text{Applied voltage}} = \frac{\text{Class 1}}{\text{Applied voltage}} = \frac{\text{Class 1}}{\text{Class 2}} = \frac{\text{Class 2}}{\text{Charge/discharge current}} = \frac{\text{Class 1}}{\text{Class 2}} = \frac{\text{Class 2}}{\text{Charge/discharge current}} = \frac{\text{Class 2}}{\text{Class 2}} = \frac{\text{Class 2}}{\text{Compensating (Class1)}} = \frac{\text{Class 2}}{\text{Class 2}} = $									
iffied Compensating (Class1) High Frequency Type High Permittivity (Class2) No breakdown or damage	. Withstanding	3 .							
Compensating (Class 1) High Frequency Type No breakdown or damage	Specified			1					
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	alue	Compensating (Class1)	High Frequency Type	No breakd	own or damage				
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		High Permittivity (Class2							
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	est								
Duration 1 to 5 sec. Charge/discharge current 50mA max. Sullation Resistance Temperature Compensating (Class1) High Frequency Type High Permittivity (Class2) Note 1 $C \le 0.047 \ \mu \text{F} : 10000 \ M \Omega $ min. C>0.047 $\mu \text{F} : 500M \Omega \cdot \mu \text{F}$ Applied voltage : Rated voltage	Methods and		Rated			voltage × 2.5			
Charge/discharge current 50mA max. Sulation Resistance Temperature Compensating (Class1) High Frequency Type High Permittivity (Class2) Note 1 $C \le 0.047 \mu \text{F} : 10000 \text{M} \Omega \text{min.}$ C>0.047 $\mu \text{F} : 500M \Omega \cdot \mu \text{F}$ Applied voltage : Rated voltage	lemarks								
Temperature Compensating (Class1) $High\ Frequency\ Type$ $I 10000\ M\Omega\ min.$ High Permittivity (Class2) Note 1 $C \le 0.047\ \mu\ F : 10000\ M\Omega\ min.$ C>0.047 $\mu\ F : 500M\ \Omega \cdot \mu\ F$ Applied voltage : Rated voltage		Charge/discharge curre	nt		50mA max.				
Temperature Compensating (Class1) High Frequency Type C $\leq 0.047 \mu \text{F} : 10000 \text{M} \Omega \text{min.}$ High Permittivity (Class2) Note 1 C $\leq 0.047 \mu \text{F} : 10000 \text{M} \Omega \text{min.}$ C $> 0.047 \mu \text{F} : 5000 \Omega \cdot \mu \text{F}$ Applied voltage : Rated voltage									
ified Compensating (Class1) High Frequency Type $ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	5. Insulation Res	sistance							
ified Compensating (Class1) High Frequency Type 10000 M Ω min. High Permittivity (Class2) Note 1 $C \le 0.047 \mu\text{F} : 10000 M\Omega$ min. C>0.047 $\mu\text{F} : 500M\Omega \cdot \mu\text{F}$ Applied voltage : Rated voltage		Temperature	Standard	10000 110					
High Permittivity (Class2) Note 1 $C \le 0.047 \mu\text{F} : 10000 \text{M}\Omega$ min. $C > 0.047 \mu\text{F} : 500 \text{M}\Omega \cdot \mu\text{F}$ Applied voltage : Rated voltage	Specified	•	High Frequency Type	10000 MΩ	? min.				
High Permittivity (Class2) Note 1 C≥0.047 μ F : 10000 M32 min. C>0.047 μ F : 500M Ω • μ F Applied voltage : Rated voltage	Value	1 '6''/	Trigit i requeries Type	0<0047	"F. 10000 MO				
Applied voltage : Rated voltage		High Permittivity (Class2) Note 1			•			
				U > 0.04/ J	μ Γ : 300 IVI Υ • μ F				
	est	Applied voltage	: Rated voltage						

: 60±5 sec.

: 50mA max.

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6. Capacitance	(Tolerance)						
Specified Value	Temperature Compensating(Class1)		Standard	C□ U□ SL	0.2pF≦C≦5pF 0.2pF≦C≦10pF C>10pF	: ±0.25pF : ±0.5pF : ±5% or ±10%	
	Compensating (Class I)	High Frequency Type		СН	0.3pF≦C≦2pF C>2pF	: ±0.1pF : ±5%	
	High Permittivity (Class2)			BJ, B7, C6, C7, D7, LD($\%$): $\pm 10\%$ or $\pm 20\%$ Note: $\%$ LD Low distortion high value multilayer ceramic capacitor			
				Cla	ss 1	Cla	ass 2
- .		Standa		I	High Frequency Type	C≦10 μ F	C>10 µ F
Test	Preconditioning	Preconditioning		None		Thermal treatment (at	t 150°C for 1hr) Note 2
Methods and Remarks	Measuring frequency		1MHz±10%		1kHz±10%	120±10Hz	
Remarks	Measuring voltage Note			0.5 to	5Vrms	1±0.2Vrms	0.5±0.1rms
	Bias application					one	

Specified	Temperature		tandard $C < 30pF : Q \ge 400 + 20C$ $C \ge 30pF : Q \ge 1000$ (C:Nominal capacitance)				
Value	Compensating(Class1)	High Frequency Type		Refer	to detailed specification		
	High Permittivity (Class2) Note 1			BJ, B	7, C6, C7, D7:2.5% max.		
				Class 1		Class 2	
			Standard		High Frequency Type	C≦10 <i>μ</i> F	C>10 μ F
	Preconditioning				one	Thermal treatment (at	150°C for 1hr) Note 2
Test	Measuring frequey		1MHz±10%		1GHz	1kHz±10%	120±10Hz
Methods and	Measuring voltage Note 1		0.5 to 5Vrms		1±0.2Vrms	0.5±0.1Vrms	
Remarks	Bias application			None			
	High Frequency Type						
	Measuring equipment	: HP	4291A				
	Measuring jig	: HP	16192A				

	Temperature Compensating(Class1)		Tem	perature Charac	cteristic [ppm/°	C] Tol	erance [ppm/°C]	
		Standard	C□: 0		CG,CH, CJ,	СК	G: ±30 H: ±60	
			U□:	— 750	UJ, UK		J: ±120 K: ±250	
			SL :	+350 to −100	00			
		High Frequency Type	Tem	perature Charac	cteristic [ppm/°	C] Tol	erance [ppm/°C]	
			C□:	C□: 0 CH H:±60				
Specified				Specification	Capacitance	Reference	Temperature Range	
Value				Opecinication	change	temperature	Temperature range	
			BJ	В	±10%	20°C	-25 to +85°C	
			Во	X5R	±15%	25°C	-55 to +85°C	
	High Permittivity (Class2)	`	B7	X7R	±15%	25°C	−55 to +125°C	
	night Permittivity (Glassz)	,	C6	X6S	±22%	25°C	-55 to +105°C	
			C7	X7S	±22%	25°C	-55 to +125°C	
			D7	X7S	+22/-33%	25°C	−55 to +125°C	
				X5R	±15%	25°C	−55 to +85°C	
			Note:	71D 1	rtion high value		antan and a state of	

Class 1

Capacitance at 20° C and 85° C shall be measured in thermal equilibrium, and the temperature characteristic shall be calculated from the following equation.

$$\frac{(C_{85}-C_{20})}{C_{20}\times\Delta T} \times 10^{6} (ppm/^{\circ}C) \qquad \Delta T = 65$$

Test Methods and Remarks

Class 2

Capacitance at each step shall be measured in thermal equilibrium, and the temperature characteristic shall be calculated from the following equation.

Step	В	X5R、X7R、X6S、X7S、X7T	
1	Minimum operat	ng temperature	
2	20°C	25°C	
3	Maximum operat	ing temperature	

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 $\frac{(C-C_2)}{C_2}$ × 100(%)

C : Capacitance in Step 1 or Step 3

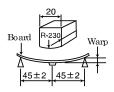
C2 : Capacitance in Step 2

9. Deflection : No abnormality Appearance Standard Capacitance change : Within $\pm 5\%$ or ± 0.5 pF, whichever is larger. Temperature Compensating (Class 1)Appearance : No abnormality Specified High Frequency Type : Within±0.5 pF Cpaitance change Value Appearance : No abnormality Capacitance change : Within ±12.5%(BJ, B7, C6, C7, D7, LD(*)) High Permittivity (Class2)

Test Methods and Remarks

	Multilayer Cera	ımic Capacitors			
	042, 063, ^{※1} 105 Type	The other types			
Board	Glass epoxy-resin substrate				
Thickness	0.8mm	1.6mm			
Warp	1mm (Soft Termination type:3mm)				
Duration	10 sec.				





Note: XLD Low distortion high value multilayer ceramic capacitor

(Unit: mm)

Capacitance measurement shall be conducted with the board bent

10. Body Stren	10. Body Strength					
	Temperature	Standard	-			
Specified Value	Compensating(Class1)	High Frequency Type	No mechanical damage.			
Value	High Permittivity (Class2))	_			
Test Methods and Remarks	High Frequency Type Applied force : 5N Duration : 10 sec.	Pres ← A →	R0.5 Pressing Jig Chip O.6A A			

11. Adhesive St	11. Adhesive Strength of Terminal Electrodes							
0 15 1	Temperature	Standard						
Specified Value	Compensating(Class1)	High Frequency Type	No terminal separati	on or its indication.				
	High Permittivity (Class2	2)						
		Multilayer Cerami	c Capacitors	Hooked jig				
Test		042, 063 Type	105 Type or more					
Methods and	Applied force	2N	5N	R=05 Doard				
Remarks	Duration	30±5 s	ec.	- Chin				
				Chip				
	Duration	30±5 s	ec.	←Chip Chip				

12. Solderability	/						
	Temperature	Standard					
Specified Value	Compensating(Class1)	High Frequency Type	At least 95%	of terminal electrode is covered l	by new solder.		
V dide	High Permittivity (Class2)						
T4		Eutectic so	older	Lead-free solder			
Test Methods and	Solder type	H60A or H	63A	Sn-3.0Ag-0.5Cu			
Remarks	Solder temperature	230±5°	С	245±3℃			
Remarks	Duration		4±1 sec.				

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13. Resistance	to Soldering				
Specified Value	Temperature	Standard	Appearance Capacitance change Q Insulation resistance Withstanding voltage	: No abnormality : Within ±2.5% or ±0 : Initial value : Initial value (between terminals)	0.25pF, whichever is larger. : No abnormality
	Compensating(Class1)	High Frequency Type	Appearance Capacitancecange Q Insulation resistance Withstanding voltage	: No abnormality : Within ±2.5% : Initial value : Initial value (between terminals) : No abnormality	
	High Permittivity(Class	2) Note 1	Appearance Capactace change Dissipation factor Insulation resistance Withstanding voltage Note: ※LD Low distor	: Initial value : Initial value (between terminals)	•
			lss 1		
		042, 063 Type	105 Type		
	Preconditioning		None		
	Preheating	150°C, 1 to 2 min.		00°C, 2 to 5 min. 00°C, 2 to 5 min.	
	Solder temp.		270±5°C		
	Duration		3 ± 0.5 sec.		
Γest Methods and	Recovery	6 to 24 hrs	s (Standard condition) N	loe 5	
Remarks				Class 2	
		042、063 Type	105, 1	07, 212 Type	316, 325 Type
	Preconditioning		Thermal treatment	(at 150°C for 1 hr) No	ote 2
	Preheating	150°C, 1 to 2 min.		00°C, 2 to 5 min. 00°C, 2 to 5 min.	80 to 100°C, 5 to 10 min. 150 to 200°C, 5 to 10 min.
	Solder temp.			.70±5°C	
	Duration		3:	±0.5 sec.	
	Recovery		24±2 hrs (Star	ndard condition)Note	5

14. Temperatur	re Cycle (Thermal Shock)						
	Temperature	Standard High Frequency Type		Capacitance change : V Q : In Insulation resistance : In	: Initial value ee : Initial value		
Specified Value	Compensating(Class1)			Capacitance change : V Q : In Insulation resistance : In	ance change : Within ±0.25pF : Initial value on resistance : Initial value		
	High Permittivity(Class2) Note 1			Appearance : No abnormality Capacitance change : Within ±7.5% (BJ, B7, C6, C7, D7, LD(※)) Dissipation factor : Initial value Insulation resistance : Initial value Withstanding voltage (between terminals) : No abnormality Note: ※LD Low distortion high value multilayer ceramic capacitor			
			C	Class 1	Class 2		
	Preconditioning			None	Thermal treatment (at 150°C for 1 hr) Note 2		
Test Methods and Remarks	1 cycle		Step 1 2 3 4	Temperatur Minimum operating Normal temp Maximum operating Normal temp	temperature erature temperature	Time(min.) 30±3 2 to 3 30±3 2 to 3	
	Number of cycles			5 1	ō times		
	Recovery	6 to 24 hrs	S (Stan	dard condition)Note 5	24±2 hrs (S	Standard condition)Note 5	

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15. Humidity (Steady State)			
	Temperature Compensating(Class1	Standard)	Capacitance change Q	: No abnormality : Within $\pm 5\%$ or ± 0.5 pF, whichever is larger. : $C < 10$ pF : $Q \ge 200 + 10$ C $10 \le C < 30$ pF : $Q \ge 275 + 2.5$ C $C \ge 30$ pF: $Q \ge 350$ (C: Nominal capacitance) : 1000 M Ω min.
Specified Value		High Frequency Type	Appearance Capacitance change Insulation resistance	: No abnormality : Within $\pm 0.5 pF$, : $1000 \ M\Omega$ min.
	High Permittivity(Class2) Note 1		Appearance : No abnormality Capacitance change : Within $\pm 12.5\%$ (BJ, B7, C6, C7, D7, LD($\%$)) Dissipation factor : 5.0% max.(BJ, B7, C6, C7, D7, LD($\%$)) Insulation resistance : $50 \text{ M} \Omega \mu \text{ F}$ or $1000 \text{ M} \Omega$ whichever is smaller. Note: $\%$ LD Low distortion high value multilayer ceramic capacitor	
			ass 1	Class 2
Test	Preconditioning	Standard N	High Frequency Type	All items Thermal treatment(at 150°C for 1 hr) Note 2
Methods and	Temperature	40±2°C	60±2°C	40±2°C
Remarks	Humidity	90 to	95%RH	90 to 95%RH
	Duration	500+2	4/-0 hrs	500+24/-0 hrs
	Recovery	6 to 24 hrs (Stand	ard condition)Note 5	24±2 hrs(Standard condition)Note 5

16. Humidity Lo	pading				
	Temperature	Standard	Appearance Capacitance change Q Insulation resistance	: Wit : C< C≧	abnormality thin $\pm 7.5\%$ or ± 0.75 pF, whichever is larger. <30 pF: Q $\ge 100+10$ C/3 ≥ 30 pF: Q ≥ 200 (C: Nominal capacitance) 0 M Ω min.
Specified Value	Compensating(Class1)	High Frequency Type	Appearance Capacitance change Insulation resistance	: C≦ C>	abnormality ≦2pF: Within ±0.4 pF >2pF: Within ±0.75 pF (C: Nominal capacitance) 0 MΩ min.
	High Permittivity (Class2	$ \begin{array}{llllllllllllllllllllllllllllllllllll$			
		C	Class 1		Class 2
		Standard	High Frequency Ty	ре	All items
	Preconditioning		None		Voltage treatment (Rated voltage are applied for 1 hour at 40°C) Note 3
Test	Temperature	40±2°C	60±2°C		40±2°C
Methods and	Humidity	90 t	:o 95%RH		90 to 95%RH
Remarks	Duration	500+	24/-0 hrs		500+24/-0 hrs
	Applied voltage	Rate	ed voltage		Rated voltage
	Charge/discharge current	50r	mA max.		50mA max.
	Recovery	6 to 24 hrs (Stan	dard condition)Note 5		24±2 hrs (Standard condition) Note 5

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17. High Tempe	erature Loading						
	Temperature Compensating(Class1)	Standard	Appearance : No abnormality Capacitance change : Within $\pm 3\%$ or $\pm 0.3 pF$, whichever is larger. Q : $C < 10 pF$: $Q \ge 200 + 10 C$ $10 \le C < 30 pF$: $Q \ge 275 + 2.5 C$ $C \ge 30 pF$: $Q \ge 350 (C$: Nominal capacitance) Insulation resistance : $1000 \text{ M} \Omega$ min.				
Specified Value		High Frequency Type	Appearance : No abnormality Capacitance change : Within $\pm 3\%$ or ± 0.3 pF, whichever is larger. Insulation resistance : $1000 \text{ M}\Omega$ min.				
	High Permittivity(Class2) Note 1	Appearance Capacitance change Dissipation factor Insulation resistance Note: ※LD Low dis	: 5.0% max.(BJ, B7, C6, C7, D7, LD(※))			
		Clas	s 1	Class 2			
		Standard H	High Frequency Type	BJ, LD(※)	C6	B7, C7, D7	
	Preconditioning	None		Voltage treatment (Twice the rated voltage shall be applied for 1 hour at 85°C, 105°C or 125°C) Note 3, 4			
Test	Temperature	Maximum operatii	ng temperature	Maximum operating temperature			
Methods and	Duration	1000+48	/-0 hrs	1000 + 48 / -0 hrs			
Remarks	Applied voltage	Rated vol	tage × 2	Rated voltage × 2 Note 4			
Nemarks	Charge/discharge current	50mA	max.	50mA max.			
	Recovery	6 to 24hr (Standard	Condition) Note 5	24±2 hrs(Standard condition)Note 5			
			Note	*LD Low distortion	on high value multil	ayer ceramic capacitor	

Note 1 The figures indicate typical specifications. Please refer to individual specifications in detail.

- Note 2 Thermal treatment : Initial value shall be measured after test sample is heat-treated at $150 + 0/-10^{\circ}$ C for an hour and kept at room temperature for 24 ± 2 hours.
- Note 3 Voltage treatment: Initial value shall be measured after test sample is voltage—treated for an hour at both the temperature and voltage specified in the test conditions, and kept at room temperature for 24±2hours.
- Note 4 150% of rated voltage is applicable to some items. Please refer to their specifications for further information.
- Note 5 Standard condition: Temperature: 5 to 35°C, Relative humidity: 45 to 85 % RH, Air pressure: 86 to 106kPa When there are questions concerning measurement results, in order to provide correlation data, the test shall be conducted under the following condition.
 - Temperature: $20\pm2^{\circ}$ C, Relative humidity: 60 to 70 % RH, Air pressure: 86 to 106kPa Unless otherwise specified, all the tests are conducted under the "standard condition".

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Medium-High Voltage Multilayer Ceramic Capacitor

■RELIABILITY DATA

	Temperature Compensating(High Frequency type) CG(C0G) : -55 to +125°C						
	Ga(Gaa)33 to +123 C						
Specified Value	High permittivity						
	X7R, X7S : −55 to +125°C						
	X5 : −55 to +85°C						
	B : -25 to +85°C						
2. Storage Tempera	ature Range						
	Temperature Compensating(High Frequency type)						
	CG(C0G) : -55 to +125°C						
Specified Value	High permittivity						
	X7R, X7S : −55 to +125°C						
	X5R : −55 to +85°C						
	B : −25 to +85°C						
3. Rated Voltage							
Specified Value	100VDC(HMK,HMJ), 250VDC(QMK,QMJ,QVS), 630VDC(SMK,SMJ)						
4. Withstanding Vol	tage (Between terminals)						
Specified Value	No breakdown or damage						
Test Methods and	Applied voltage : Rated voltage × 2.5 (HMK,HMJ), Rated voltage × 2 (QMK,QMJ,QVS), Rated voltage × 1.2 (SMK,SMJ)						
Remarks	Duration : 1 to 5sec.						
	Carge/discharge current : 50mA max.						

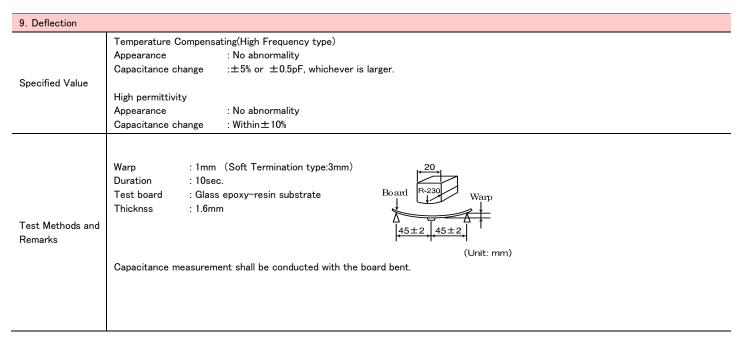
O. Insulation (CSISE	ance				
0 15 111	Temperature Compensating(10000M Ω min	High Frequency type)			
Specified Value	High permittivity $100M\Omega~\mu$ F or $10G\Omega$, whichever is smaller.				
Test Methods and Remarks	Applied voltage Duration Charge/discharge current	: Rated voltage(HMK,HMJ, QMK,QMJ,QVS), 500V(SMK,SMJ) : 60±5sec. : 50mA max.			

6. Capacitance (To	olerance)					
Specified Value	Temperature Compensating(High Frequency type) $\pm 0.1 pF (C < 5pF) \ \pm 0.25pF (C < 10pF) \ \pm 0.5pF (5pF \le C < 10pF) \ \pm 2\% (C = 10pF) \ \pm 5\% (C \ge 10pF)$					
	High permittivity					
	±10%, ±20%					
	Temperature Compensating(High Frequency type)					
	Measuring frequency	: 1MHz±10%				
	Measuring voltage	: 0.5 to 5Vrms				
Test Methods and	Bias application	: None				
Remarks	High permittivity					
	Measuring frequency	: 1kHz±10%				
	Measuring voltage	: 1 ± 0.2 Vrms				
	Bias application	: None				

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7. Q or Dissipation	Factor					
	Temperature Compensa	ting(High Frequency type)				
	C < 30pF : Q ≥ 800 + 20C					
	C≧30pF: Q≧1400	C:Normal Capacitance(/pF)				
Specified Value						
	High permittivity					
	3.5%max (HMK,HMJ)					
	2.5%max(QMK,QMJ, SM	K,SMJ)				
	Temperature Compensa	ting(High Frequency type)				
	Measuring frequency	: 1MHz±10%				
	Measuring voltage	: 0.5 to 5Vrms				
Test Methods and	Bas application	: None				
Remarks	High permittivity					
	Measuring frequency	: 1kHz±10%				
	Measuring voltage	: 1±0.2Vrms				
	Bas application	: None				

8. Temperature Cha	aracteristic of Capacitance
	Temperature Compensating(High Frequency type) COG :±30ppm(25 to +125°C)
Specified Value	High permittivity B : ±10%(-25 to +85°C) X5R : ±15%(-55 to +85°C) X7R : ±15%(-55 to +125°C) X7S : ±22%(-55 to +125°C)
Test Methods and Remarks	Temperature Compensating(High Frequency type) Capacitance at 25° C and 85° C shall be measured in thermal equilibrium, and the temperature characteristic shall be calculated from the following equation. $\frac{(C_{85}-C_{25})}{C_{25}\times\Delta T}\times 10^{6}\times [\text{ppm}/^{\circ}\text{C}]$ High permittivity Capacitance value at each step shall be measured in thermal equilibrium, and the temperature characteristic shall be calculated from the following equation. $\begin{array}{c ccccccccccccccccccccccccccccccccccc$
	C : Capacitance value in Step 1 or Step 3 C2 : Capacitance value in Step 2



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10. Adhesive Strength of Terminal Electrodes Specified Value No terminal separation or its indication. Temperature Compensating(High Frequency type) Applied force : 2N Hooked jig Duration : 10±5sec. Board Test Methods and Remarks High permittivity Applied force : 5N Hooked jig Duration : 30±5sec. Board

11. Solderability					
Specified Value At least 95% of terminal electrode is covered by new solder					
		Eutectic solder	Lead-free solder		
Test Methods and	Solder type	H60A or H63A	Sn-3.0Ag-0.5Cu		
Remarks	Solder temperature	230±5°C	245±3°C		
	Duration	4±1 sec.			

12. Resistance to S	Soldering						
	Temperature Compensating(High Frequency type)						
	Appearance	: No abnormality					
	Capacitance change	: C※≦10pF :±0.25pF C※>10pF :±2.5% ※Normal capacitance					
	Insulation resistance	: Initial value					
	Withstanding voltage	(between terminals): No abnormality					
Specified Value							
	Appearance	: No abnormality					
	Capacitance change	nge : Within±15%(HMK,HMJ), ±10%(QMK,QMJ, SMK,SMJ)					
	Dissipation factor	: Inital value					
	Insulation resistance	: Initial value					
	Withstanding voltage	(between terminals): No abnormality					
	Preconditioning	: Thermal treatment (at 150°C for 1hr) Note1 (Only High permittivity)					
Test Methods and	Solder temperature	: 270±5℃					
Remarks	Duration	: 3±0.5sec.					
riciliai no	Preheating conditions	: 80 to 100°C, 2 to 5 min. 150 to 200°C, 2 to 5min.					
	Recovery	: 24±2hrs under the stadard condition Note3					

13. Temperature C	ycle(Thermal Shock)			
	Temperature Comp	ensating(High Frequency type)			
	Appearance	: No abnormality			
	Capacitance change	Capacitance change : C ≤10pF:±0.25% C ⇒10pF:±2.5%			
	Insulation resistance	e : Initial value			
	Withstanding voltag	e (between terminals) : No abnormality			
Specified Value	High permittivity				
	Appearance	: No abnormality			
	Capacitance change	: Within±15%(HMK,HMJ),±7.5%(QMK,QMJ, SMK,SMJ)			
	Dissipation factor	: Initial value	: Initial value		
	Insulation resistance : Initial value				
	Withstanding voltag	Withstanding voltage (between terminals): No abnormality			
	Preconditioning : Th	ermal treatment (at 150°C for 1hr) Note1			
	Conditions for 1 cy			<u></u>	
	Step	temperature (°C)	Time (min.)		
Test Methods and	1	Minimum operating temperature	30±3min.		
Remarks	2	Normal temperature	2 to 3min.		
Nomai No	3	Maximum operating temperature	30±3min.		
	4	Normal temperature	2 to 3min.		
	Number of cycles:	5 times			
	Recovery : 24±2hr	s under the standard condition Note3			

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14. Humidity (Stea		
	Temperature Compensating	(High Frequency type)
	Appearance	: No abnormality
	Capacitance change	: C※≦10pF :±0.5pF C※>10pF :±5% ※Normal capacitance
	Insulation resistance	: $1000M\Omega$ min
Specified Value		
specified value	High permittivity	
	Appearance	: No abnormality
	Capacitance change	: Within±15%
	Dissipation factor	: 7%max(HMK,HMJ), 5%max(QMK,QMJ, SMK,SMJ).
	Insulation resistance	: 25M Ω μ F or 1000M Ω , whichever is smaller.
	Preconditioning	: Thermal treatment (at 150°C for 1hr) Note1 (Only High permittivity)
	Temperature	: 40±2°C
est Methods and	Humidity	: 90 to 95%RH
Remarks	Duration	: 500 +24/-0 hrs
	Recovery	: 24±2hrs under the standard condition Note3
	recovery	. 24 ± 21113 under the standard condition notes
5. Humidity Loadin	ng .	
	Temperature Compensating	(High Frequency type)
	Appearance	: No abnormality
	Capacitance change	: C $\frac{5}{2}$ 0.0pF : ± 0.4 pF 2.0pF < C $\frac{5}{2}$ 10pF : ± 0.75 pF C $\frac{5}{2}$ 10pF : ± 7.5 %
		: ※Normal capacitance
	Insulation resistance	: $500M\Omega$ min
Specified Value		
	High permittivity	
	Appearance	: No abnormality
	Capacitance change	: Within±15%
	Dissipation factor	: 7%max(HMK,HMJ), 5%max(QMK,QMJ, SMK,SMJ).
	Insulation resistance	: $10 \mathrm{M}\Omega~\mu$ F or $500 \mathrm{M}\Omega$, whichever is smaller.
	According to JIS 5102 claus	ne 9 9
	Preconditioning	: Voltage treatment Note2 (Only High permittivity)
	Temperature	: 40±2°C
Test Methods and	Humidity	: 90 to 95%RH
Remarks	Applied voltage	: Rated voltage
Ciliai KS	Charge/discharge current	: 50mA max.
	Duration	: 500 +24/-0 hrs
	Recovery	: 24±2hrs under the standard condition Note3
	recovery	. 24 - 2113 dilddi dio standard Condition Notico
6 III-l- T	1	
6. High Temperatu		40=
	Temperature Compensating	
	Appearance	: No abnormality
	Capacitance change	: C※≦10pF:±0.3pF C※>10pF:±3%
	Insulation resistance	:1000M Ω min
Specified Value		
,	High permittivity	
	Appearance	: No abnormality
	Capacitance change	: Within ± 15%
	Dissipation factor	: 7%max(HMK,HMJ), 5%max(QMK,QMJ, SMK,SMJ).
	Insulation resistance	: $50M\Omega \mu F$ or $1000M\Omega$, whichever is smaller.
	According to JIS 5102 claus	se 9.10.
	Preconditioning	: Voltage treatment Note2 (Only High permittivity)
	Temperature	: Maximum operating temperature
est Methods and	Applied voltage	: Rated voltage × 2 (HMK,HMJ,QVS) Rated voltage × 1.5 (QMK,QMJ) Rated voltage × 1.2 (SMK,SMJ)
Remarks	Charge/discharge current	: 50mA max.
	Duration	1000 + 24/-0 hrs
	Recovery	: 24±2hrs under the standard condition Note3
lote1 Thermal tracture	-	d after test sample is heat-treated at 150+0/-10°C for an hour and kept at room temperature
iote i i nermai treatm	ent : Initial value shall be measure for 24±2hours.	u alter test sample is neat-treated at 130 ±0/ = 10 € for an nour and kept at room temperature
lote2 Voltage treatme		ed after test sample is voltage-treated for an hour at both the temperature and voltage specified in
		I kept at room temperature for 24±2hours.
lote3 Standard condit	tion : Temperature: 5 to 35°C, Re	elative humidity: 45 to 85 % RH, Air pressure: 86 to 106kPa
	When there are questions of	oncerning measurement results, in order to provide correlation data, the test shall be conducted
	and the second s	

Temperature: 20±2°C, Relative humidity: 60 to 70 % RH, Air pressure: 86 to 106kPa Unless otherwise specified, all the tests are conducted under the "standard condition".

under the following condition.

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Multilayer Ceramic Capacitors

■ RELIABILITY DATA

Test

Methods and

Remarks

Applied voltage

Charge/discharge current

Duration

KELIABILIT	. 2						
1.Operating Te	mperature Range						
	Temperature	Standard					
	Compensating (Class1)	High Frequency Type	-55 to -	+125°C			
	Componicating (Class 1)	7					
				Specification	Temperature	Pange	
				B	-25 to +		
					-55 to +		
Specified		B7	X5R X7R	-55 to +1			
Value	High Permittivity (Class2	C6	X6S	-55 to +1			
	Trigit i Citrictivity (Olassz	,	C7	X7S	-55 to +1		
			D7	X7T	-55 to +1		
			LD(※)	X5R	-55 to +		
			<u> </u>	LD Low distortion I			
				.,	g		
	•		1				
2 Stawara Can	ditions						
2. Storage Cor	laitions	1	1				
	Temperature Standard			−55 to +125°C			
	Compensating(Class1)	High Frequency Type	9				
				Specification	Temperature	Range	
			Б.	В	-25 to +	85°C	
Specified			BJ	X5R	-55 to +	85°C	
Value			B7	X7R	-55 to +1	25°C	
	High Permittivity (Class2)		C6	X6S	−55 to +1	05°C	
			C7	X7S	−55 to +1	25°C	
			D7	X7T	−55 to +1	25°C	
			LD(※)	X5R	-55 to +	85°C	
				KLD Low distortion №	nigh value multilayer	ceramic capa	
3. Rated Volta	ge						
			50VDC 25	50VDC, 25VDC			
Specified	Temperature Compensating(Class1)						
Value		High Frequency Type		50VDC, 25VDC			
	High Permittivity (Class2)		50VDC, 3	5VDC, 25VDC, 16VD	C, 10VDC, 6.3VDC,	4VDC, 2.5VDC	
4. Withstanding	y Voltage (Between termina	ls)					
	Temperature	Standard					
Specified	Compensating (Class 1)		No break	No breakdown or damage			
Value		High Frequency Type	e No breakd	lown or damage			
	High Permittivity (Class2)					
T 4		(Class 1	(Class 2		
Test Methods and	Applied voltage	Rate	d volta × 3	Rated	voltage × 2.5		
Remarks	Duration			1 to 5 sec.			
Ciliains	Charge/discharge curren	nt		50mA max.			
			·				
5. Insulation Re	asistance						
J. Misulation Re		0					
	Temperature	Standard	10000 M S	2 min.			
Specified	Compensating(Class1)	High Frequency Type	9				
Value	High Demokratic to (OL C) N-+- 1	C≦0.047	μ F : 10000 MΩ min	l.		
	High Permittivity (Class2) Note I		<i>μ</i> F : 500M Ω • <i>μ</i> F			
T 4	Applied veltage						

: Rated voltage

: 60±5 sec.

: 50mA max.

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6. Capacitance	(Tolerance)					
Specified Value	Temperature Compensating(Class1)	Standard	C□ U□ SL		: ±0.25pF : ±0.5pF : ±5% or ±10%	
	Compensating (Class I)	High Frequency Type	СН	0.3pF≦C≦2pF C>2pF	: ±0.1pF : ±5%	
	High Permittivity (Class2)			7, C6, C7, D7, LD(※) : = ※LD Low distortion hig	±10% or ±20% h value multilayer cerami	c capacitor
					CI	ass 2
- .		Standa	rd	High Frequency Type	C≦10 μ F	C>10 μ F
Test	Preconditioning		None		Thermal treatment (a	at 150°C for 1hr) Note 2
Methods and Remarks	Measuring frequency		1MHz±10%		1kHz±10%	120±10Hz
	Measuring voltage Note		0.5 to 5Vrms		1±0.2Vrms	0.5±0.1rms
	Bias application		one			

Specified Value	Temperature Compensating(Class1)	:	Standard	C < 30pF : Q ≥ 400 + 20C C ≥ 30pF : Q ≥ 1000 (C:Nominal capacitance)				
	Compensating (Glass I)	High Frequency Type		Refer to detailed specification				
	High Permittivity (Class2) Note 1			BJ, B7, C6, C7, D7:2.5% max.				
				Cla	ss 1	Class 2		
			Standard		High Frequency Type	C≦10 <i>μ</i> F	C>10 μ F	
	Preconditioning			None		Thermal treatment (at 150°C for 1hr) Note:		
Test	Measuring frequey		1MHz±10%		1GHz	1kHz±10%	120±10Hz	
Methods and	Measuring voltage Note 1			0.5 to	5Vrms	1±0.2Vrms	0.5±0.1Vrms	
Remarks	Bias application			None				
	High Frequency Type							
	Measuring equipment	: HP	4291A					
	Measuring jig	: HP	16192A					

8. Temperature	e Characteristic (Without vo	ltage application)						
			Tem	perature Chara	cteristic [ppm/°	C] Tole	erance [ppm/°C]	
		Standard	C□: 0					
	Temperature Compensating(Class1)	Standard	U□ :	— 750	UJ, UK		J: ±120 K: ±250	
			SL :	+350 to −100	00			
		High Frequency Type	Tem	Temperature Characteristic [ppm/°C		C] Tole	Tolerance [ppm/°C]	
		Trigit i requericy Type	C□:	C□: 0 CH			H: ±60	
Specified				Specification	Capacitance	Reference	Tomporatura Panga	
Value			$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	Temperature Nange				
			ВΙ	В	±10%	20°C	−25 to +85°C	1: ±60 Temperature Range -25 to +85°C -55 to +85°C -55 to +125°C
			ВО	X5R	±15%	25°C	−55 to +85°C	
	High Downittivity (Class)	1	B7	X7R	±15%	25°C	−55 to +125°C	
	High Permittivity (Class2)	,	C6	X6S	±22%	25°C	−55 to +105°C	
			C7	X7S	±22%	25°C	−55 to +125°C	
			D7	X7S	+22/-33%	25°C	−55 to +125°C	
			LD(※)	X5R	±15%	25°C	-55 to +85°C	
			Note:	LD Low disto	ortion high value	multilayer ceran	nic capacitor	-1

Class 1

Capacitance at 20° C and 85° C shall be measured in thermal equilibrium, and the temperature characteristic shall be calculated from the following equation.

$$\frac{(C_{85}-C_{20})}{C_{20}\times\Delta T} \times 10^{6} (ppm/^{\circ}C) \qquad \Delta T = 65$$

Test Methods and Remarks

Class 2

Capacitance at each step shall be measured in thermal equilibrium, and the temperature characteristic shall be calculated from the following equation.

1 Minimum operating temperature 2 20°C 25°C	Step	В	X5R, X7R, X6S, X7S, X7T		
2 200	1	Minimum operat	ng temperature		
	2	20°C	25°C		
3 Maximum operating temperature	3	Maximum operat	ing temperature		

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 $\frac{(C-C_2)}{C_2}$ × 100(%)

C : Capacitance in Step 1 or Step 3

C2 : Capacitance in Step 2

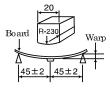
9. Deflection : No abnormality Appearance Standard Capacitance change : Within $\pm 5\%$ or ± 0.5 pF, whichever is larger. Temperature Compensating (Class 1)Appearance : No abnormality Specified High Frequency Type : Within±0.5 pF Cpaitance change Value Appearance : No abnormality Capacitance change : Within ±12.5%(BJ, B7, C6, C7, D7, LD(*)) High Permittivity (Class2)

Test Methods and

Remarks

	Multilayer Cera	mic Capacitors			
	042, 063, ^{※1} 105 Type	The other types			
Board	Glass epoxy-resin substrate				
Thickness	0.8mm	1.6mm			
Warp	1mm (Soft Termination type:3mm)				
Duration	ration 10 sec.				





Note: XLD Low distortion high value multilayer ceramic capacitor

(Unit: mm)

Capacitance measurement shall be conducted with the board bent

10. Body Stren	10. Body Strength					
	Temperature	Standard	1			
Specified Value	Compensating(Class1)	High Frequency Type	No mechanical damage.			
Value	High Permittivity (Class2))	_			
Test Methods and Remarks	High Frequency Type Applied force : 5N Duration : 10 sec.	Pres ← A →	R0.5 Pressing Jig Chip A			

11. Adhesive St	11. Adhesive Strength of Terminal Electrodes							
0 15 1	Temperature	Standard						
Specified Value	Compensating(Class1)	High Frequency Type	No terminal separati	on or its indication.				
	High Permittivity (Class	2)						
		Multilayer Ceramio	Capacitors	Hooked jig				
Test	042, 063 Type		105 Type or more					
Methods and	Applied force	2N	5N	R=05 Doard				
Remarks	Duration	30±5 se	ec.					
				Chip				
				Chip				

12. Solderability	12. Solderability							
	Temperature Standard							
Specified Value	Compensating(Class1)	High Frequency Type	At least 95%	of terminal electrode is covered	by new solder.			
Value	High Permittivity (Class2))						
T4		Eutectic so	older	Lead-free solder				
Test	Solder type	H60A or H	63A	Sn-3.0Ag-0.5Cu				
Methods and	Solder temperature	230±5°	С	245±3°C				
Remarks	Duration		4±1	sec.				

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13. Resistance	to Soldering						
Specified Value	Temperature	Standard	Appearance Capacitance change Q Insulation resistance Withstanding voltage	: No abnormality : Within ±2.5% or ±0 : Initial value : Initial value (between terminals)	0.25pF, whichever is larger. : No abnormality		
	Compensating(Class1)	High Frequency Type	Appearance Capacitancecange Q Insulation resistance Withstanding voltage	: No abnormality : Within ±2.5% : Initial value : Initial value (between terminals): No abnormality			
	High Permittivity(Class	2) Note 1	Appearance : No abormality Capactace change : Within ±7.5%(BJ, E Dissipation factor : Initial value Insulation resistance : Initial value Withstanding voltage (between terminals) Note: ※LD Low distortion high value multilay		•		
			lss 1				
		042, 063 Type	1	I05 Type			
	Preconditioning		None				
	Preheating	150°C, 1 to 2 min.		00°C, 2 to 5 min. 00°C, 2 to 5 min.			
	Solder temp.		270±5°C				
	Duration						
Гest Methods and	Recovery	6 to 24 hrs	s(Standard condition)	Noe 5			
Remarks				Class 2			
		042、063 Type	105, 1	107, 212 Type	316, 325 Type		
	Preconditioning		Thermal treatment	(at 150°C for 1 hr) No	ote 2		
	Preheating	150°C, 1 to 2 min.		00°C, 2 to 5 min. 00°C, 2 to 5 min.	80 to 100°C, 5 to 10 min. 150 to 200°C, 5 to 10 min.		
	Solder temp.			270±5℃			
	Duration		3	±0.5 sec.			
	Recovery		3±0.5 sec. 24±2 hrs(Standard condition)Note 5				

14. Temperatur	re Cycle (Thermal Shock)						
	Standard Temperature		$ \begin{array}{llllllllllllllllllllllllllllllllllll$		·		
Specified Value	Compensating(Class1)	High Frequency Type		Capacitance change : W Q : Ir Insulation resistance : Ir	: No abnormality : Within ±0.25pF : Initial value : Initial value (between terminals) : No abnormality		
	High Permittivity(Class2	Insulation resistance Withstanding voltage		Capacitance change : W Dissipation factor : In Insulation resistance : In Withstanding voltage (be	: No abnormality : Within ±7.5%(BJ, B7, C6, C7, D7, LD(※)) : Initial value : Initial value (between terminals): No abnormality rtion high value multilayer ceramic capacitor		
		Class 1			Class 2		
	Preconditioning			None Thermal treatment (at 150°C for Note 2			
Test Methods and Remarks	1 cycle	-	Step 1 2 3 4	Temperatur Minimum operating Normal temperating Maximum operating Normal temperating	temperature erature temperature	Time(min.) 30±3 2 to 3 30±3 2 to 3	
	Number of cycles			5 t	times		
	Recovery	6 to 24 hrs	(Stan	dard condition)Note 5	24±2 hrs (S	standard condition)Note 5	

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15. Humidity(Steady State)				
	Temperature Compensating(Class1	Standard Capacitance change : Q :		: No abnormality : Within $\pm 5\%$ or $\pm 0.5 pF$, whichever is larger. : $C < 10 pF$: $Q \ge 200 + 10 C$ $10 \le C < 30 pF$: $Q \ge 275 + 2.5 C$ $C \ge 30 pF$: $Q \ge 350 (C$: Nominal capacitance) : $1000 \ M\Omega$ min.	
Specified Value		High Frequency Type	Appearance Capacitance change Insulation resistance	: No abnormality : Within $\pm 0.5 \text{pF},$: 1000 M Ω min.	
	High Permittivity(Cla	ass2) Note 1		: No abnormality : Within \pm 12.5% (BJ, B7, C6, C7, D7, LD(\divideontimes)) : 5.0% max.(BJ, B7, C6, C7, D7, LD(\divideontimes)) : 50 M Ω μ F or 1000 M Ω whichever is smaller. on high value multilayer ceramic capacitor	
			ass 1	Class 2	
Test	Preconditioning	Standard N	High Frequency Type	All items Thermal treatment(at 150°C for 1 hr) Note 2	
Methods and	Temperature	40±2°C	60±2°C	40±2°C	
Remarks	Humidity	90 to	95%RH	90 to 95%RH	
	Duration	500+2	4/-0 hrs	500+24/-0 hrs	
	Recovery	6 to 24 hrs (Stand	ard condition)Note 5	24±2 hrs(Standard condition)Note 5	

16. Humidity Lo	pading					
	Temperature	Standard	Appearance Capacitance change Q Insulation resistance	: Wit : C < C≧	abnormality thin $\pm 7.5\%$ or ± 0.75 pF, whichever is larger. < 30 pF: $Q \ge 100 + 10$ C/3 ≥ 30 pF: $Q \ge 200$ (C: Nominal capacitance) 0 M Ω min.	
Specified Value	Compensating(Class1)	High Frequency Type Capacitance change : Capacitanc			abnormality ≦2pF∶Within ±0.4 pF >2pF∶Within ±0.75 pF (C∶Nominal capacitance) 0 MΩ min.	
	High Permittivity(Class2) Note 1	Appearance : No abnormality Capacitance change : Within $\pm 12.5\%$ (BJ, B7, C6, C7, D7, LD($\%$)) Dissipation factor : 5.0% max. (BJ, B7, C6, C7, D7, LD($\%$)) Insulation resistance : 25 M Ω μ F or 500 M Ω , whichever is smaller. Note: $\%$ LD Low distortion high value multilayer ceramic capacitor		thin ±12.5ν (BJ, B7, C6, C7, D7, LD(※)) % max. (BJ, B7, C6, C7, D7, LD(※)) ΜΩ μF or 500 ΜΩ, whichever is smaller.	
		C	Class 1		Class 2	
		Standard	High Frequency Type		All items	
	Preconditioning		None		Voltage treatment (Rated voltage are applied for 1 hour at 40°C) Note 3	
Test	Temperature	40±2°C	60±2°C		40±2°C	
Methods and	Humidity	90 t	90 to 95%RH		90 to 95%RH	
Remarks	Duration	500+	24/-0 hrs		500+24/-0 hrs	
	Applied voltage	Rate	d voltage		Rated voltage	
	Charge/discharge current	50r	mA max.		50mA max.	
	Recovery	6 to 24 hrs (Stan	dard condition)Note 5		24±2 hrs (Standard condition) Note 5	

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17. High Tempe	erature Loading					
Specified Value	Temperature Compensating(Class1)	Standard	Appearance Capacitance change Q Insulation resistance	: C<10pF: Q≧200+10C 10≦C<30pF:Q≧275+2.5C C≧30pF: Q≧350(C:Nominal capacitance)		
		High Frequency Type	Appearance Capacitance change Insulation resistance			
	High Permittivity (Class2) Note 1		Appearance Capacitance change Dissipation factor Insulation resistance Note: **LD Low dis*	: 5.0% max.(BJ,	6(BJ, B7, C6, C7, D B7, C6, C7, D7, LD(1000 MΩ, whicheve	ێ)) r is smaller.
		Class 1		Class 2		
		Standard H	High Frequency Type	BJ, LD(※)	C6	B7, C7, D7
	Preconditioning	None		Voltage treatment (Twice the rated voltage shall be applied for 1 hour at 85°C, 105°C or 125°C) Note 3, 4		
Test	Temperature	Maximum operating temperature		Maximum operating temperature		
Methods and	Duration	1000+48	/-0 hrs	1000+48/-0 hrs		
Remarks	Applied voltage	Rated vol	tage × 2	Rated voltage × 2 Note 4		
	Charge/discharge current	50mA max.		50mA max.		
	Recovery	6 to 24hr(Standard	condition) Note 5	24±2 hrs(Standard condition)Note 5		
			Note:	※LD Low distortion	on high value multil	ayer ceramic capacitor

Note 1 The figures indicate typical specifications. Please refer to individual specifications in detail.

- Note 2 Thermal treatment : Initial value shall be measured after test sample is heat-treated at $150 + 0/-10^{\circ}$ C for an hour and kept at room temperature for 24 ± 2 hours.
- Note 3 Voltage treatment: Initial value shall be measured after test sample is voltage—treated for an hour at both the temperature and voltage specified in the test conditions, and kept at room temperature for 24±2hours.
- Note 4 150% of rated voltage is applicable to some items. Please refer to their specifications for further information.
- Note 5 Standard condition: Temperature: 5 to 35°C, Relative humidity: 45 to 85 % RH, Air pressure: 86 to 106kPa When there are questions concerning measurement results, in order to provide correlation data, the test shall be conducted under the following condition.
 - Temperature: 20±2°C, Relative humidity: 60 to 70 % RH, Air pressure: 86 to 106kPa Unless otherwise specified, all the tests are conducted under the "standard condition".

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Medium-High Voltage Multilayer Ceramic Capacitor

100VDC(HMK,HMJ), 250VDC(QMK,QMJ,QVS), 630VDC(SMK,SMJ)

: 50mA max.

■ RELIABILITY DATA

	Temperature Compensating(High Frequency type) CG(C0G) : -55 to +125°C			
Specified Value	High permittivity			
	X7R, X7S : −55 to +125°C			
	X5 : -55 to +85°C			
	B : -25 to +85°C			
2. Storage Tempe	Temperature Compensating(High Frequency type) CG(C0G) : -55 to +125°C			
	High permittivity			
Specified Value	High permittivity			
Specified Value	High permittivity X7R, X7S : −55 to +125°C			
Specified Value				

Carge/discharge current

4. Withstanding Volt	tage (Between terminals)	
Specified Value	No breakdown or damage	
Test Methods and Remarks	Applied voltage Duration	: Rated voltage × 2.5 (HMK,HMJ), Rated voltage × 2 (QMK,QMJ,QVS), Rated voltage × 1.2 (SMK,SMJ) : 1 to 5 sec.

5. Insulation Resistance

3. Rated Voltage
Specified Value

Specified Value	Temperature Compensating 10000M Ω min	(High Frequency type)
•	High permittivity 100M Ω μ F or 10G Ω , which	never is smaller.
Test Methods and Remarks	Applied voltage Duration Charge/discharge current	: Rated voltage(HMK,HMJ, QMK,QMJ,QVS), 500V(SMK,SMJ) : 60±5sec. : 50mA max.

6. Capacitance (Tolerance)
------------------	------------

Specified Value	Temperature Compensating(High Frequency type) $\pm 0.1 pF (C < 5pF) \pm 0.25pF (C < 10pF) \pm 0.5pF (5pF \le C < 10pF) \pm 2\%(C = 10pF) \pm 5\%(C \ge 10pF)$ High permittivity $\pm 10\%, \pm 20\%$		
Test Methods and Remarks	Temperature Compensating Measuring frequency Measuring voltage Bias application High permittivity Measuring frequency Measuring voltage Bias application	g(High Frequency type) : 1MHz±10% : 0.5 to 5Vrms : None : 1kHz±10% : 1±0.2Vrms : None	

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7. Q or Dissipation	Factor	
	Temperature Compensatin	g(High Frequency type)
	C<30pF: Q≧800+20C	
	C≧30pF: Q≧1400 (C:Normal Capacitance(/pF)
Specified Value		
	High permittivity	
	3.5%max(HMK,HMJ)	
	2.5%max(QMK,QMJ, SMK,S	SMJ)
	Temperature Compensatin	g(High Frequency type)
	Measuring frequency	: 1MHz±10%
	Measuring voltage	: 0.5 to 5Vrms
Test Methods and	Bas application	: None
Remarks	High permittivity	
	Measuring frequency	: 1kHz±10%
	Measuring voltage	: 1 ± 0.2 Vrms
	Bas application	: None

8. Temperature Ch	aracteristic of Capacitance
· ·	Temperature Compensating(High Frequency type) COG :±30ppm(25 to +125°C)
Specified Value	High permittivity B : ±10%(-25 to +85°C) X5R : ±15%(-55 to +85°C) X7R : ±15%(-55 to +125°C) X7S : ±22%(-55 to +125°C)
	Temperature Compensating(High Frequency type) Capacitance at 25°C and 85°C shall be measured in thermal equilibrium, and the temperature characteristic shall be calculated from the following equation. $\frac{(C_{85}-C_{25})}{C_{25}\times\Delta T}\times 10^6\times [\text{ppm/°C}]$ High permittivity Capacitance value at each step shall be measured in thermal equilibrium, and the temperature characteristic shall be calculated from the following equation.
Test Methods and Remarks	Step B X5R, X7R, X7S 1 Minimum operating tempeature 2 20°C 25°C 3 Maximum operating temperature

	Temperature Compensating(High Frequency type)
	Appearance : No abnormality
	Capacitance change :±5% or ±0.5pF, whichever is larger.
Specified Value	
	High permittivity
	Appearance : No abnormality Capacitance change : Within±10%
Test Methods and Remarks	Warp : 1mm (Soft Termination type:3mm) Duration : 10sec. Test board : Glass epoxy-resin substrate Thicknss : 1.6mm Board R-230 Warp
	(Unit: mm)
	Capacitance measurement shall be conducted with the board bent.

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10. Adhesive Strength of Terminal Electrodes Specified Value No terminal separation or its indication. Temperature Compensating(High Frequency type) Applied force : 2N Hooked jig Duration : 10±5sec. Test Methods and Remarks High permittivity Applied force : 5N Hooked jig Duration : 30±5sec. Board

11. Solderability				
Specified Value	At least 95% of terminal electrode is covered by new solder			
		Eutectic solder	Lead-free solder	
Test Methods and	Solder type	H60A or H63A	Sn-3.0Ag-0.5Cu	
Remarks	Solder temperature	230±5°C	245±3°C	
	Duration	4±1	sec.	

12. Resistance to S	Soldering		
	Temperature Compensating(High Frequency type)		
	Appearance	: No abnormality	
	Capacitance change	: C※≦10pF :±0.25pF C※>10pF :±2.5% ※Normal capacitance	
	Insulation resistance	: Initial value	
	Withstanding voltage	(between terminals): No abnormality	
Specified Value	High permittivity		
	Appearance	: No abnormality	
	Capacitance change	: Within±15%(HMK,HMJ), ±10%(QMK,QMJ, SMK,SMJ)	
	Dissipation factor	: Inital value	
	Insulation resistance	: Initial value	
	Withstanding voltage	(between terminals): No abnormality	
	Preconditioning	: Thermal treatment (at 150°C for 1hr) Note1 (Only High permittivity)	
Test Methods and	Solder temperature	: 270±5℃	
Remarks	Duration	: 3±0.5sec.	
remarks	Preheating conditions	: 80 to 100°C, 2 to 5 min. 150 to 200°C, 2 to 5min.	
	Recovery	: 24±2hrs under the stadard condition Note3	

	•				
13. Temperature Cycle(Thermal Shock)					
	Temperati	ure Compens	ating(High Frequency type)		
	Appearance	ce	: No abnormality		
	Capacitan	ce change	: C※≦10pF :±0.25% C※>10pF :±2.5%		
	Insulation	resistance	: Initial value		
	Withstand	ing voltage	(between terminals): No abnormality		
Specified Value	High perm	ittivity			
	Appearance		: No abnormality		
	Capacitance change		: Within±15%(HMK,HMJ), ±7.5%(QMK,QMJ, SMK,SMJ)		
	Dissipation factor		: Initial value		
	Insulation resistance		: Initial value		
	Withstanding voltage (between terminals): No abnormality				
	Preconditi	ioning : Thern	nal treatment (at 150°C for 1hr) Note1		
	Conditions	s for 1 cycle			_
	Step		temperature (°C)	Time (min.)	
Test Methods and	1		Minimum operating temperature	30±3min.	
Remarks	2		Normal temperature	2 to 3min.	
TOHIGHTS	3		Maximum operating temperature	30±3min.	
	4		Normal temperature	2 to 3min.]
	Number of	f cycles : 5 ti	mes		
	Recovery	: 24±2hrs u	nder the standard condition Note3		

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ļ.	Temperature Compensating	(High Frequency type)
	Appearance	: No abnormality
	Capacitance change	: C※≦10pF :±0.5pF C※>10pF :±5%
	Insulation resistance	: $1000M\Omega$ min
Specified Value	100-de la companio de la	
	High permittivity	AL L. P.
	Appearance Capacitance change	: No abnormality : Within±15%
	Dissipation factor	: Within±15% : 7%max(HMK,HMJ), 5%max(QMK,QMJ, SMK,SMJ).
	Insulation resistance	: 76 max (1 mM $_{\odot}$), 56 max (1 mM $_{\odot}$), 1 max (1 mM $_{\odot}$). : 25 M Ω μ F or 1000 M Ω , whichever is smaller.
	Preconditioning	: Thermal treatment (at 150°C for 1hr) Note1 (Only High permittivity)
	Temperature	: 40±2°C
Test Methods and	Humidity	: 90 to 95%RH
Remarks	Duration	: 500 + 24/-0 hrs
	Recovery	: 24±2hrs under the standard condition Note3
5. Humidity Loadin	ıg	
	Temperature Compensating	
	Appearance	: No abnormality
	Capacitance change	: C※≦2.0pF :±0.4pF 2.0pF < C≦10pF : ±0.75pF C※>10pF :±7.5% : ※Normal capacitance
	Insulation resistance	: %Normal capacitance
Specified Value	Insulation resistance	. 30000 32 111111
specified value	High permittivity	
	Appearance	: No abnormality
	Capacitance change	: Within±15%
	Dissipation factor	: 7%max(HMK,HMJ), 5%max(QMK,QMJ, SMK,SMJ).
	Insulation resistance	: 10M Ω μ F or 500M Ω , whichever is smaller.
	According to JIS 5102 claus	se 9.9.
ļ	Preconditioning	: Voltage treatment Note2 (Only High permittivity)
	Temperature	: 40±2°C
Test Methods and	Humidity	: 90 to 95%RH
Remarks	Applied voltage	: Rated voltage
ļ	Charge/discharge current	: 50mA max.
ļ	Duration	: 500 + 24/-0 hrs
	Recovery	: 24±2hrs under the standard condition Note3
0 IF I T	1 2	
16. High Temperatu		
16. High Temperatu	Temperature Compensating	
I 6. High Temperatu	Temperature Compensating Appearance	: No abnormality
16. High Temperatu	Temperature Compensating Appearance Capacitance change	: No abnormality : C%≤10pF :±0.3pF C%>10pF :±3%
6. High Temperatu	Temperature Compensating Appearance	: No abnormality
	Temperature Compensating Appearance Capacitance change Insulation resistance	: No abnormality : C%≤10pF :±0.3pF C%>10pF :±3%
	Temperature Compensating Appearance Capacitance change Insulation resistance High permittivity	: No abnormality : $C \approx 10 \text{pF} : \pm 0.3 \text{pF}$ $C \approx 10 \text{pF} : \pm 3\%$: $1000 \text{M} \Omega \text{ min}$
	Temperature Compensating Appearance Capacitance change Insulation resistance High permittivity Appearance	: No abnormality : $C \approx 10 pF :\pm 0.3 pF$ $C \approx 10 pF :\pm 3\%$: $1000 M \Omega min$: No abnormality
	Temperature Compensating Appearance Capacitance change Insulation resistance High permittivity Appearance Capacitance change	: No abnormality : $C \approx 10 \text{pF} : \pm 0.3 \text{pF}$ $C \approx 10 \text{pF} : \pm 3\%$: $1000 \text{M} \Omega \text{ min}$: No abnormality : Within $\pm 15\%$
	Temperature Compensating Appearance Capacitance change Insulation resistance High permittivity Appearance	: No abnormality : $C \approx 10 pF :\pm 0.3 pF$ $C \approx 10 pF :\pm 3\%$: $1000 M \Omega min$: No abnormality
	Temperature Compensating Appearance Capacitance change Insulation resistance High permittivity Appearance Capacitance change Dissipation factor	: No abnormality : C ≤ 10pF :±0.3pF C > 10pF :±3% :1000M Ω min : No abnormality : Within±15% : 7*max(HMK,HMJ), 5*max(QMK,QMJ, SMK,SMJ). : 50M Ω μ F or 1000M Ω, whichever is smaller.
	Temperature Compensating Appearance Capacitance change Insulation resistance High permittivity Appearance Capacitance change Dissipation factor Insulation resistance	: No abnormality : C ≤ 10pF :±0.3pF C > 10pF :±3% :1000M Ω min : No abnormality : Within±15% : 7*max(HMK,HMJ), 5*max(QMK,QMJ, SMK,SMJ). : 50M Ω μ F or 1000M Ω, whichever is smaller.
Specified Value	Temperature Compensating Appearance Capacitance change Insulation resistance High permittivity Appearance Capacitance change Dissipation factor Insulation resistance According to JIS 5102 claus	: No abnormality $: C \not \cong \le 10 \text{pF} : \pm 0.3 \text{pF} C \not \otimes > 10 \text{pF} : \pm 3\%$ $: 1000 \text{M} \Omega \text{ min}$ $: \text{No abnormality}$ $: \text{Within} \pm 15\%$ $: 7\% \text{max} (\text{HMK}, \text{HMJ}), 5\% \text{max} (\text{QMK}, \text{QMJ}, \text{SMK}, \text{SMJ}).$ $: 50 \text{M} \Omega \mu \text{ F or } 1000 \text{M} \Omega, \text{ whichever is smaller.}$ se 9.10 .
Specified Value	Temperature Compensating Appearance Capacitance change Insulation resistance High permittivity Appearance Capacitance change Dissipation factor Insulation resistance According to JIS 5102 claus Preconditioning	: No abnormality : C ≤ 10pF :±0.3pF C > 10pF :±3% :1000M Ω min : No abnormality : Within±15% : 7 : 7 : 7 : 7 : 1000M Ω μ F or 1000M Ω, whichever is smaller. se 9.10. : Voltage treatment Note2 (Only High permittivity)
16. High Temperatu Specified Value Test Methods and Remarks	Temperature Compensating Appearance Capacitance change Insulation resistance High permittivity Appearance Capacitance change Dissipation factor Insulation resistance According to JIS 5102 claus Preconditioning Temperature	: No abnormality : C in ≤ 10pF:±0.3pF C in > 10pF:±3% :1000M Ω min : No abnormality : Within±15% : 7 in × 10max (HMK,HMJ), 5 in × 10max (
Specified Value	Temperature Compensating Appearance Capacitance change Insulation resistance High permittivity Appearance Capacitance change Dissipation factor Insulation resistance According to JIS 5102 claus Preconditioning Temperature Applied voltage	: No abnormality : C ≤ 10pF :±0.3pF C > 10pF :±3% :1000M Ω min : No abnormality : Within±15% : 7 max (HMK,HMJ), 5 max (QMK,QMJ, SMK,SMJ). : 50M Ω μ F or 1000M Ω, whichever is smaller. se 9.10. : Voltage treatment Note2 (Only High permittivity) : Maximum operating temperature : Rated voltage × 2 (HMK,HMJ,QVS) Rated voltage × 1.5 (QMK,QMJ) Rated voltage × 1.2 (SMK,SMJ)
Specified Value	Temperature Compensating Appearance Capacitance change Insulation resistance High permittivity Appearance Capacitance change Dissipation factor Insulation resistance According to JIS 5102 claus Preconditioning Temperature Applied voltage Charge/discharge current	: No abnormality : C ≤ ≤ 10pF :±0.3pF C > 10pF :±3% :1000M Ω min : No abnormality : Within±15% : 7 **max(HMK,HMJ), 5 **max(QMK,QMJ, SMK,SMJ). : 50M Ω μ F or 1000M Ω, whichever is smaller. se 9.10. : Voltage treatment Note2 (Only High permittivity) : Maximum operating temperature : Rated voltage × 2 (HMK,HMJ,QVS) Rated voltage × 1.5 (QMK,QMJ) Rated voltage × 1.2 (SMK,SMJ) : 50mA max.

Temperature: $20\pm2^{\circ}$ C, Relative humidity: 60 to 70 % RH, Air pressure: 86 to 106kPa Unless otherwise specified, all the tests are conducted under the "standard condition".

Note3 Standard condition : Temperature: 5 to 35°C, Relative humidity: 45 to 85 % RH, Air pressure: 86 to 106kPa

under the following condition.

When there are questions concerning measurement results, in order to provide correlation data, the test shall be conducted

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Precautions on the use of Multilayer Ceramic Capacitors

■PRECAUTIONS

1. Circuit Design

- ◆Verification of operating environment, electrical rating and performance
 - 1. A malfunction of equipment in fields such as medical, aerospace, nuclear control, etc. may cause serious harm to human life or have severe social ramifications.

Therefore, any capacitors to be used in such equipment may require higher safety and reliability, and shall be clearly differentiated from them used in general purpose applications.

Precautions

- ◆Operating Voltage (Verification of Rated voltage)
 - 1. The operating voltage for capacitors must always be their rated voltage or less.
 - If an AC voltage is loaded on a DC voltage, the sum of the two peak voltages shall be the rated voltage or less.
 - For a circuit where an AC or a pulse voltage may be used, the sum of their peak voltages shall also be the rated voltage or less.
 - 2. Even if an applied voltage is the rated voltage or less reliability of capacitors may be deteriorated in case that either a high frequency AC voltage or a pulse voltage having rapid rise time is used in a circuit.

2. PCB Design

Precautions

- ◆Pattern configurations (Design of Land-patterns)
- 1. When capacitors are mounted on PCBs, the amount of solder used (size of fillet) can directly affect the capacitor performance. Therefore, the following items must be carefully considered in the design of land patterns:
 - (1) Excessive solder applied can cause mechanical stresses which lead to chip breaking or cracking. Therefore, please consider appropriate land-patterns for proper amount of solder.
 - (2) When more than one component are jointly soldered onto the same land, each component's soldering point shall be separated by solder-resist.
- ◆Pattern configurations (Capacitor layout on PCBs)

After capacitors are mounted on boards, they can be subjected to mechanical stresses in subsequent manufacturing processes (PCB cutting, board inspection, mounting of additional parts, assembly into the chassis, wave soldering of the boards, etc.). For this reason, land pattern configurations and positions of capacitors shall be carefully considered to minimize stresses.

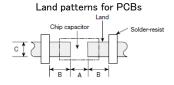
◆Pattern configurations (Design of Land-patterns)

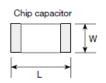
The following diagrams and tables show some examples of recommended land patterns to prevent excessive solder amounts.

- (1) Recommended land dimensions for typical chip capacitors
- Multilayer Ceramic Capacitors : Recommended land dimensions (unit: mm)

Wave-soldering

Туре		107	212	316	325
6:-0	┙	1.6	2.0	3.2	3.2
Size	W	0.8	1.25	1.6	2.5
A	١	0.8 to 1.0	1.0 to 1.4	1.8 to 2.5	1.8 to 2.5
E	3	0.5 to 0.8	0.8 to 1.5	0.8 to 1.7	0.8 to 1.7
С		0.6 to 0.8	0.9 to 1.2	1.2 to 1.6	1.8 to 2.5
	,	0.0 to 0.8	0.9 to 1.2	1.2 to 1.0	1.0 to 2.3





Reflow-soldering

Technical considerations

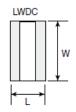
			0							
	Ту	ре	042	063	105	107	212	316	325	432
Ι,	Size	Г	0.4	0.6	1.0	1.6	2.0	3.2	3.2	4.5
Ľ	3126	W	0.2	0.3	0.5	0.8	1.25	1.6	2.5	3.2
	A	,	0.15 to 0.25	0.20 to 0.30	0.45 to 0.55	0.8 to 1.0	0.8 to 1.2	1.8 to 2.5	1.8 to 2.5	2.5 to 3.5
	Е	8	0.15 to 0.20	0.20 to 0.30	0.40 to 0.50	0.6 to 0.8	0.8 to 1.2	1.0 to 1.5	1.0 to 1.5	1.5 to 1.8
	C		0.15 to 0.30	0.25 to 0.40	0.45 to 0.55	0.6 to 0.8	0.9 to 1.6	1.2 to 2.0	1.8 to 3.2	2.3 to 3.5

Note: Recommended land size might be different according to the allowance of the size of the product.

●LWDC: Recommended land dimensions for reflow-soldering

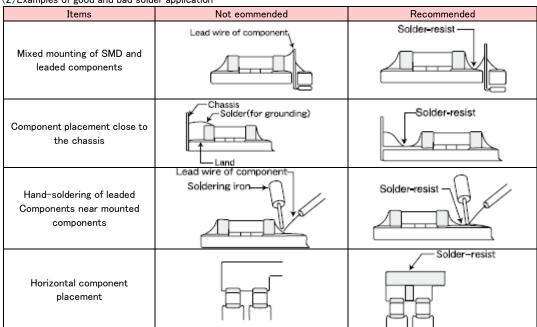
(unit: mm)

·				
Type		105	107	212
C: L		0.52	0.8	1.25
Size	W	1.0	1.6	2.0
Α		0.18 to 0.22	0.25 to 0.3	0.5 to 0.7
В		0.2 to 0.25	0.3 to 0.4	0.4 to 0.5
С		0.9 to 1.1	1.5 to 1.7	1.9 to 2.1



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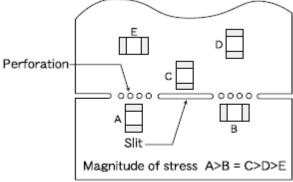
(2) Examples of good and bad solder application



- ◆Pattern configurations (Capacitor layout on PCBs)
 - 1-1. The following is examples of good and bad capacitor layouts; capacitors shall be located to minimize any possible mechanical stresses from board warp or deflection.

Items	Not recommended	Recommended	
Deflection of board			Place the product at a right angle to the direction of the anticipated mechanical stress.

1-2. The amount of mechanical stresses given will vary depending on capacitor layout. Please refer to diagram below.



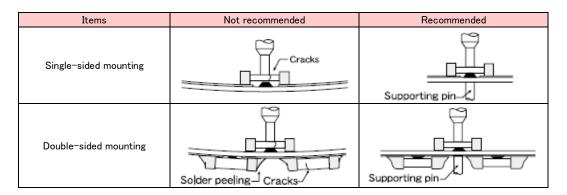
1-3. When PCB is split, the amount of mechanical stress on the capacitors can vary according to the method used. The following methods are listed in order from least stressful to most stressful: push-back, slit, V-grooving, and perforation. Thus, please consider the PCB, split methods as well as chip location.

Adjustment of mounting machine 1. When capacitors are mounted on PCB, excessive impact load shall not be imposed on them. 2. Maintenance and inspection of mounting machines shall be conducted periodically. ◆ Selection of Adhesives 1. When chips are attached on PCBs with adhesives prior to soldering, it may cause capacitor characteristics degradation unless the following factors are appropriately checked: size of land patterns, type of adhesive, amount applied, hardening temperature and hardening period. Therefore, please contact us for further information. ◆ Adjustment of mounting machine 1. When the bottom dead center of a pick-up nozzle is too low, excessive force is imposed on capacitors and causes damages. To avoid this, the following points shall be considerable. (1) The bottom dead center of the pick-up nozzle shall be adjusted to the surface level of PCB without the board deflection.

- considerations
- (1) The bottom dead center of the pick-up nozzle shall be adjusted to the surface level of PCB without the board deflection.

 (2) The pressure of nozzle shall be adjusted between 1 and 3 N static loads.
- (3) To reduce the amount of deflection of the board caused by impact of the pick-up nozzle, supporting pins or back-up pins shall be used on the other side of the PCB. The following diagrams show some typical examples of good and bad pick-up nozzle placement:

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2. As the alignment pin is worn out, adjustment of the nozzle height can cause chipping or cracking of capacitors because of mechanical impact on the capacitors.

To avoid this, the monitoring of the width between the alignment pins in the stopped position, maintenance, check and replacement of the pin shall be conducted periodically.

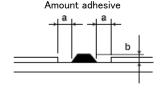
Selection of Adhesives

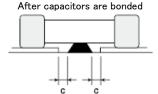
Some adhesives may cause IR deterioration. The different shrinkage percentage of between the adhesive and the capacitors may result in stresses on the capacitors and lead to cracking. Moreover, too little or too much adhesive applied to the board may adversely affect components. Therefore, the following precautions shall be noted in the application of adhesives.

- (1) Required adhesive characteristics
 - a. The adhesive shall be strong enough to hold parts on the board during the mounting & solder process.
 - b. The adhesive shall have sufficient strength at high temperatures.
 - c. The adhesive shall have good coating and thickness consistency.
 - d. The adhesive shall be used during its prescribed shelf life.
 - e. The adhesive shall harden rapidly.
 - f. The adhesive shall have corrosion resistance.
 - g. The adhesive shall have excellent insulation characteristics.
 - h. The adhesive shall have no emission of toxic gasses and no effect on the human body.
- (2) The recommended amount of adhesives is as follows;

[Recommended condition]

Figure	212/316 case sizes as examples	
a 0.3mm min		
b	100 to 120 μ m	
c Adhesives shall not contact land		





4. Soldering

Precautions

◆Selection of Flux

Since flux may have a significant effect on the performance of capacitors, it is necessary to verify the following conditions prior to use;

- (1) Flux used shall be less than or equal to 0.1 wt% (in Cl equivalent) of halogenated content. Flux having a strong acidity content shall not be applied.
- (2) When shall capacitors are soldered on boards, the amount of flux applied shall be controlled at the optimum level.
- (3) When water-soluble flux is used, special care shall be taken to properly clean the boards.

◆ Soldering

Temperature, time, amount of solder, etc. shall be set in accordance with their recommended conditions.

Sn-Zn solder paste can adversely affect MLCC reliability.

Please contact us prior to usage of Sn-Zn solder.

◆Selection of Flux

- 1-1. When too much halogenated substance (Chlorine, etc.) content is used to activate flux, or highly acidic flux is used, it may lead to corrosion of terminal electrodes or degradation of insulation resistance on the surfaces of the capacitors.
- 1-2. Flux is used to increase solderability in wave soldering. However if too much flux is applied, a large amount of flux gas may be emitted and may adversely affect the solderability. To minimize the amount of flux applied, it is recommended to use a flux-bubbling system.
- 1-3. Since the residue of water-soluble flux is easily dissolved in moisture in the air, the residues on the surfaces of capacitors in high humidity conditions may cause a degradation of insulation resistance and reliability of the capacitors. Therefore, the cleaning methods and the capability of the machines used shall also be considered carefully when water-soluble flux is used.

Technical considerations

♦Soldering

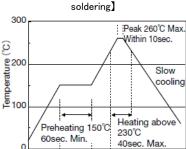
- · Ceramic chip capacitors are susceptible to thermal shock when exposed to rapid or concentrated heating or rapid cooling.
- · Therefore, the soldering must be conducted with great care so as to prevent malfunction of the components due to excessive thermal
- Preheating: Capacitors shall be preheated sufficiently, and the temperature difference between the capacitors and solder shall be within 100 to 130°C.
- · Cooling : The temperature difference between the capacitors and cleaning process shall not be greater than 100°C.
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[Reflow soldering]

[Recommended conditions for eutectic

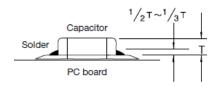
soldering Preheating 230°C Within 10 sec. 60sec 60sec Temperature (°C) 200 Min. Slow cooling 100

Recommended condition for Pb-free



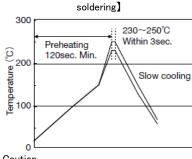
Caution

- \bigcirc The ideal condition is to have solder mass(fillet) controlled to 1/2 to 1/3 of the thickness of a capacitor.
- ②Because excessive dwell times can adversely affect solderability, soldering duration shall be kept as close to recommended times as possible.
- ③Allowable number of reflow soldering: 2 times max.

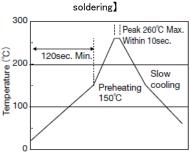


[Wave soldering]

[Recommended conditions for eutectic



[Recommended condition for Pb-free

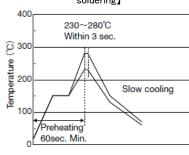


Caution

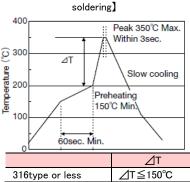
- ①Wave soldering must not be applied to capacitors designated as for reflow soldering only.
- 2 Allowable number of wave soldering: 1 times max.

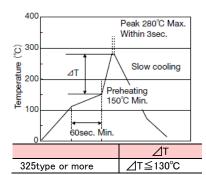
[Hand soldering]

[Recommended conditions for eutectic soldering]



[Recommended condition for Pb-free





- ①Use a 50W soldering iron with a maximum tip diameter of 1.0 mm.
- 2The soldering iron shall not directly touch capacitors.
- 3 Allowable number of hand soldering: 1 times max.

5. Cleaning

◆Cleaning conditions

Precautions

- 1. When PCBs are cleaned after capacitors mounting, please select the appropriate cleaning solution in accordance with the intended use of the cleaning. (e.g. to remove soldering flux or other materials from the production process.)
- 2. Cleaning condition shall be determined after it is verified by using actual cleaning machine that the cleaning process does not affect capacitor's characteristics.

Technical considerations

- 1. The use of inappropriate cleaning solutions can cause foreign substances such as flux residue to adhere to capacitors or deteriorate their outer coating, resulting in a degradation of the capacitor's electrical properties (especially insulation resistance).
- 2. Inappropriate cleaning conditions (insufficient or excessive cleaning) may adversely affect the performance of In the case of ultrasonic cleaning, too much power output can cause excessive vibration of PCBs which may lead cracking of capacitors or the soldered portion, or decrease the terminal electrodes' strength. Therefore, the following conditions shall be carefully checked;

Ultrasonic output: 20 W/ ℓ or less Ultrasonic frequency: 40 kHz or less

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	Ultrasonic washing period : 5 min. or less
6. Resin coating	and mold
Precautions	 With some type of resins, decomposition gas or chemical reaction vapor may remain inside the resin during the hardening period o while left under normal storage conditions resulting in the deterioration of the capacitor's performance. When a resin's hardening temperature is higher than capacitor's operating temperature, the stresses generated by the excessive hea
	may lead to damage or destruction of capacitors. The use of such resins, molding materials etc. is not recommended.

7. Handling	
	◆Splitting of PCB 1. When PCBs are split after components mounting, care shall be taken so as not to give any stresses of deflection or twisting to the board. 2. Board separation shall not be done manually, but by using the appropriate devices.
Precautions	 ◆Mechanical considerations Be careful not to subject capacitors to excessive mechanical shocks. (1) If ceramic capacitors are dropped onto a floor or a hard surface, they shall not be used. (2) Please be careful that the mounted components do not come in contact with or bump against other boards or components.

8. Storage condi	tions			
Precautions	 ◆Storage 1. To maintain the solderability of terminal electrodes and to keep packaging materials in good condition, care must be taken to control temperature and humidity in the storage area. Humidity should especially be kept as low as possible. •Recommended conditions Ambient temperature: Below 30°C Humidity: Below 70% RH The ambient temperature must be kept below 40°C. Even under ideal storage conditions, solderability of capacitor is deteriorated as time passes, so capacitors shall be used within 6 months from the time of delivery. •Ceramic chip capacitors shall be kept where no chlorine or sulfur exists in the air. The capacitance values of high dielectric constant capacitors will gradually decrease with the passage of time, so care shall be taken to design circuits. Even if capacitance value decreases as time passes, it will get back to the initial value by a heat treatment at 150°C for 1hour. 			
Technical considerations	I quality loss of taping/packaging materials. For this reason, capacitors shall be used within 6 months from the time of delivery. If exceeding t			

**RCR-2335B (Safety Application Guide for fixed ceramic capacitors for use in electronic equipment) is published by JEITA. Please check the guide regarding precautions for deflection test, soldering by spot heat, and so on.

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High Reliability Application Multilayer Ceramic Capacitors

■RELIABILITY DATA

RELIABILITY DATA			
1. Operating Tempe	rature Range		
Specified Value	X7R(-55°C to +125°C)		
Test Methods and Remarks	Continuous use is available in this range. (reference temperature : 25°C)		
2 High act On a vation	townsont us Dance		
Specified Value	X7R(-55°C to +125°C)		
Test Methods and Remarks	Maximum ambient temperature at which capacitors can be continuously used with rated voltage applied.		
3. Rated Voltage			
Specified Value	Please refer to the page of the "PART NUMBERS".		
Test Methods and Remarks	Continuous maximum applied voltage. If an AC voltage is loaded on a DC voltage, the sum of the two peak voltages should be lower than the rated voltage of the capacitor.		
4. Shape and Dimer			
Specified Value	Please refer to the page of the "EXTERNAL DIMENSIONS".		
5. Heat Treatment			
Test Methods and Remarks	Initial value shall be measured after test sample is heat—treated at $150+0/-10^{\circ}$ C for an hour and kept at room temperature for 24 \pm 2 hours.		
6. Voltage Treatmen			
Test Methods and Remarks	Initial value shall be measured after test sample is voltage—treated for an hour at temperature and voltage which are specified as test conditions, and kept at room temperature for 24 ± 2 hours.		
7. Dielectric Withst	anding Voltage(between terminals)		
Specified Value	No abnormality.		
	Applied voltage : Rated voltage × 2.5		
Test Methods and Remarks	Duration : 1 to 5 seconds.		
	Charging and discharging current shall be 50mA max.		
0.1 1.1 D.11			
8. Insulation Resista			
Specified Value	Larger than whichever smaller of 500 M Ω • μ F or 10* M Ω Applied voltage : Rated voltage		
Test Methods and	Applied voltage : Rated voltage Duration : 60±5 seconds.		
Remarks	Charging and discharging current shall be 50mA max.		
9. Capacitance and			
Specified Value	Please refer to the page of the "PART NUMBERS".		
Test Methods and Remarks	Measurement frequency : $1 \text{kHz} \pm 10\% (C \le 10 \mu\text{F})$ Measurement voltage : $1 \pm 0.2 \text{Vrms} (C \le 10 \mu\text{F})$ $0.5 \pm 0.1 \text{V} (6.3 \text{V rated voltage})$		
	Heat treatment specified in No.5 of the specification shall be conducted prior to measurement.		
10. Q or Dissipation	factor $(an\delta)$		
Specified Value	Please refer to the page of the "PART NUMBERS".		
-	Measurement frequency : 1kHz±10%(C≤10 μ F)		
Test Methods and Remarks	Measurement voltage : 1 ± 0.2 Vrms($C \le 10 \mu F$) 0.5 ±0.1 V(6.3V rated voltage)		
	Heat treatment specified in No.5 of the specification shall be conducted prior to measurement. NO DC bias is applied.		

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11. Temperature Characteristic (without DC bias) $X7R(-55^{\circ}C \text{ to } +125^{\circ}C): \pm 15\%$ Specified Value Confirming to EIA RS-198-D (1991) Heat treatment specified in No.5 of the specification shall be conducted prior to measurement. Change of the maximum capacitance deviation in step 1 to 5. Temperature (°C) step Test Methods and 1 +25Remarks 2 Minimum operating temperature 3 +25 4 Maximum operating temperature 5

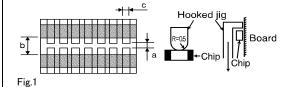
12. Adhesive Force of Terminal Electrodes

Specified Value Appearance: Terminal electrodes shall be no exfoliation or a sign of exfoliation.

Solder lands refer to fig.1.

	1608 size	larger than 2012 size	
Applying force	5N	10N	
Duration	30±5 seconds.		
Board	Glass epoxy-resin substrate		
Thickness	1.6mm		

Test Methods and Remarks



	Case size			
Dimension	1608	2012	3216	3225
а	1.0	1.2	2.2	2.2
b	3.0	4.0	5.0	5.0
С	1.2	1.65	2.0	2.9

13. Vibration			
Specified Value	Appearance : No abnormality Capacitance change : Initial value shall be satisfied. Dissipation factor : Initial value shall be satisfied. Insulation resistance : Initial value shall be satisfied.		
Test Methods and Remarks	heat treated as specified in No Solder lands refer to figure 1. Direction of the vibration test Vibrationfrequency Total amplitude	2.5 of the specification shall be conducted prior to test. Measurement shall be conducted after test sample is 0.5. 2. X, Y, Z each of 3 orientations for 2 hours respectively (total 6 hours) 3. 10 to 55 to 10Hz (1 minutes each) 3. 1.5 mm 3. 1.8 mall be made after test sample is kept at room temperature for 24 ±2 hours.	

14. Resistance to S				
	Appearance	: No abnormality		
	Capacitance change	: ≦±7.5%		
Specified Value	Dissipation factor	: Initial value shall be satisfied.		
	Insulation resistance	: Initial value shall be satisfied.		
	Dielectric withstanding volta	ge (between terminals): No abnormality		
	Heat treatment specified in No.5 of the specification shall be conducted prior to test.			
	Immerse test sample in an solder solution (Sn-3Ag-0.5Cu).			
	Soldering temperature	: 270°C±5°C		
Test Methods and	Duration : 3±0.5 seconds			
Remarks	Soaking position : Test sample is soaked until the termnal electrode is covered in solder solution.			
	Preheating condition	: 3216 size or smaller size: 120 to 150°C for 1 minute,		
		3225 size: 100 to 120°C for 1 minute, 170 to 200°C for 1 minute.		

15. Solderability			
Specified Value	More than 95% of terminal electrode shall be covered with fresh solder.		
Test Methods and Remarks	•	n No.5 of the specification shall be conducted prior to test. solder solution(Sn-3Ag-0.5Cu). : 245°C±5°C : 4±1 seconds : Test sample is immersed until the terminal electrode is covered in solder solution.	

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16. Thermal shock Appearance

Specified Value

: No abnormality Capacitance change : ≦±7.5%

Dissipation factor : Initial value shall be satisfied. Insulation resistance : Initial value shall be satisfied. Dielectric withstanding voltage (between terminals): No abnormality

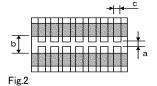
Heat treatment specified in No.5 of the specification shall be conducted prior to test. Measurement shall be conducted after test sample is heat treated as specified in No.5.

Step	Temperature (°C)	Time (min.)	Transfer time
1	Minimum usage temperature	15	within 20 seconds
2	Maximum usage temperature	15	within 20 seconds

Test Methods and Remarks

Test cycles: 100 times.

Measurement after the test shall be made after test sample is kept at room temperature for 24 ± 2 hours.



	Case size			
Dimension	1608	2012	3216	3225
а	0.6	0.8	2.0	2.0
b	2.2	3.0	4.4	4.4
С	0.9	1.3	1.7	2.6

	v Loading

Test Methods and

Remarks

Appearance : No abnormality Specified Value Capacitance change : ±12.5% Note1 Dissipation factor : 5.0%max. Insulation resistance : Larger than whichever smaller of 25M Ω • μ F or 500M Ω

> Test condition : 85°C/85%RH. Duration : 1000 + 48/-0 hours.DC bias : Applied rated voltage.

Voltage treatment specified in No.6 of the specification shall be conducted prior to test.

Measurement after the test shall be made after test sample is kept at room temperature for 24 \pm 2 hours.

18. High Temperature Loading

Appearance : No abnormality Specified Value $\cdot \le +12.5\%$ Capacitance change Note1 Dissipation factor : 5.0%max.

Insulation resistance : Larger than whichever smaller of 25M $\Omega \cdot \mu$ F or 500M Ω

Voltage treatment specified in No.6 of the specification shall be conducted prior to test. Test sample shall be put in thermostatic oven with maximum temperature.

Test Methods and Applied voltage : Rated voltage x 2

Remarks Duration : 1000 + 48/-0 hours.Charging and discharging current shall be 50mA or less.

Measurement after the test shall be made after test sample is kept at room temperature for 24 ±2 hours.

19. Resistance to Flexure of substrate

Appearance : No abnormality Capacitance change : ≦±12.5% Specified Value Dissipation factor : 5.0%max.

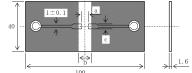
Insulation resistance : Initial value shall be satisfied.

Warp : 1mm

Testing board : Grass epoxy - resin substrate

Thickness : 1.6mm Test board and solder lands : Refer to fig. 3.

Test Methods and Remarks



	Gase size			
Dimension	1608	2012	3216	3225
а	0.6	8.0	2.0	2.0
b	2.2	3.0	4.4	4.4
С	0.9	1.3	1.7	2.6



Measurement shall be made with board in the bent position. (fig.4)



20. High Temperatu	20. High Temperature Exposure				
Specified Value Note1	Appearance Capacitance change Dissipation factor Insulation resistance	: No abnormality : $\leq \pm 12.5\%$: 5.0% max. : Larger than whichever smaller of $500M\Omega \cdot \mu$ F or $10000M\Omega$			
Test Methods and Remarks	Heat treatment specified in No.5 of the specification shall be conducted prior to test. Test sample shall be put in thermostatic oven with maximum temperature. Duration: 1000 +48/-0 hours. Initial value shall be measured after test sample is heat—treated specified No.5. Measurement after the test shall be made after test sample is kept at room temperature for 24 ±2 hours.				

21. Temperature Cy	ycling		
	Appearance	e : No abnormality	
Specified Value	Capacitano	e change : ≦±7.5%	
Note1	Dissipation	factor : Initial value shall be satisfied	ed
	Insulation r	esistance : Initial value shall be satisfie	ed
	Measureme	ment specified in No.5 of the specification shall be on the shall be conducted after test sample is heat tre f the one cycle Temperature (°C)	•
	Step	•	
Test Methods and		Minimum usage temperature	30±3
Remarks	2	+25	2 to 3
r comants	3	Maximum usage temperature	30±3
	4	+25 2	
	Test cycles	s:200 times	
	Solder land	ls refer to fig. 2.	
	Measureme	ent after the test shall be made after test sample is	kept at room tempe

22. Body strength	
Specified Value	No mechanical damage
Test Methods and Remarks	Applying force : 10N Applying time : 10 seconds $ \begin{array}{c} R=0.5 \\ R=0.5 $

Note 1 The figures indicate typical specifications. Please refer to individual specifications in detail.

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Precautions on the use of High Reliability Application Multilayer Ceramic Capacitors

PRECAUTIONS

1.Circuit Design

- ◆Verification of operating environment, electrical rating and performance
 - A malfunction in medical equipment, spacecraft, nuclear reactors, etc. may cause serious harm to human life or have severe social ramifications.

As such, any capacitors to be used in such equipment may require higher safety and/or reliability considerations and should be clearly differentiated from components used in general purpose applications.

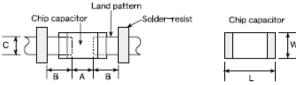
Precautions

- ◆Operating Voltage (Verification of Rated voltage)
 - 1. The operating voltage for capacitors must always be lower than their rated values.
 - If an AC voltage is loaded on a DC voltage, the sum of the two peak voltages should be lower than the rated value of the capacitor chosen. For a circuit where both an AC and a pulse voltage may be present, the sum of their peak voltages should also be lower than the capacitor's rated voltage.
 - 2. Even if the applied voltage is lower than the rated value, the reliability of capacitors might be reduced if either a high frequency AC voltage or a pulse voltage having rapid rise time is present in the circuit.

2. PCB Design

Precautions

- ◆Pattern configurations (Design of Land-patterns)
 - 1. When capacitors are mounted on a PCB, the amount of solder used (size of fillet) can directly affect capacitor performance. Therefore, the following items must be carefully considered in the design of solder land patterns:
 - (1) The amount of solder applied can affect the ability of chips to withstand mechanical stresses which may lead to breaking or cracking. Therefore, when designing land-patterns it is necessary to consider the appropriate size and configuration of the solder pads which in turn determines the amount of solder necessary to form the fillets.
 - (2) When more than one part is jointly soldered onto the same land or pad, the pad must be designed so that each component's soldering point is separated by solder-resist.
- ◆Pattern configurations (Capacitor layout on panelized [breakaway] PC boards)
 - After capacitors have been mounted on the boards, chips can be subjected to mechanical stresses in subsequent manufacturing processes (PCB cutting, board inspection, mounting of additional parts, assembly into the chassis, wave soldering the reflow soldered boards etc.) For this reason, planning pattern configurations and the position of SMD capacitors should be carefully performed to minimize stress
- ◆Pattern configurations (Design of Land-patterns)
 - 1. The following diagrams and tables show some examples of recommended patterns to prevent excessive solder amounts. (larger fillets which extend above the component end terminations) Examples of improper pattern designs are also shown.
 - (1) Recommended land dimensions for a typical chip capacitor land patterns for PCBs



Recommended land dimensions for reflow-soldering(unit: mm)

Туре		107	212	316	325
Size	┙	1.6	2.0	3.2	3.2
Size	W	0.8	1.25	1.6	2.5
Α		0.8~1.0	0.8~1.2	1.8~2.5	1.8~2.5
В		0.6~0.8	0.8~1.2	1.0~1.5	1.0~1.5
С		0.6~0.8	0.9~1.6	1.2~2.0	1.8~3.2

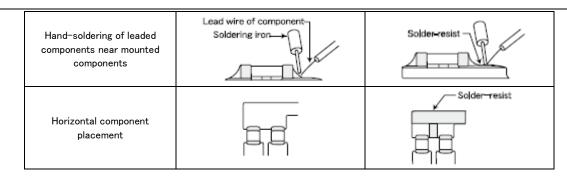
Technical considerations

Excess solder can affect the ability of chips to withstand mechanical stresses. Therefore, please take proper precautions when designing land-patterns.

(2) Examples of good and bad solder application

Items	Not recommended	Recommended	
Mixed mounting of SMD and leaded components	Lead wire of component.	Solder-resist	
Component placement close to the chassis	Chassis —Solder(for grounding) —Electrode pattern	Solder-resist	

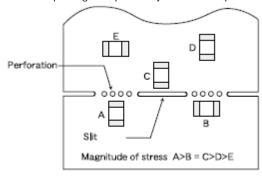
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- ◆Pattern configurations (Capacitor layout on panelized [breakaway] PC boards)
 - 1-1. The following is examples of good and bad capacitor layout; SMD capacitors should be located to minimize any possible mechanical stresses from board warp or deflection.

Items	Not recommended	Recommended	
Deflection of the board			Place the product at a right angle to the direction of the anticipated mechanical stress.

1-2. To layout the capacitors for the breakaway PC board, it should be noted that the amount of mechanical stresses given will vary depending on capacitor layout. The example below shows recommendations for better design.



1-3. When breaking PC boards along their perforations, the amount of mechanical stress on the capacitors can vary according to the method used. The following methods are listed in order from least stressful to most stressful: push-back, slit, V-grooving, and perforation. Thus, any ideal SMD capacitor layout must also consider the PCB splitting procedure.

3.Soldering

Precautions

Technical

considerations

◆Selection of Flux

- 1. Since flux may have a significant effect on the performance of capacitors, it is necessary to verify the following conditions prior to use;
 - (1) Flux used should be with less than or equal to 0.1 wt% (equivalent to chlorine) of halogenated content. Flux having strong acidity content should not be applied.
 - (2) When soldering capacitors on the board, the amount of flux applied should be controlled at the optimum level.
- (3) When using water-soluble flux, special care should be taken to properly clean the boards.

◆Soldering

- Temperature, time, amount of solder, etc. are specified in accordance with the following recommended conditions.
 Sn-Zn solder paste can affect MLCC reliability performance.
 - Please contact us prior to usage.

◆Selection of Flux

- 1-1. When too much halogenated substance (Chlorine, etc.) content is used to activate the flux, or highly acidic flux is used, an excessive amount of residue after soldering may lead to corrosion of the terminal electrodes or degradation of insulation resistance on the surface of the capacitors.
- 1-2. Flux is used to increase solderability in flow soldering, but if too much is applied, a large amount of flux gas may be emitted and may detrimentally affect solderability. To minimize the amount of flux applied, it is recommended to use a flux-bubbling system.
- 1-3. Since the residue of water-soluble flux is easily dissolved by water content in the air, the residue on the surface of capacitors in high humidity conditions may cause a degradation of insulation resistance and therefore affect the reliability of the components. The cleaning methods and the capability of the machines used should also be considered carefully when selecting water-soluble flux.

◆ Soldering

1-1. Preheating when soldering

Heating: Ceramic chip components should be preheated to within 100 to 130°C of the soldering.

Cooling: The temperature difference between the components and cleaning process should not be greater than 100°C.

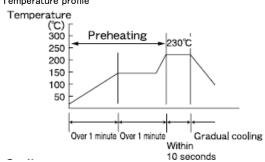
Ceramic chip capacitors are susceptible to thermal shock when exposed to rapid or concentrated heating or rapid cooling. Therefore, the soldering process must be conducted with great care so as to prevent malfunction of the components due to excessive thermal shock.

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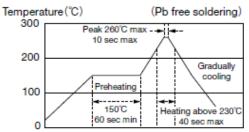
[Recommended conditions for soldering]

[Reflow soldering]

Temperature profile



[Recommended conditions for Pd Free soldering]

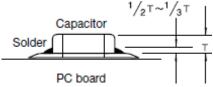


m %Ceramic chip components should be preheated to within 100 to 130°C of the soldering.

*Assured to be reflow soldering for 2 times.

Caution

1The ideal condition is to have solder mass (fillet) controlled to 1/2 to 1/3 of the thickness of the capacitor, as shown below:



②Because excessive dwell times can detrimentally affect solderability, soldering duration should be kept as close to recommended times as possible.